

S29GLxxxA MirrorBit[™] Flash Family

S29GL064A, S29GL032A 64 Megabit, 32 Megabit 3.0, Volt-only Page Mode Flash Memory Featuring 200 nm MirrorBit Process Technology

Data Sheet

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Data Sheet



ADVANCE INFORMATION

Distinctive Characteristics

Architectural Advantages

■ Single power supply operation

- 3 volt read, erase, and program operations
- Manufactured on 200 nm MirrorBit process technology
- Secured Silicon Sector region
 - 128-word/256-byte sector for permanent, secure identification through an 8-word/16-byte random Electronic Serial Number, accessible through a command sequence
 - May be programmed and locked at the factory or by the customer

Flexible sector architecture

- 64Mb (uniform sector models): 128 32 Kword (64 KB) sectors
- 64Mb (boot sector models): 127 32 Kword (64 KB) sectors + 8 4Kword (8KB) boot sectors
- 32Mb (uniform sector models): 64 32Kword (64KB) sectors
- 32Mb (boot sector models): 63 32Kword (64KB) sectors + 8 4Kword (8KB) boot sectors
- Compatibility with JEDEC standards
 - Provides pinout and software compatibility for singlepower supply flash, and superior inadvertent write protection
- 100,000 erase cycles typical per sector
- 20-year data retention typical

Performance Characteristics

- High performance
 - 90 ns access time
 - 4-word/8-byte page read buffer
 - 25 ns page read times
 - 16-word/32-byte write buffer which reduces overall programming time for multiple-word updates
- Low power consumption (typical values at 3.0 V, 5 MHz)
 - 18 mA typical active read current
 - 50 mA typical erase/program current
 - 1 µA typical standby mode current

Package options

- 48-pin TSOP
- 56-pin TSOP
- 64-ball Fortified BGA
- 48-ball fine-pitch BGA

Software & Hardware Features

Software features

- Program Suspend & Resume: read other sectors before programming operation is completed
- Erase Suspend & Resume: read/program other sectors before an erase operation is completed
- Data# polling & toggle bits provide status
- CFI (Common Flash Interface) compliant: allows host system to identify and accommodate multiple flash devices
- Unlock Bypass Program command reduces overall multiple-word programming time

Hardware features

- Sector Group Protection: hardware-level method of preventing write operations within a sector group
- Temporary Sector Unprotect: V_{ID}-level method of charging code in locked sectors
- WP#/ACC input accelerates programming time (when high voltage is applied) for greater throughput during system production. Protects first or last sector regardless of sector protection settings on uniform sector models
- Hardware reset input (RESET#) resets device
- Ready/Busy# output (RY/BY#) detects program or erase cycle completion

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Advance Information

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Combination

Some data sheets will contain a combination of products with different designations (Advance Information, Preliminary, or Full Production). This type of document will distinguish these products and their designations wherever necessary, typically on the first page, the ordering information page, and pages with DC Characteristics table and AC Erase and Program table (in the table notes). The disclaimer on the first page refers the reader to the notice on this page.

Full Production (No Designation on Document)

When a product has been in production for a period of time such that no changes or only nominal changes are expected, the Preliminary designation is removed from the data sheet. Nominal changes may include those affecting the number of ordering part numbers available, such as the addition or deletion of a speed option, temperature range, package type, or V_{10} range. Changes may also include those needed to clarify a description or to correct a typographical error or incorrect specification. Spansion LLC applies the following conditions to documents in this category:

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General Description

The S29GLxxxA family of devices are 3.0 V single power Flash memory manufactured using 200 nm MirrorBit technology. The S29GL064A is a 64 Mb, organized as 4,194,304 words or 8,388,608 bytes. The S29GL032A is a 32 Mb, organized as 2,097,152 words or 4,194,304 bytes. Depending on the model number, the devices have an 8-bit wide data bus only, 16-bit wide data bus only, or a 16-bit wide data bus that can also function as an 8-bit wide data bus by using the BYTE# input. The devices can be programmed either in the host system or in standard EPROM programmers.

Access times as fast as 90 ns are available. Note that each access time has a specific operating voltage range (V_{CC}) as specified in the Product Selector Guide and the Ordering Information sections. Package offerings include 48-pin TSOP, 56-pin TSOP, 48-ball fine-pitch BGA and 64-ball Fortified BGA, depending on model number. Each device has separate chip enable (CE#), write enable (WE#) and output enable (OE#) controls.

Each device requires only a **single 3.0 volt power supply** for both read and write functions. In addition to a V_{CC} input, a high-voltage **accelerated program (ACC)** feature provides shorter programming times through increased current on the WP#/ACC input. This feature is intended to facilitate factory throughput during system production, but may also be used in the field if desired.

The device is entirely command set compatible with the **JEDEC single-powersupply Flash standard**. Commands are written to the device using standard microprocessor write timing. Write cycles also internally latch addresses and data needed for the programming and erase operations.

The **sector erase architecture** allows memory sectors to be erased and reprogrammed without affecting the data contents of other sectors. The device is fully erased when shipped from the factory.

Device programming and erasure are initiated through command sequences. Once a program or erase operation has begun, the host system need only poll the DQ7 (Data# Polling) or DQ6 (toggle) **status bits** or monitor the **Ready/Busy# (RY/BY#)** output to determine whether the operation is complete. To facilitate programming, an **Unlock Bypass** mode reduces command sequence overhead by requiring only two write cycles to program data instead of four.

Hardware data protection measures include a low V_{CC} detector that automatically inhibits write operations during power transitions. The hardware sector protection feature disables both program and erase operations in any combination of sectors of memory. This can be achieved in-system or via programming equipment.

The **Erase Suspend/Erase Resume** feature allows the host system to pause an erase operation in a given sector to read or program any other sector and then complete the erase operation. The **Program Suspend/Program Resume** feature enables the host system to pause a program operation in a given sector to read any other sector and then complete the program operation.

The **hardware RESET# pin** terminates any operation in progress and resets the device, after which it is then ready for a new operation. The RESET# pin may be tied to the system reset circuitry. A system reset would thus also reset the device, enabling the host system to read boot-up firmware from the Flash memory device.



The device reduces power consumption in the **standby mode** when it detects specific voltage levels on CE# and RESET#, or when addresses have been stable for a specified period of time.

The **Write Protect (WP#)** feature protects the first or last sector by asserting a logic low on the WP#/ACC pin or WP# pin, depending on model number. The protected sector will still be protected even during accelerated programming.

The **Secured Silicon Sector** provides a 128-word/256-byte area for code or data that can be permanently protected. Once this sector is protected, no further changes within the sector can occur.

Spansion MirrorBit flash technology combines years of Flash memory manufacturing experience to produce the highest levels of quality, reliability and cost effectiveness. The device electrically erases all bits within a sector simultaneously via hot-hole assisted erase. The data is programmed using hot electron injection.



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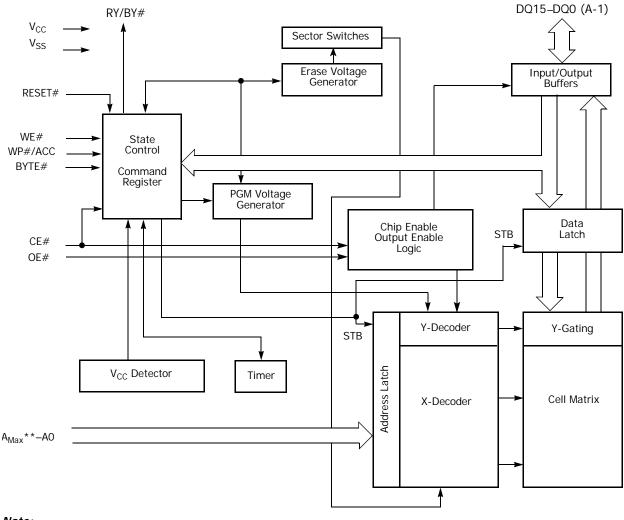


Product Selector Guide

S29GL064A, S29GL032A

Part Number		S29GL064	4	S29GL032A			
Speed Option	90	10	11	90	10	11	
Max. Access Time (ns)	90	100	110	90	100	110	
Max. CE# Access Time (ns)	90	100	110	90	100	110	
Max. Page Access Time (ns)	25	30	30	25	30	30	
Max. OE# Access Time (ns)	25	30	30	25	30	30	

Block Diagram



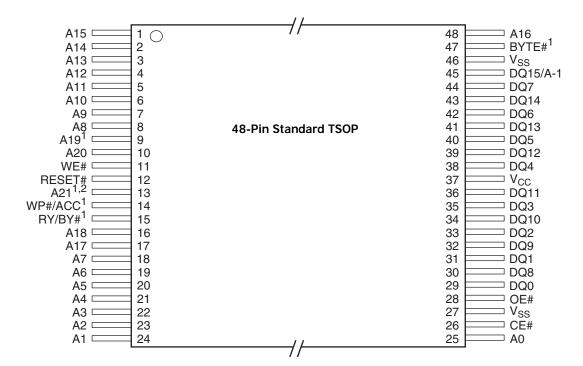
Note:

 $*A_{MAX} GL064A = A21.$ $*A_{MAX} GL032A = A20.$

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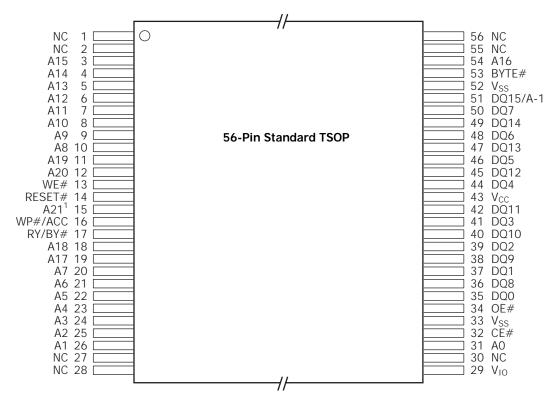
Connection Diagrams



Notes:

1. Pin 9 is A21, Pin 13 is ACC, Pin 14 is WP#, Pin 15 is A19, and Pin 47 is V_{IO} on S29GL064A (models R6, R7).

2. Pin 13 is NC on S29GL032A.

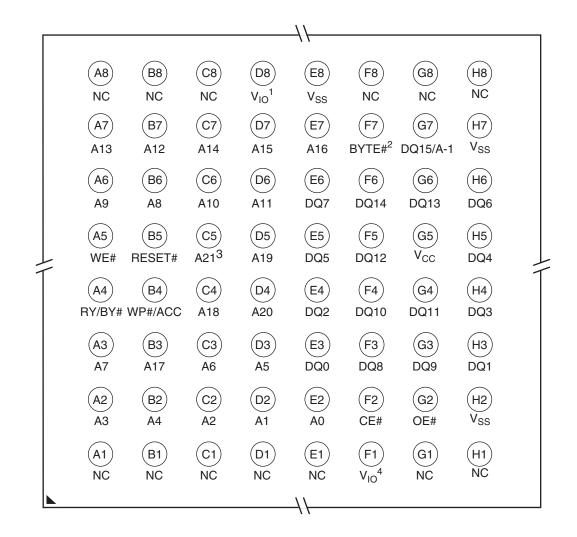


Notes:

1. Pin 15 is NC on S29GL032A.



64-ball Fortified BGA Top View, Balls Facing Down



Notes:

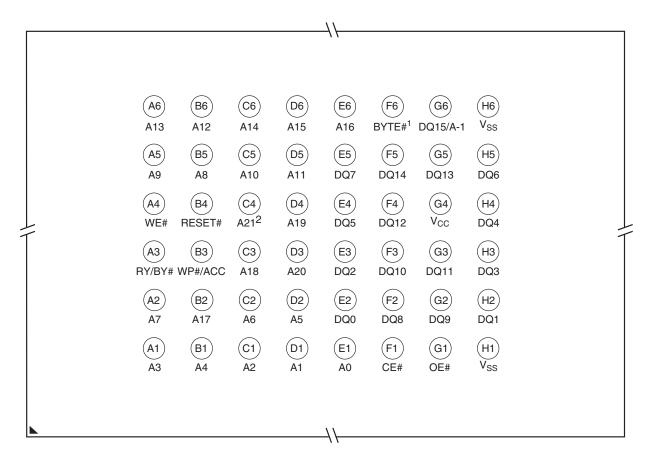
- 1. Ball D8 and Ball F1 are NC on S29GL064A (models R3, R4).
- 2. Ball F7 is NC on S29GL064A (model R5).
- 3. Ball C5 is NC on S29GL032A.

Special Package Handling Instructions

Special handling is required for Flash Memory products in moulded packages (TSOP and BGA). The package and/or data integrity may be compromised if the package body is exposed to temperatures above 150°C for prolonged periods of time.



48-ball Fine-pitch BGA Top View, Balls Facing Down



Notes:

- 1. Ball F6 is V_{IO} on S29GL064A (models R5).
- 2. Ball C4 is NC on S29GL032A.

Special Package Handling Instructions

Special handling is required for Flash Memory products in molded packages (TSOP and BGA). The package and/or data integrity may be compromised if the package body is exposed to temperatures above 150°C for prolonged periods of time.

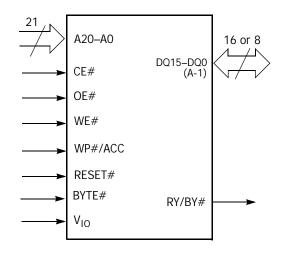


Pin Descriptions

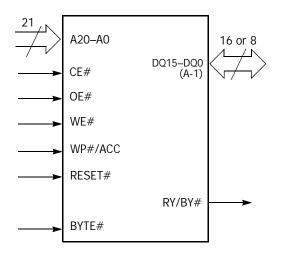
A21–A0	=	22 Address inputs
A20–A0	=	21 Address inputs
DQ7-DQ0	=	8 Data inputs/outputs
DQ14-DQ0	=	15 Data inputs/outputs
DQ15/A-1	=	DQ15 (Data input/output, word mode), A-1 (LSB
		Address input, byte mode)
CE#	=	Chip Enable input
OE#	=	Output Enable input
WE#	=	Write Enable input
WP#/ACC	=	Hardware Write Protect input/Programming
		Acceleration input
ACC	=	Acceleration input
WP#	=	Hardware Write Protect input
RESET#	=	Hardware Reset Pin input
RY/BY#	=	Ready/Busy output
BYTE#	=	Selects 8-bit or 16-bit mode
V _{CC}	=	3.0 volt-only single power supply
		(see Product Selector Guide for speed options and
		voltage supply tolerances)
V _{SS}	=	Device Ground
NC	=	Pin Not Connected Internally
V _{IO}	=	Output Buffer Power
NC	=	voltage supply tolerances) Device Ground Pin Not Connected Internally



Logic Symbol-S29GL032A (Models RI, R2)

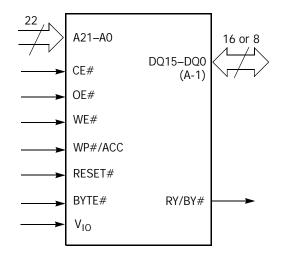


Logic Symbol-S29GL032A (Models R3, R4)

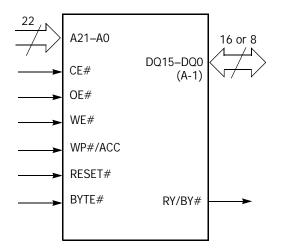




Logic Symbol-S29GL064A (Models RI, R2, R8, R9)

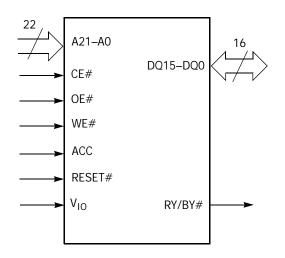


Logic Symbol-S29GL064A (Models R3, R4)

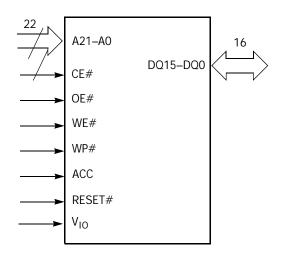




Logic Symbol-S29GL064A (Model R5)



Logic Symbol-S29GL064A (Model R6, R7)

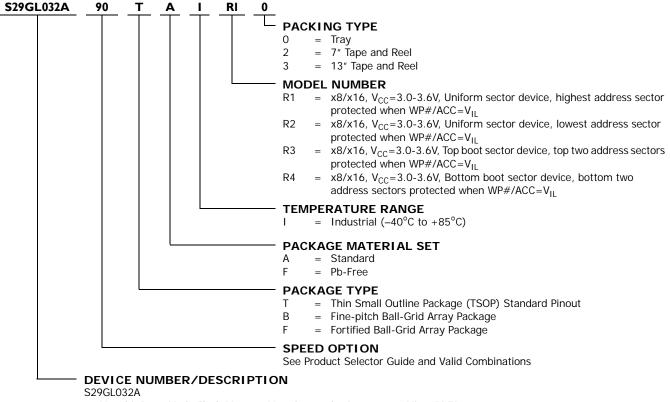




Ordering Information-S29GL032A

S29GL032A Standard Products

Standard products are available in several packages and operating ranges. The order number (Valid Combination) is formed by a combination of the following:



32 Megabit Page-Mode Flash Memory Manufactured using 200 nm MirrorBit™ Process Technology, 3.0 Volt-only Read, Program, and Erase



	5	Dashara Das										
Device Number	Speed Option	Package, Material, & Temperature Range	Model Number	Packing Type	Package Des (Notes							
S29GL032A	90, 10, 11	TAI,TFI	R1,R2	D1 D0	D1 D0	D1 D2	D4 D0	D1 D0	D1 D0		TS056 (2)	TSOP
		FAI,FFI		0,2,3 (Note 1)	LAA064 (3)	Fortified BGA						
		TAI,TFI			TS048 (2)	TSOP						
		BAI,BFI	R3,R4		FBC048 (3)	Fine-Pitch BGA						
		FAI,FFI			LAA064 (3)	Fortified BGA						

Table I. S29GL032A Ordering Options

Notes:

1. Type 0 is standard. Specify others as required: TSOPs can be packed in Types 0 and 3; BGAs can be packed in Types 0, 2, or 3.

2. TSOP package marking omits packing type designator from the ordering part number.

3. BGA package marking omits leading "\$29" and packing type designator from the ordering part number.

Valid Combinations

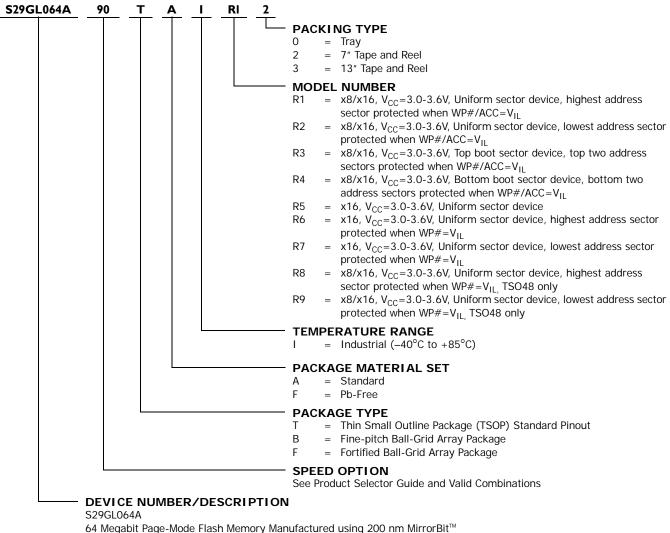
Valid Combinations list configurations planned to be supported in volume for this device. Consult your local sales office to confirm availability of specific valid combinations and to check on newly released combinations.



Ordering Information-S29GL064A

S29GL064A Standard Products

Standard products are available in several packages and operating ranges. The order number (Valid Combination) is formed by a combination of the following:



64 Megabit Page-Mode Flash Memory Manufactured using 200 nm Mirrol Process Technology, 3.0 Volt-only Read, Program, and Erase



Device Number	Speed Option	Package, Material & Temperature Range	Model Number	Packing Type	Package Description								
	29GL064A 90, 10, 11		R3, R4, R6, R7, R8, R9		TS048 (note 2)	TSOP							
S29GL064A 90		90, 10, 11	90, 10, 11	90, 10, 11	90, 10, 11	90, 10, 11	90, 10, 11	TAI, TFI	R1, R2	0, 2, 3	TS056 (note 2)	TSOP	
								90, 10, 11	90, 10, 11	90, 10, 11	BAI, BFI	R3, R4, R5	(Note 1)
						FAI, FFI	R1, R2, R3, R4, R5	T	LAA064 (note 3)	Fortified BGA			

Table 2. S29GL064A Valid Combinations

Notes:

- 1. Type 0 is standard. Specify others as required: TSOPs can be packed in Types 0 and 3; BGAs can be packed in Types 0, 2, or 3.
- 2. TSOP package marking omits packing type designator from ordering part number.
- 3. BGA package marking omits leading "S29" and packing type designator from ordering part number.

Valid Combinations

Valid Combinations list configurations planned to be supported in volume for this device. Consult your local sales office to confirm availability of specific valid combinations and to check on newly released combinations.



Device Bus Operations

This section describes the requirements and use of the device bus operations, which are initiated through the internal command register. The command register itself does not occupy any addressable memory location. The register is a latch used to store the commands, along with the address and data information needed to execute the command. The contents of the register serve as inputs to the internal state machine. The state machine outputs dictate the function of the device. Table 3 lists the device bus operations, the inputs and control levels they require, and the resulting output. The following subsections describe each of these operations in further detail.

									DQ8-DQ15		
Operation	CE#	OE#	WE#	RESET#	WP#	ACC	Addresses (Note 1)	DQ0- DQ7	BYTE# = V _{IH}	BYTE# = V _{IL}	
Read	L	L	Н	Н	Х	Х	A _{IN}	D _{OUT}	D _{OUT}		
Write (Program/Erase)	L	Н	L	Н	(Note 3)	х	A _{IN}	(Note 4)	(Note 4)	DQ8–DQ14 = High-Z,	
Accelerated Program	L	Н	L	Н	(Note 3)	V _{HH}	A _{IN}	(Note 4)	(Note 4)	DQ15 = A-1	
Standby	V _{CC} ± 0.3 V	Х	х	V _{CC} ± 0.3 V	х	Н	Х	High-Z	High-Z	High-Z	
Output Disable	L	Н	Н	Н	Х	Х	Х	High-Z	High-Z	High-Z	
Reset	Х	Х	Х	L	Х	Х	Х	High-Z	High-Z	High-Z	
Sector Group Protect (Note 2)	L	Н	L	V _{ID}	Н	Х	SA, A6 =L, A3=L, A2=L, A1=H, A0=L	(Note 4)	Х	х	
Sector Group Unprotect (Note 2)	L	Н	L	V _{ID}	Н	х	SA, A6=H, A3=L, A2=L, A1=H, A0=L	(Note 4)	Х	х	
Temporary Sector Group Unprotect	Х	Х	Х	V _{ID}	Н	Х	A _{IN}	(Note 4)	(Note 4)	High-Z	

Table 3.	Device	Bus	Operations

Legend: $L = Logic Low = V_{IL}$, $H = Logic High = V_{IH}$, $V_{ID} = 11.5-12.5 V$, $V_{HH} = 11.5-12.5 V$, X = Don't Care, SA = Sector Address, $A_{IN} = Address In$, $D_{IN} = Data In$, $D_{OUT} = Data Out$

Notes:

- 1. Addresses are Amax: A0 in word mode; Amax: A-1 in byte mode. Sector addresses are Amax: A15 in both modes.
- 2. The sector protect and sector unprotect functions may also be implemented via programming equipment. See the "Sector Group Protection and Unprotection" section.
- 3. If WP# = V_{IL}, the first or last sector remains protected (for uniform sector devices), and the two outer boot sectors are protected (for boot sector devices). If WP# = V_{IH}, the first or last sector, or the two outer boot sectors will be protected or unprotected as determined by the method described in "Sector Group Protection and Unprotection". All sectors are unprotected when shipped from the factory (The Secured Silicon Sector may be factory protected depending on version ordered.)
- 4. D_{IN} or D_{OUT} as required by command sequence, data polling, or sector protect algorithm (see Figure 7).



Word/Byte Configuration

The BYTE# pin controls whether the device data I/O pins operate in the byte or word configuration. If the BYTE# pin is set at logic '1', the device is in word configuration, DQ0–DQ15 are active and controlled by CE# and OE#.

If the BYTE# pin is set at logic '0', the device is in byte configuration, and only data I/O pins DQ0–DQ7 are active and controlled by CE# and OE#. The data I/O pins DQ8–DQ14 are tri-stated, and the DQ15 pin is used as an input for the LSB (A-1) address function.

Requirements for Reading Array Data

To read array data from the outputs, the system must drive the CE# and OE# pins to V_{IL}. CE# is the power control and selects the device. OE# is the output control and gates array data to the output pins. WE# should remain at V_{IH}.

The internal state machine is set for reading array data upon device power-up, or after a hardware reset. This ensures that no spurious alteration of the memory content occurs during the power transition. No command is necessary in this mode to obtain array data. Standard microprocessor read cycles that assert valid addresses on the device address inputs produce valid data on the device data outputs. The device remains enabled for read access until the command register contents are altered.

See "Reading Array Data" for more information. Refer to the AC Read-Only Operations table for timing specifications and the timing diagram. Refer to the DC Characteristics table for the active current specification on reading array data.

Page Mode Read

The device is capable of fast page mode read and is compatible with the page mode Mask ROM read operation. This mode provides faster read access speed for random locations within a page. The page size of the device is 4 words/8 bytes. The appropriate page is selected by the higher address bits A(max)–A2. Address bits A1–A0 in word mode (A1–A-1 in byte mode) determine the specific word within a page. This is an asynchronous operation; the microprocessor supplies the specific word location.

The random or initial page access is equal to t_{ACC} or t_{CE} and subsequent page read accesses (as long as the locations specified by the microprocessor falls within that page) is equivalent to t_{PACC} . When CE# is deasserted and reasserted for a subsequent access, the access time is t_{ACC} or t_{CE} . Fast page mode accesses are obtained by keeping the "read-page addresses" constant and changing the "intra-read page" addresses.

Writing Commands/Command Sequences

To write a command or command sequence (which includes programming data to the device and erasing sectors of memory), the system must drive WE# and CE# to V_{IL}, and OE# to V_{IH}.

The device features an **Unlock Bypass** mode to facilitate faster programming. Once the device enters the Unlock Bypass mode, only two write cycles are required to program a word, instead of four. The "Word Program Command Sequence" section has details on programming data to the device using both standard and Unlock Bypass command sequences.



An erase operation can erase one sector, multiple sectors, or the entire device. Table 4-Table 20 indicates the address space that each sector occupies.

Refer to the DC Characteristics table for the active current specification for the write mode. The AC Characteristics section contains timing specification tables and timing diagrams for write operations.

Write Buffer

Write Buffer Programming allows the system write to a maximum of 16 words/32 bytes in one programming operation. This results in faster effective programming time than the standard programming algorithms. See "Write Buffer" for more information.

Accelerated Program Operation

The device offers accelerated program operations through the ACC function. This is one of two functions provided by the WP#/ACC or ACC pin, depending on model number. This function is primarily intended to allow faster manufacturing throughput at the factory.

If the system asserts V_{HH} on this pin, the device automatically enters the aforementioned Unlock Bypass mode, temporarily unprotects any protected sector groups, and uses the higher voltage on the pin to reduce the time required for program operations. The system would use a two-cycle program command sequence as required by the Unlock Bypass mode. Removing V_{HH} from the WP#/ ACC or ACC pin, depending on model number, returns the device to normal operation. Note that the WP#/ACC or ACC pin must not be at V_{HH} for operations other than accelerated programming, or device damage may result. WP# has an internal pullup; when unconnected, WP# is at V_{IH} .

Autoselect Functions

If the system writes the autoselect command sequence, the device enters the autoselect mode. The system can then read autoselect codes from the internal register (which is separate from the memory array) on DQ7–DQ0. Standard read cycle timings apply in this mode. Refer to the "Autoselect Mode" section on page 30 and "Autoselect Command Sequence" section on page 44 sections for more information.

Standby Mode

When the system is not reading or writing to the device, it can place the device in the standby mode. In this mode, current consumption is greatly reduced, and the outputs are placed in the high impedance state, independent of the OE# input.

The device enters the CMOS standby mode when the CE# and RESET# pins are both held at V_{IO} ± 0.3 V. (Note that this is a more restricted voltage range than V_{IH}.) If CE# and RESET# are held at V_{IH}, but not within V_{IO} ± 0.3 V, the device will be in the standby mode, but the standby current will be greater. The device requires standard access time (t_{CE}) for read access when the device is in either of these standby modes, before it is ready to read data.

If the device is deselected during erasure or programming, the device draws active current until the operation is completed.

Refer to the "DC Characteristics" section on page 65 for the standby current specification.



Automatic Sleep Mode

The automatic sleep mode minimizes Flash device energy consumption. The device automatically enables this mode when addresses remain stable for t_{ACC} + 30 ns. The automatic sleep mode is independent of the CE#, WE#, and OE# control signals. Standard address access timings provide new data when addresses are changed. While in sleep mode, output data is latched and always available to the system. Refer to the "DC Characteristics" section on page 65 for the automatic sleep mode current specification.

RESET#: Hardware Reset Pin

The RESET# pin provides a hardware method of resetting the device to reading array data. When the RESET# pin is driven low for at least a period of t_{RP} , the device immediately terminates any operation in progress, tristates all output pins, and ignores all read/write commands for the duration of the RESET# pulse. The device also resets the internal state machine to reading array data. The operation that was interrupted should be reinitiated once the device is ready to accept another command sequence, to ensure data integrity.

Current is reduced for the duration of the RESET# pulse. When RESET# is held at $V_{SS}\pm0.3$ V, the device draws CMOS standby current (I_{CC5}). If RESET# is held at V_{IL} but not within $V_{SS}\pm0.3$ V, the standby current will be greater.

The RESET# pin may be tied to the system reset circuitry. A system reset would thus also reset the Flash memory, enabling the system to read the boot-up firmware from the Flash memory.

Refer to the AC Characteristics tables for RESET# parameters and to Figure 15 for the timing diagram.

Output Disable Mode

When the OE# input is at $V_{\rm IH},$ output from the device is disabled. The output pins are placed in the high impedance state.

Sector	A20-A15	Sector Size (KB/ Kwords)	8-bit Address Range	16-bit Address Range	Sector	A20-A15	Sector Size (KB/ Kwords)	8-bit Address Range	16-bit Address Range
SA0	000000	64/32	000000-00FFFF	000000-007FFF	SA32	100000	64/32	200000-20FFFF	100000-107FFF
SA1	00001	64/32	010000-01FFFF	008000-00FFFF	SA33	100001	64/32	210000-21FFFF	108000-10FFFF
SA2	000010	64/32	020000-02FFFF	010000-017FFF	SA34	100010	64/32	220000-22FFFF	110000–117FFF
SA3	000011	64/32	030000-03FFFF	018000-01FFFF	SA35	100011	64/32	230000-23FFFF	118000–11FFFF
SA4	000100	64/32	040000-04FFFF	020000-027FFF	SA36	100100	64/32	240000-24FFFF	120000-127FFF
SA5	000101	64/32	050000-05FFFF	028000-02FFFF	SA37	100101	64/32	250000-25FFFF	128000–12FFFF
SA6	000110	64/32	060000-06FFFF	030000-037FFF	SA38	100110	64/32	260000-26FFFF	130000–137FFF
SA7	000111	64/32	070000-07FFFF	038000-03FFFF	SA39	100111	64/32	270000-27FFFF	138000–13FFFF
SA8	001000	64/32	080000-08FFFF	040000-047FFF	SA40	101000	64/32	280000-28FFFF	140000-147FFF
SA9	001001	64/32	090000-09FFFF	048000-04FFFF	SA41	101001	64/32	290000-29FFFF	148000–14FFFF
SA10	001010	64/32	0A0000-0AFFFF	050000-057FFF	SA42	101010	64/32	2A0000–2AFFFF	150000–157FFF
SA11	001011	64/32	0B0000-0BFFFF	058000-05FFFF	SA43	101011	64/32	2B0000-2BFFFF	158000-15FFFF
SA12	001100	64/32	0C0000-0CFFFF	060000-067FFF	SA44	101100	64/32	2C0000-2CFFFF	160000-167FFF
SA13	001101	64/32	0D0000-0DFFFF	068000-06FFFF	SA45	101101	64/32	2D0000-2DFFFF	168000-16FFFF
SA14	001110	64/32	0E0000-0EFFFF	070000-077FFF	SA46	101110	64/32	2E0000-2EFFFF	170000-177FFF
SA15	0011111	64/32	0F0000-0FFFFF	078000-07FFFF	SA47	101111	64/32	2F0000-2FFFFF	178000–17FFFF
SA16	010000	64/32	100000-10FFFF	080000-087FFF	SA48	110000	64/32	300000-30FFFF	180000–187FFF
SA17	010001	64/32	110000-11FFFF	088000-08FFFF	SA49	110001	64/32	310000-31FFFF	188000–18FFFF
SA18	0 1 0 0 1 0	64/32	120000-12FFFF	090000-097FFF	SA50	110010	64/32	320000-32FFFF	190000–197FFF
SA19	0 1 0 0 1 1	64/32	130000-13FFFF	098000-09FFFF	SA51	1 1 0 0 1 1	64/32	330000-33FFFF	198000–19FFFF
SA20	0 1 0 1 0 0	64/32	140000-14FFFF	0A0000-0A7FFF	SA52	110100	64/32	340000-34FFFF	1A0000-1A7FFF
SA21	0 1 0 1 0 1	64/32	150000-15FFFF	0A8000-0AFFFF	SA53	1 1 0 1 0 1	64/32	350000-35FFFF	1A8000–1AFFFF
SA22	0 1 0 1 1 0	64/32	160000-16FFFF	0B0000-0B7FFF	SA54	1 1 0 1 1 0	64/32	360000-36FFFF	1B0000-1B7FFF
SA23	0 1 0 1 1 1	64/32	170000-17FFFF	0B8000-0BFFFF	SA55	1 1 0 1 1 1	64/32	370000-37FFFF	1B8000–1BFFFF
SA24	0 1 1 0 0 0	64/32	180000-18FFFF	0C0000-0C7FFF	SA56	111000	64/32	380000-38FFFF	1C0000-1C7FFF
SA25	0 1 1 0 0 1	64/32	190000-19FFFF	0C8000-0CFFFF	SA57	1 1 1 0 0 1	64/32	390000-39FFFF	1C8000-1CFFFF
SA26	0 1 1 0 1 0	64/32	1A0000–1AFFFF	0D0000-0D7FFF	SA58	1 1 1 0 1 0	64/32	3A0000-3AFFFF	1D0000-1D7FFF
SA27	0 1 1 0 1 1	64/32	1B0000-1BFFFF	0D8000-0DFFFF	SA59	1 1 1 0 1 1	64/32	3B0000-3BFFFF	1D8000–1DFFFF
SA28	0 1 1 1 0 0	64/32	1C0000-1CFFFF	0E0000-0E7FFF	SA60	1 1 1 1 0 0	64/32	3C0000-3CFFFF	1E0000-1E7FFF
SA29	0 1 1 1 0 1	64/32	1D0000-1DFFFF	0E8000-0EFFFF	SA61	1 1 1 1 0 1	64/32	3D0000-3DFFFF	1E8000–1EFFFF
SA30	0 1 1 1 1 0	64/32	1E0000–1EFFFF	OF0000-OF7FFF	SA62	1 1 1 1 1 0	64/32	3E0000-3EFFFF	1F0000-1F7FFF
SA31	0 1 1 1 1 1	64/32	1F0000–1FFFFF	OF8000-OFFFFF	SA63	1 1 1 1 1 1	64/32	3F0000–3FFFFF	1F8000–1FFFFF

Table 4. S29GL032M (Models RI, R2) Sector Addresses



Table 5. S29GL032M (Models R3) Top Boot Sector Addresses

Sector	A20–A12	Sector Size (KB/ Kwords)	8-bit Address Range	16-bit Address Range	Sector	A20–A12	Sector Size (KB/ Kwords)	8-bit Address Range	16-bit Address Range
SA0	000000xxx	64/32	000000h-00FFFFh	00000h-07FFh	SA36	100100xxx	64/32	240000h-24FFFFh	120000h–127FFFh
SA1	000001xxx	64/32	010000h-01FFFFh	08000h–0FFFFh	SA37	100101xxx	64/32	250000h-25FFFFh	128000h-12FFFFh
SA2	000010xxx	64/32	020000h-02FFFFh	10000h–17FFFh	SA38	100110xxx	64/32	260000h-26FFFh	130000h–137FFFh
SA3	000011xxx	64/32	030000h-03FFFFh	18000h–1FFFFh	SA39	100111xxx	64/32	270000h-27FFFh	138000h–13FFFFh
SA4	000100xxx	64/32	040000h-04FFFFh	20000h-27FFh	SA40	101000xxx	64/32	280000h-28FFFFh	140000h–147FFFh
SA5	000101xxx	64/32	050000h-05FFFFh	28000h–2FFFFh	SA41	101001xxx	64/32	290000h-29FFFFh	148000h–14FFFFh
SA6	000110xxx	64/32	060000h-06FFFFh	30000h-37FFFh	SA42	101010xxx	64/32	2A0000h-2AFFFFh	150000h–157FFFh
SA7	000111xxx	64/32	070000h-07FFFh	38000h–3FFFFh	SA43	101011xxx	64/32	2B0000h-2BFFFFh	158000h-15FFFFh
SA8	001000xxx	64/32	080000h-08FFFFh	40000h-47FFFh	SA44	101100xxx	64/32	2C0000h-2CFFFFh	160000h–167FFFh
SA9	001001xxx	64/32	090000h-09FFFFh	48000h-4FFFFh	SA45	101101xxx	64/32	2D0000h-2DFFFFh	168000h–16FFFFh
SA10	001010xxx	64/32	0A0000h-0AFFFFh	50000h-57FFFh	SA46	101110xxx	64/32	2E0000h-2EFFFFh	170000h–177FFFh
SA11	001011xxx	64/32	0B0000h-0BFFFFh	58000h-5FFFFh	SA47	101111xxx	64/32	2F0000h-2FFFFFh	178000h–17FFFFh
SA12	001100xxx	64/32	0C0000h-0CFFFFh	60000h-67FFh	SA48	110000xxx	64/32	300000h-30FFFFh	180000h–187FFFh
SA13	001101xxx	64/32	0D0000h-0DFFFFh	68000h–6FFFFh	SA49	110001xxx	64/32	310000h-31FFFFh	188000h–18FFFFh
SA14	001101xxx	64/32	0E0000h-0EFFFFh	70000h-77FFFh	SA50	110010xxx	64/32	320000h-32FFFFh	190000h–197FFFh
SA15	001111xxx	64/32	0F0000h-0FFFFFh	78000h–7FFFFh	SA51	110011xxx	64/32	330000h-33FFFFh	198000h–19FFFFh
SA16	010000xxx	64/32	100000h-00FFFFh	80000h-87FFh	SA52	100100xxx	64/32	340000h-34FFFFh	1A0000h–1A7FFFh
SA17	010001xxx	64/32	110000h-11FFFFh	88000h-8FFFFh	SA53	110101xxx	64/32	350000h-35FFFFh	1A8000h–1AFFFFh
SA18	010010xxx	64/32	120000h-12FFFFh	90000h-97FFFh	SA54	110110xxx	64/32	360000h-36FFFFh	1B0000h-1B7FFFh
SA19	010011xxx	64/32	130000h-13FFFFh	98000h–9FFFFh	SA55	110111xxx	64/32	370000h-37FFFh	1B8000h–1BFFFFh
SA20	010100xxx	64/32	140000h-14FFFFh	A0000h–A7FFFh	SA56	111000xxx	64/32	380000h-38FFFFh	1C0000h-1C7FFFh
SA21	010101xxx	64/32	150000h-15FFFFh	A8000h–AFFFFh	SA57	111001xxx	64/32	390000h-39FFFFh	1C8000h-1CFFFFh
SA22	010110xxx	64/32	160000h-16FFFh	B0000h-B7FFh	SA58	111010xxx	64/32	3A0000h-3AFFFFh	1D0000h-1D7FFh
SA23	010111xxx	64/32	170000h-17FFFh	B8000h-BFFFFh	SA59	111011xxx	64/32	3B0000h-3BFFFFh	1D8000h-1DFFFFh
SA24	011000xxx	64/32	180000h-18FFFFh	C0000h-C7FFFh	SA60	111100xxx	64/32	3C0000h-3CFFFFh	1E0000h-1E7FFFh
SA25	011001xxx	64/32	190000h-19FFFFh	C8000h–CFFFFh	SA61	111101xxx	64/32	3D0000h-3DFFFFh	1E8000h–1EFFFFh
SA26	011010xxx	64/32	1A0000h-1AFFFFh	D0000h-D7FFh	SA62	111110xxx	64/32	3E0000h-3EFFFh	1F0000h–1F7FFFh
SA27	011011xxx	64/32	1B0000h-1BFFFFh	D8000h–DFFFFh	SA63	111111000	8/4	3F0000h-3F1FFFh	1F8000h-1F8FFFh
SA28	011000xxx	64/32	1C0000h-1CFFFFh	E0000h-E7FFh	SA64	111111001	8/4	3F2000h-3F3FFFh	1F9000h-1F9FFFh
SA29	011101xxx	64/32	1D0000h-1DFFFFh	E8000h-EFFFFh	SA65	111111010	8/4	3F4000h-3F5FFFh	1FA000h–1FAFFFh
SA30	011110xxx	64/32	1E0000h-1EFFFh	F0000h-F7FFFh	SA66	111111011	8/4	3F6000h-3F7FFh	1FB000h–1FBFFFh
SA31	011111xxx	64/32	1F0000h-1FFFFh	F8000h-FFFFFh	SA67	111111100	8/4	3F8000h-3F9FFFh	1FC000h-1FCFFFh
SA32	100000xxx	64/32	200000h-20FFFFh	F9000h-107FFFh	SA68	111111101	8/4	3FA000h-3FBFFFh	1FD000h-1FDFFFh
SA33	100001xxx	64/32	210000h-21FFFFh	108000h-10FFFFh	SA69	111111110	8/4	3FC000h-3FDFFFh	1FE000h-1FEFFFh
SA34	100010xxx	64/32	220000h-22FFFFh	110000h-117FFFh	SA70	111111111	8/4	3FE000h-3FFFFh	1FF000h–1FFFFFh
SA35	101011xxx	64/32	230000h-23FFFFh	118000h-11FFFFh					

Table 6. S29GL032M (Models R4) Bottom Boot Sector Addresses (Sheet I of 2)

Sector	A20–A12	Sector Size (KB/ Kwords)	8-bit Address Range	16-bit Address Range	Sector	A20–A12	Sector Size (KB/ Kwords)	8-bit Address Range	16-bit Address Range
SA0	00000000	8/4	000000h-001FFFh	00000h-00FFFh	SA19	001100xxx	64/32	0C0000h-0CFFFFh	60000h–67FFh
SA1	00000001	8/4	002000h-003FFFh	01000h–01FFFh	SA20	001101xxx	64/32	0D0000h-0DFFFFh	68000h–6FFFFh
SA2	000000010	8/4	004000h-005FFFh	02000h-02FFFh	SA21	001101xxx	64/32	0E0000h-0EFFFFh	70000h–77FFFh
SA3	000000011	8/4	006000h-007FFFh	03000h–03FFFh	SA22	001111xxx	64/32	0F0000h-0FFFFFh	78000h–7FFFFh
SA4	000000100	8/4	008000h-009FFFh	04000h–04FFFh	SA23	010000xxx	64/32	100000h-00FFFFh	80000h-87FFFh
SA5	000000101	8/4	00A000h-00BFFFh	05000h-05FFFh	SA24	010001xxx	64/32	110000h-11FFFFh	88000h-8FFFFh
SA6	000000110	8/4	00C000h-00DFFFh	06000h-06FFFh	SA25	010010xxx	64/32	120000h-12FFFFh	90000h–97FFh
SA7	000000111	8/4	00E000h-00FFFFFh	07000h–07FFFh	SA26	010011xxx	64/32	130000h-13FFFFh	98000h–9FFFFh
SA8	000001xxx	64/32	010000h-01FFFFh	08000h–0FFFFh	SA27	010100xxx	64/32	140000h-14FFFFh	A0000h–A7FFFh
SA9	000010xxx	64/32	020000h-02FFFFh	10000h–17FFFh	SA28	010101xxx	64/32	150000h-15FFFFh	A8000h–AFFFFh
SA10	000011xxx	64/32	030000h-03FFFFh	18000h–1FFFFh	SA29	010110xxx	64/32	160000h-16FFFh	B0000h–B7FFFh
SA11	000100xxx	64/32	040000h-04FFFFh	20000h-27FFFh	SA30	010111xxx	64/32	170000h–17FFFFh	B8000h–BFFFFh
SA12	000101xxx	64/32	050000h-05FFFFh	28000h–2FFFFh	SA31	011000xxx	64/32	180000h-18FFFFh	C0000h-C7FFFh
SA13	000110xxx	64/32	060000h-06FFFFh	30000h-37FFFh	SA32	011001xxx	64/32	190000h-19FFFh	C8000h–CFFFFh
SA14	000111xxx	64/32	070000h-07FFFh	38000h–3FFFFh	SA33	011010xxx	64/32	1A0000h–1AFFFFh	D0000h–D7FFh
SA15	001000xxx	64/32	080000h-08FFFFh	40000h-47FFFh	SA34	011011xxx	64/32	1B0000h-1BFFFFh	D8000h-DFFFFh
SA16	001001xxx	64/32	090000h-09FFFFh	48000h–4FFFFh	SA35	011000xxx	64/32	1C0000h-1CFFFFh	E0000h–E7FFFh
SA17	001010xxx	64/32	0A0000h-0AFFFFh	50000h-57FFFh	SA36	011101xxx	64/32	1D0000h-1DFFFFh	E8000h–EFFFFh
SA18	001011xxx	64/32	0B0000h-0BFFFFh	58000h–5FFFFh	SA37	011110xxx	64/32	1E0000h–1EFFFFh	F0000h-F7FFFh



Table 6. S29GL032M (Models R4) Bottom Boot Sector Addresses (Sheet 2 of 2)

Sector	A20–A12	Sector Size (KB/ Kwords)	8-bit Address Range	16-bit Address Range	Sector	A20–A12	Sector Size (KB/ Kwords)	8-bit Address Range	16-bit Address Range
SA38	0111111xxx	64/32	1F0000h–1FFFFFh	F8000h-FFFFFh	SA55	110000xxx	64/32	300000h-30FFFFh	180000h–187FFFh
SA39	100000xxx	64/32	200000h-20FFFFh	F9000h-107FFFh	SA56	110001xxx	64/32	310000h-31FFFFh	188000h-18FFFFh
SA40	100001xxx	64/32	210000h-21FFFFh	108000h-10FFFFh	SA57	110010xxx	64/32	320000h-32FFFFh	190000h–197FFh
SA41	100010xxx	64/32	220000h-22FFFFh	110000h-117FFFh	SA58	110011xxx	64/32	330000h-33FFFFh	198000h–19FFFFh
SA42	101011xxx	64/32	230000h-23FFFFh	118000h-11FFFFh	SA59	100100xxx	64/32	340000h-34FFFFh	1A0000h–1A7FFFh
SA43	100100xxx	64/32	240000h-24FFFFh	120000h-127FFh	SA60	110101xxx	64/32	350000h-35FFFFh	1A8000h–1AFFFFh
SA44	100101xxx	64/32	250000h-25FFFFh	128000h-12FFFFh	SA61	110110xxx	64/32	360000h-36FFFFh	1B0000h-1B7FFFh
SA45	100110xxx	64/32	260000h-26FFFFh	130000h-137FFFh	SA62	110111xxx	64/32	370000h-37FFFh	1B8000h–1BFFFFh
SA46	100111xxx	64/32	270000h-27FFFh	138000h-13FFFFh	SA63	111000xxx	64/32	380000h-38FFFFh	1C0000h-1C7FFFh
SA47	101000xxx	64/32	280000h-28FFFFh	140000h-147FFFh	SA64	111001xxx	64/32	390000h-39FFFFh	1C8000h-1CFFFFh
SA48	101001xxx	64/32	290000h-29FFFFh	148000h-14FFFFh	SA65	111010xxx	64/32	3A0000h-3AFFFFh	1D0000h-1D7FFFh
SA49	101010xxx	64/32	2A0000h-2AFFFFh	150000h-157FFh	SA66	111011xxx	64/32	3B0000h-3BFFFFh	1D8000h–1DFFFFh
SA50	101011xxx	64/32	2B0000h-2BFFFFh	158000h-15FFFFh	SA67	111100xxx	64/32	3C0000h-3CFFFFh	1E0000h–1E7FFh
SA51	101100xxx	64/32	2C0000h-2CFFFFh	160000h-167FFh	SA68	111101xxx	64/32	3D0000h-3DFFFFh	1E8000h–1EFFFFh
SA52	101101xxx	64/32	2D0000h-2DFFFFh	168000h-16FFFh	SA69	111110xxx	64/32	3E0000h-3EFFFFh	1F0000h–1F7FFFh
SA53	101110xxx	64/32	2E0000h-2EFFFh	170000h-177FFFh	SA70	1111111xxx	64/32	3F0000h-3FFFFFh	1F8000h–1FFFFFh
SA54	101111xxx	64/32	2F0000h-2FFFFFh	178000h-17FFFFh					

Table 7. S29GL064A (Models RI, R2, R8, R9) Sector Addresses (Sheet I of 2)

Sector	A21–A15	Sector Size (KB/ Kwords)	8-bit Address Range	16-bit Address Range	Sector	A21–A15	Sector Size (KB/ Kwords)	8-bit Address Range	16-bit Address Range
SA0	0000000	64/32	000000-00FFFF	000000-007FFF	SA37	0100101	64/32	250000-25FFFF	128000-12FFFF
SA1	0000001	64/32	010000-01FFFF	008000-00FFFF	SA38	0100110	64/32	260000-26FFFF	130000–137FFF
SA2	0000010	64/32	020000-02FFFF	010000-017FFF	SA39	0100111	64/32	270000-27FFFF	138000–13FFFF
SA3	0000011	64/32	030000-03FFFF	018000-01FFFF	SA40	0101000	64/32	280000-28FFFF	140000-147FFF
SA4	0000100	64/32	040000-04FFFF	020000-027FFF	SA41	0101001	64/32	290000-29FFFF	148000–14FFFF
SA5	0000101	64/32	050000-05FFFF	028000-02FFFF	SA42	0101010	64/32	2A0000-2AFFFF	150000-157FFF
SA6	0000110	64/32	060000-06FFFF	030000-037FFF	SA43	0101011	64/32	2B0000-2BFFFF	158000–15FFFF
SA7	0000111	64/32	070000-07FFFF	038000-03FFFF	SA44	0101100	64/32	2C0000-2CFFFF	160000-167FFF
SA8	0001000	64/32	080000-08FFFF	040000-047FFF	SA45	0101101	64/32	2D0000-2DFFFF	168000-16FFFF
SA9	0001001	64/32	090000-09FFFF	048000-04FFFF	SA46	0101110	64/32	2E0000-2EFFFF	170000-177FFF
SA10	0001010	64/32	0A0000-0AFFFF	050000-057FFF	SA47	0101111	64/32	2F0000-2FFFFF	178000–17FFFF
SA11	0001011	64/32	0B0000-0BFFFF	058000-05FFFF	SA48	0110000	64/32	300000-30FFFF	180000-187FFF
SA12	0001100	64/32	0C0000-0CFFFF	060000-067FFF	SA49	0110001	64/32	310000-31FFFF	188000–18FFFF
SA13	0001101	64/32	0D0000-0DFFFF	068000-06FFFF	SA50	0110010	64/32	320000-32FFFF	190000–197FFF
SA14	0001110	64/32	0E0000-0EFFFF	070000-077FFF	SA51	0110011	64/32	330000-33FFFF	198000–19FFFF
SA15	0001111	64/32	0F0000-0FFFFF	078000-07FFFF	SA52	0110100	64/32	340000-34FFFF	1A0000-1A7FFF
SA16	0010000	64/32	100000-10FFFF	080000-087FFF	SA53	0110101	64/32	350000-35FFFF	1A8000–1AFFFF
SA17	0010001	64/32	110000-11FFFF	088000-08FFFF	SA54	0110110	64/32	360000-36FFFF	1B0000-1B7FFF
SA18	0010010	64/32	120000-12FFFF	090000-097FFF	SA55	0110111	64/32	370000-37FFFF	1B8000–1BFFFF
SA19	0010011	64/32	130000-13FFFF	098000-09FFFF	SA56	0111000	64/32	380000-38FFFF	1C0000-1C7FFF
SA20	0010100	64/32	140000-14FFFF	0A0000-0A7FFF	SA57	0111001	64/32	390000-39FFFF	1C8000-1CFFFF
SA21	0010101	64/32	150000-15FFFF	0A8000-0AFFFF	SA58	0111010	64/32	3A0000-3AFFFF	1D0000-1D7FFF
SA22	0010110	64/32	160000-16FFFF	0B0000-0B7FFF	SA59	0111011	64/32	3B0000-3BFFFF	1D8000–1DFFFF
SA23	0010111	64/32	170000-17FFFF	0B8000-0BFFFF	SA60	0111100	64/32	3C0000-3CFFFF	1E0000-1E7FFF
SA24	0011000	64/32	180000-18FFFF	0C0000-0C7FFF	SA61	0111101	64/32	3D0000-3DFFFF	1E8000–1EFFFF
SA25	0011001	64/32	190000-19FFFF	0C8000-0CFFFF	SA62	0111110	64/32	3E0000-3EFFFF	1F0000–1F7FFF
SA26	0011010	64/32	1A0000–1AFFFF	0D0000-0D7FFF	SA63	0111111	64/32	3F0000-3FFFFF	1F8000–1FFFFF
SA27	0011011	64/32	1B0000-1BFFFF	0D8000-0DFFFF	SA64	1000000	64/32	400000-40FFFF	200000-207FFF
SA28	0011100	64/32	1C0000-1CFFFF	0E0000-0E7FFF	SA65	1000001	64/32	410000-41FFFF	208000-20FFFF
SA29	0011101	64/32	1D0000-1DFFFF	0E8000-0EFFFF	SA66	1000010	64/32	420000-42FFFF	210000-217FFF
SA30	0011110	64/32	1E0000-1EFFFF	OF0000-OF7FFF	SA67	1000011	64/32	430000-43FFFF	218000-21FFFF
SA31	0011111	64/32	1F0000–1FFFFF	0F8000-0FFFFF	SA68	1000100	64/32	440000-44FFFF	220000-227FFF
SA32	0100000	64/32	200000-20FFFF	100000-107FFF	SA69	1000101	64/32	450000-45FFFF	228000-22FFFF
SA33	0100001	64/32	210000-21FFFF	108000-10FFFF	SA70	1000110	64/32	460000-46FFFF	230000-237FFF
SA34	0100010	64/32	220000-22FFFF	110000-117FFF	SA71	1000111	64/32	470000-47FFFF	238000-23FFFF
SA35	0100011	64/32	230000-23FFFF	118000-11FFFF	SA72	1001000	64/32	480000-48FFFF	240000-247FFF
SA36	0100100	64/32	240000-24FFFF	120000-127FFF	SA73	1001001	64/32	490000-49FFFF	248000-24FFFF



Sector	A21–A15	Sector Size (KB/ Kwords)	8-bit Address Range	16-bit Address Range	Sector	A21–A15	Sector Size (KB/ Kwords)	8-bit Address Range	16-bit Address Range
SA74	1001010	64/32	4A0000–4AFFFF	250000-257FFF	SA101	1100101	64/32	650000-65FFFF	328000-32FFFF
SA75	1001011	64/32	4B0000-4BFFFF	258000-25FFFF	SA102	1100110	64/32	660000-66FFFF	330000-337FFF
SA76	1001100	64/32	4C0000-4CFFFF	260000-267FFF	SA103	1100111	64/32	670000-67FFFF	338000-33FFFF
SA77	1001101	64/32	4D0000-4DFFFF	268000-26FFFF	SA104	1101000	64/32	680000-68FFFF	340000-347FFF
SA78	1001110	64/32	4E0000-4EFFFF	270000-277FFF	SA105	1101001	64/32	690000-69FFFF	348000-34FFFF
SA79	1001111	64/32	4F0000-4FFFFF	278000-27FFFF	SA106	1101010	64/32	6A0000-6AFFFF	350000-357FFF
SA80	1010000	64/32	500000-50FFFF	280000-287FFF	SA107	1101011	64/32	6B0000-6BFFFF	358000-35FFFF
SA81	1010001	64/32	510000-51FFFF	288000-28FFFF	SA108	1101100	64/32	6C0000-6CFFFF	360000-367FFF
SA82	1010010	64/32	520000-52FFFF	290000-297FFF	SA109	1101101	64/32	6D0000-6DFFFF	368000-36FFFF
SA83	1010011	64/32	530000-53FFFF	298000-29FFFF	SA110	1101110	64/32	6E0000-6EFFFF	370000-377FFF
SA84	1010100	64/32	540000-54FFFF	2A0000-2A7FFF	SA111	1101111	64/32	6F0000-6FFFFF	378000-37FFFF
SA85	1010101	64/32	550000-55FFFF	2A8000-2AFFFF	SA112	1110000	64/32	700000-70FFFF	380000-387FFF
SA86	1010110	64/32	560000-56FFFF	2B0000-2B7FFF	SA113	1110001	64/32	710000-71FFFF	388000-38FFFF
SA87	1010111	64/32	570000-57FFFF	2B8000-2BFFFF	SA114	1110010	64/32	720000-72FFFF	390000-397FFF
SA88	1011000	64/32	580000-58FFFF	2C0000-2C7FFF	SA115	1110011	64/32	730000-73FFFF	398000-39FFFF
SA89	1011001	64/32	590000-59FFFF	2C8000-2CFFFF	SA116	1110100	64/32	740000-74FFFF	3A0000-3A7FFF
SA90	1011010	64/32	5A0000-5AFFFF	2D0000-2D7FFF	SA117	1110101	64/32	750000-75FFFF	3A8000–3AFFFF
SA91	1011011	64/32	5B0000-5BFFFF	2D8000-2DFFFF	SA118	1110110	64/32	760000-76FFFF	3B0000-3B7FFF
SA92	1011100	64/32	5C0000-5CFFFF	2E0000-2E7FFF	SA119	1110111	64/32	770000-77FFFF	3B8000–3BFFFF
SA93	1011101	64/32	5D0000-5DFFFF	2E8000-2EFFFF	SA120	1111000	64/32	780000-78FFFF	3C0000-3C7FFF
SA94	1011110	64/32	5E0000-5EFFFF	2F0000-2F7FFF	SA121	1111001	64/32	790000-79FFFF	3C8000-3CFFFF
SA95	1011111	64/32	5F0000-5FFFFF	2F8000-2FFFFF	SA122	1111010	64/32	7A0000–7AFFFF	3D0000-3D7FFF
SA96	1100000	64/32	600000-60FFFF	300000-307FFF	SA123	1111011	64/32	7B0000–7BFFFF	3D8000-3DFFFF
SA97	1100001	64/32	610000-61FFFF	308000-30FFFF	SA124	1111100	64/32	7C0000-7CFFFF	3E0000-3E7FFF
SA98	1100010	64/32	620000-62FFFF	310000-317FFF	SA125	1111101	64/32	7D0000–7DFFFF	3E8000–3EFFFF
SA99	1100011	64/32	630000-63FFFF	318000-31FFFF	SA126	1111110	64/32	7E0000–7EFFFF	3F0000-3F7FFF
SA100	1100100	64/32	640000-64FFFF	320000-327FFF	SA127	1111111	64/32	7F0000–7FFFFF	3F8000-3FFFFF

Table 7.S29GL064A (Models RI, R2, R8, R9) Sector Addresses (Sheet 2 of 2)

 Table 8.
 S29GL064A (Model R3) Top Boot Sector Addresses (Sheet I of 2)

Sector	A21–A15	Sector Size (KB/ Kwords)	8-bit Address Range	16-bit Address Range	Sector	A21–A15	Sector Size (KB/ Kwords)	8-bit Address Range	16-bit Address Range
SA0	0000000xxx	64/32	000000h-00FFFFh	00000h-07FFFh	SA34	0100010xxx	64/32	220000h-22FFFFh	110000h-117FFFh
SA1	0000001xxx	64/32	010000h-01FFFFh	08000h-0FFFFh	SA35	0101011xxx	64/32	230000h-23FFFFh	118000h-11FFFFh
SA2	0000010xxx	64/32	020000h-02FFFFh	10000h-17FFFh	SA36	0100100xxx	64/32	240000h-24FFFFh	120000h-127FFFh
SA3	0000011xxx	64/32	030000h-03FFFFh	18000h-1FFFFh	SA37	0100101xxx	64/32	250000h-25FFFFh	128000h-12FFFFh
SA4	0000100xxx	64/32	040000h-04FFFFh	20000h-27FFFh	SA38	0100110xxx	64/32	260000h-26FFFFh	130000h-137FFFh
SA5	0000101xxx	64/32	050000h-05FFFFh	28000h-2FFFFh	SA39	0100111xxx	64/32	270000h-27FFFFh	138000h-13FFFFh
SA6	0000110xxx	64/32	060000h-06FFFFh	30000h-37FFFh	SA40	0101000xxx	64/32	280000h-28FFFFh	140000h-147FFFh
SA7	0000111xxx	64/32	070000h-07FFFFh	38000h-3FFFFh	SA41	0101001xxx	64/32	290000h-29FFFFh	148000h-14FFFFh
SA8	0001000xxx	64/32	080000h-08FFFFh	40000h-47FFFh	SA42	0101010xxx	64/32	2A0000h-2AFFFFh	150000h-157FFFh
SA9	0001001xxx	64/32	090000h-09FFFFh	48000h-4FFFFh	SA43	0101011xxx	64/32	2B0000h-2BFFFFh	158000h-15FFFFh
SA10	0001010xxx	64/32	0A0000h-0AFFFFh	50000h-57FFFh	SA44	0101100xxx	64/32	2C0000h-2CFFFFh	160000h-167FFFh
SA11	0001011xxx	64/32	0B0000h-0BFFFFh	58000h-5FFFFh	SA45	0101101xxx	64/32	2D0000h-2DFFFFh	168000h-16FFFFh
SA12	0001100xxx	64/32	0C0000h-0CFFFFh	60000h-67FFFh	SA46	0101110xxx	64/32	2E0000h-2EFFFFh	170000h-177FFFh
SA13	0001101xxx	64/32	0D0000h-0DFFFFh	68000h-6FFFFh	SA47	0101111xxx	64/32	2F0000h-2FFFFFh	178000h-17FFFFh
SA14	0001101xxx	64/32	0E0000h-0EFFFFh	70000h-77FFFh	SA48	0110000xxx	64/32	300000h-30FFFFh	180000h-187FFFh
SA15	0001111xxx	64/32	0F0000h-0FFFFFh	78000h-7FFFFh	SA49	0110001xxx	64/32	310000h-31FFFFh	188000h-18FFFFh
SA16	0010000xxx	64/32	100000h-00FFFFh	80000h-87FFFh	SA50	0110010xxx	64/32	320000h-32FFFFh	190000h-197FFFh
SA17	0010001xxx	64/32	110000h-11FFFFh	88000h-8FFFFh	SA51	0110011xxx	64/32	330000h-33FFFFh	198000h-19FFFFh
SA18	0010010xxx	64/32	120000h-12FFFFh	90000h-97FFFh	SA52	0100100xxx	64/32	340000h-34FFFFh	1A0000h-1A7FFFh
SA19	0010011xxx	64/32	130000h-13FFFFh	98000h-9FFFFh	SA53	0110101xxx	64/32	350000h-35FFFFh	1A8000h-1AFFFFh
SA20	0010100xxx	64/32	140000h-14FFFFh	A0000h-A7FFFh	SA54	0110110xxx	64/32	360000h-36FFFFh	1B0000h-1B7FFFh
SA21	0010101xxx	64/32	150000h-15FFFFh	A8000h–AFFFFh	SA55	0110111xxx	64/32	370000h-37FFFFh	1B8000h-1BFFFFh
SA22	0010110xxx	64/32	160000h-16FFFFh	B0000h-B7FFFh	SA56	0111000xxx	64/32	380000h-38FFFFh	1C0000h-1C7FFFh
SA23	0010111xxx	64/32	170000h-17FFFFh	B8000h-BFFFFh	SA57	0111001xxx	64/32	390000h-39FFFFh	1C8000h-1CFFFFh
SA24	0011000xxx	64/32	180000h-18FFFFh	C0000h-C7FFFh	SA58	0111010xxx	64/32	3A0000h-3AFFFFh	1D0000h-1D7FFFh
SA25	0011001xxx	64/32	190000h-19FFFFh	C8000h-CFFFFh	SA59	0111011xxx	64/32	3B0000h-3BFFFFh	1D8000h-1DFFFFh
SA26	0011010xxx	64/32	1A0000h-1AFFFFh	D0000h-D7FFFh	SA60	0111100xxx	64/32	3C0000h-3CFFFFh	1E0000h-1E7FFFh
SA27	0011011xxx	64/32	1B0000h-1BFFFFh	D8000h-DFFFFh	SA61	0111101xxx	64/32	3D0000h-3DFFFFh	1E8000h-1EFFFFh
SA28	0011000xxx	64/32	1C0000h-1CFFFFh	E0000h-E7FFFh	SA62	0111110xxx	64/32	3E0000h-3EFFFFh	1F0000h-1F7FFFh
SA29	0011101xxx	64/32	1D0000h-1DFFFFh	E8000h-EFFFFh	SA63	01111111xxx	64/32	3F0000h-3FFFFFh	1F8000h-1FFFFFh
SA30	0011110xxx	64/32	1E0000h-1EFFFFh	F0000h-F7FFFh	SA64	100000xxx	64/32	400000h-40FFFFh	200000h-207FFFh
SA31	0011111xxx	64/32	1F0000h-1FFFFFh	F8000h-FFFFFh	SA65	1000001xxx	64/32	410000h-41FFFFh	208000h-20FFFFh
SA32	010000xxx	64/32	200000h-20FFFFh	F9000h-107FFFh	SA66	1000010xxx	64/32	420000h-42FFFFh	210000h-217FFFh
SA33	0100001xxx	64/32	210000h-21FFFFh	108000h-10FFFFh	SA67	1000011xxx	64/32	430000h-43FFFFh	218000h-21FFFFh

		Sector					Sector		· · · · · · · · · · · · · · · · · · ·
Sector	A21–A15	Size (KB/ Kwords)	8-bit Address Range	16-bit Address Range	Sector	A21–A15	Size (KB/ Kwords)	8-bit Address Range	16-bit Address Range
SA68	1000100xxx	64/32	440000h-44FFFFh	220000h-227FFFh	SA102	1100110xxx	64/32	660000h-66FFFFh	330000h-337FFFh
SA69	1000101xxx	64/32	450000h-45FFFFh	228000h-22FFFFh	SA103	1100111xxx	64/32	670000h-67FFFh	338000h-33FFFFh
SA70	1000110xxx	64/32	460000h-46FFFFh	230000h-237FFFh	SA104	1101000xxx	64/32	680000h-68FFFFh	340000h-347FFFh
SA71	1000111xxx	64/32	470000h-47FFFFh	238000h-23FFFFh	SA105	1101001xxx	64/32	690000h-69FFFFh	348000h-34FFFFh
SA72	1001000xxx	64/32	480000h-48FFFFh	240000h-247FFFh	SA106	1101010xxx	64/32	6A0000h-6AFFFFh	350000h-357FFFh
SA73	1001001xxx	64/32	490000h-49FFFFh	248000h-24FFFFh	SA107	1101011xxx	64/32	6B0000h-6BFFFFh	358000h-35FFFFh
SA74	1001010xxx	64/32	4A0000h-4AFFFFh	250000h-257FFFh	SA108	1101100xxx	64/32	6C0000h-6CFFFh	360000h-367FFFh
SA75	1001011xxx	64/32	4B0000h-4BFFFFh	258000h-25FFFFh	SA109	1101101xxx	64/32	6D0000h-6DFFFFh	368000h-36FFFFh
SA76	1001100xxx	64/32	4C0000h-4CFFFFh	260000h-267FFFh	SA110	1101110xxx	64/32	6E0000h-6EFFFFh	370000h-377FFFh
SA77	1001101xxx	64/32	4D0000h-4DFFFFh	268000h-26FFFFh	SA111	1101111xxx	64/32	6F0000h-6FFFFFh	378000h-37FFFFh
SA78	1001110xxx	64/32	4E0000h-4EFFFFh	270000h-277FFFh	SA112	1110000xxx	64/32	700000h-70FFFFh	380000h-387FFFh
SA79	1001111xxx	64/32	4F0000h-4FFFFFh	278000h-27FFFFh	SA113	1110001xxx	64/32	710000h-71FFFFh	388000h-38FFFFh
SA80	1010000xxx	64/32	500000h-50FFFFh	280000h-28FFFFh	SA114	1110010xxx	64/32	720000h-72FFFFh	390000h-397FFFh
SA81	1010001xxx	64/32	510000h-51FFFFh	288000h-28FFFFh	SA115	1110011xxx	64/32	730000h-73FFFFh	398000h-39FFFFh
SA82	1010010xxx	64/32	520000h-52FFFFh	290000h-297FFFh	SA116	1110100xxx	64/32	740000h-74FFFFh	3A0000h-3A7FFFh
SA83	1010011xxx	64/32	530000h-53FFFFh	298000h-29FFFFh	SA117	1110101xxx	64/32	750000h-75FFFFh	3A8000h-3AFFFFh
SA84	1010100xxx	64/32	540000h-54FFFFh	2A0000h-2A7FFFh	SA118	1110110xxx	64/32	760000h-76FFFFh	3B0000h-3B7FFFh
SA85	1010101xxx	64/32	550000h-55FFFFh	2A8000h-2AFFFFh	SA119	1110111xxx	64/32	770000h-77FFFFh	3B8000h-3BFFFFh
SA86	1010110xxx	64/32	560000h-56FFFFh	2B0000h-2B7FFFh	SA120	1111000xxx	64/32	780000h-78FFFFh	3C0000h-3C7FFFh
SA87	1010111xxx	64/32	570000h-57FFFFh	2B8000h-2BFFFFh	SA121	1111001xxx	64/32	790000h-79FFFFh	3C8000h-3CFFFFh
SA88	1011000xxx	64/32	580000h-58FFFFh	2C0000h-2C7FFFh	SA122	1111010xxx	64/32	7A0000h-7AFFFFh	3D0000h-3D7FFFh
SA89	1011001xxx	64/32	590000h-59FFFFh	2C8000h-2CFFFFh	SA123	1111011xxx	64/32	7B0000h-7BFFFFh	3D8000h-3DFFFFh
SA90	1011010xxx	64/32	5A0000h-5AFFFFh	2D0000h-2D7FFFh	SA124	1111100xxx	64/32	7C0000h-7CFFFFh	3E0000h-3E7FFFh
SA91	1011011xxx	64/32	5B0000h-5BFFFFh	2D8000h-2DFFFFh	SA125	1111101xxx	64/32	7D0000h-7DFFFFh	3E8000h-3EFFFFh
SA92	1011100xxx	64/32	5C0000h-5CFFFFh	2E0000h-2E7FFFh	SA126	1111110xxx	64/32	7E0000h-7EFFFFh	3F0000h-3F7FFFh
SA93	1011101xxx	64/32	5D0000h-5DFFFFh	2E8000h-2EFFFFh	SA127	1111111000	8/4	7F0000h-7F1FFFh	3F8000h-3F8FFFh
SA94	1011110xxx	64/32	5E0000h-5EFFFFh	2F0000h-2FFFFFh	SA128	1111111001	8/4	7F2000h-7F3FFFh	3F9000h-3F9FFFh
SA95	1011111xxx	64/32	5F0000h-5FFFFFh	2F8000h-2FFFFFh	SA129	1111111010	8/4	7F4000h-7F5FFFh	3FA000h-3FAFFFh
SA96	1100000xxx	64/32	600000h-60FFFFh	300000h-307FFFh	SA130	1111111011	8/4	7F6000h-7F7FFFh	3FB000h-3FBFFFh
SA97	1100001xxx	64/32	610000h-61FFFFh	308000h-30FFFFh	SA131	1111111100	8/4	7F8000h-7F9FFFh	3FC000h-3FCFFFh
SA98	1100010xxx	64/32	620000h-62FFFFh	310000h-317FFFh	SA132	1111111101	8/4	7FA000h-7FBFFFh	3FD000h-3FDFFFh
SA99	1100011xxx	64/32	630000h-63FFFFh	318000h-31FFFFh	SA133	1111111110	8/4	7FC000h-7FDFFFh	3FE000h-3FEFFFh
SA100	1100100xxx	64/32	640000h-64FFFFh	320000h-327FFFh	SA134	11111111111	8/4	7FE000h-7FFFFFh	3FF000h-3FFFFFh
SA101	1100101xxx	64/32	650000h-65FFFFh	328000h-32FFFFh					

 Table 8.
 S29GL064A (Model R3) Top Boot Sector Addresses (Sheet 2 of 2)

Table 9. S29GL064A (Model R4) Bottom Boot Sector Addresses (Sheet I of 2	Table 9.	S29GL064A	(Model R4)	Bottom Boot Sector	Addresses	(Sheet I of 2)
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Sector	A21–A15	Sector Size (KB/ Kwords)	8-bit Address Range	16-bit Address Range	Sector	A21–A15	Sector Size (KB/ Kwords)	8-bit Address Range	16-bit Address Range
SA0	000000000	8/4	000000h-001FFFh	00000h-00FFFh	SA27	0010100xxx	64/32	140000h-14FFFFh	A0000h-A7FFFh
SA1	000000001	8/4	002000h-003FFFh	01000h-01FFFh	SA28	0010101xxx	64/32	150000h-15FFFFh	A8000h–AFFFFh
SA2	000000010	8/4	004000h-005FFFh	02000h-02FFFh	SA29	0010110xxx	64/32	160000h-16FFFFh	B0000h-B7FFFh
SA3	000000011	8/4	006000h-007FFFh	03000h-03FFFh	SA30	0010111xxx	64/32	170000h-17FFFFh	B8000h-BFFFFh
SA4	000000100	8/4	008000h-009FFFh	04000h-04FFFh	SA31	0011000xxx	64/32	180000h-18FFFFh	C0000h-C7FFFh
SA5	000000101	8/4	00A000h-00BFFFh	05000h-05FFFh	SA32	0011001xxx	64/32	190000h-19FFFFh	C8000h–CFFFFh
SA6	000000110	8/4	00C000h-00DFFFh	06000h-06FFFh	SA33	0011010xxx	64/32	1A0000h-1AFFFFh	D0000h-D7FFFh
SA7	000000111	8/4	00E000h-00FFFFFh	07000h-07FFFh	SA34	0011011xxx	64/32	1B0000h-1BFFFFh	D8000h-DFFFFh
SA8	0000001xxx	64/32	010000h-01FFFFh	08000h-0FFFFh	SA35	0011000xxx	64/32	1C0000h-1CFFFFh	E0000h-E7FFFh
SA9	0000010xxx	64/32	020000h-02FFFFh	10000h-17FFFh	SA36	0011101xxx	64/32	1D0000h-1DFFFFh	E8000h-EFFFFh
SA10	0000011xxx	64/32	030000h-03FFFFh	18000h-1FFFFh	SA37	0011110xxx	64/32	1E0000h-1EFFFFh	F0000h-F7FFFh
SA11	0000100xxx	64/32	040000h-04FFFFh	20000h-27FFFh	SA38	0011111xxx	64/32	1F0000h-1FFFFFh	F8000h-FFFFFh
SA12	0000101xxx	64/32	050000h-05FFFFh	28000h-2FFFFh	SA39	0100000xxx	64/32	200000h-20FFFFh	F9000h-107FFFh
SA13	0000110xxx	64/32	060000h-06FFFFh	30000h-37FFFh	SA40	0100001xxx	64/32	210000h-21FFFFh	108000h-10FFFFh
SA14	0000111xxx	64/32	070000h-07FFFFh	38000h-3FFFFh	SA41	0100010xxx	64/32	220000h-22FFFFh	110000h-117FFFh
SA15	0001000xxx	64/32	080000h-08FFFFh	40000h-47FFFh	SA42	0101011xxx	64/32	230000h-23FFFFh	118000h-11FFFFh
SA16	0001001xxx	64/32	090000h-09FFFFh	48000h-4FFFFh	SA43	0100100xxx	64/32	240000h-24FFFFh	120000h-127FFFh
SA17	0001010xxx	64/32	0A0000h-0AFFFFh	50000h-57FFFh	SA44	0100101xxx	64/32	250000h-25FFFFh	128000h-12FFFFh
SA18	0001011xxx	64/32	0B0000h-0BFFFFh	58000h-5FFFFh	SA45	0100110xxx	64/32	260000h-26FFFFh	130000h-137FFFh
SA19	0001100xxx	64/32	0C0000h-0CFFFFh	60000h-67FFFh	SA46	0100111xxx	64/32	270000h-27FFFFh	138000h-13FFFFh
SA20	0001101xxx	64/32	0D0000h-0DFFFFh	68000h-6FFFFh	SA47	0101000xxx	64/32	280000h-28FFFFh	140000h-147FFFh
SA21	0001101xxx	64/32	0E0000h-0EFFFFh	70000h-77FFFh	SA48	0101001xxx	64/32	290000h-29FFFFh	148000h-14FFFFh
SA22	0001111xxx	64/32	0F0000h-0FFFFFh	78000h-7FFFFh	SA49	0101010xxx	64/32	2A0000h-2AFFFFh	150000h-157FFFh
SA23	0010000xxx	64/32	100000h-00FFFFh	80000h-87FFFh	SA50	0101011xxx	64/32	2B0000h-2BFFFFh	158000h-15FFFFh
SA24	0010001xxx	64/32	110000h-11FFFFh	88000h-8FFFFh	SA51	0101100xxx	64/32	2C0000h-2CFFFFh	160000h-167FFFh
SA25	0010010xxx	64/32	120000h-12FFFFh	90000h-97FFFh	SA52	0101101xxx	64/32	2D0000h-2DFFFFh	168000h-16FFFFh
SA26	0010011xxx	64/32	130000h-13FFFFh	98000h–9FFFFh	SA53	0101110xxx	64/32	2E0000h-2EFFFFh	170000h-177FFFh

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Table 9.	S29GL064A	(Model R4)) Bottom Boot S	Sector Addresses	(Sheet 2 of 2))
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δ (Kb) Kwords) Range Range δ (Kb) Kwords/ (Kb) Range Range Range SA55 0101111xxx 64/32 20000h-2FFFFF 178000h-17FFFFh SA95 1011001xx 64/32 58000h-58FFFFF 2C8000h-2C7 SA55 011001xx 64/32 30000h-38FFFF 188000h-18FFFFh SA97 101101xx 64/32 50000h-58FFFF 120800h-22F SA55 0110011xx 64/32 330000h-38FFFF 198000h-19FFFh SA99 101110xx 64/32 50000h-58FFFF 120800h-22F SA60 0110011xx 64/32 330000h-38FFFF 18000h-187FFFh SA10 1011110xx 64/32 50000h-58FFFF 2E0000h-22F SA61 0110101xx 64/32 380000h-38FFFF 140000h-187FFFh SA102 1011110xx 64/32 50000h-58FFFF 2E0000h-22F SA62 0110101xx 64/32 380000h-38FFFF 120000h-187FFFh SA102 101110xx 64/32 50000h-58FFFF 2E0000h-22F SA63 0111001xx 64/32			Contor					Contor		
SA55 0110000xxx 64/32 30000h-30FFFFh 18000h-18FFFFh SA96 1011010xxx 64/32 50000h-S0FFFFh 20000h-20F SA56 0110010xxx 64/32 30000h-32FFFFh 18000h-19FFFFh SA97 101101xxx 64/32 50000h-50FFFFh 20000h-20F SA57 0110010xxx 64/32 30000h-34FFFFh 19000h-19FFFFh SA99 101110xxx 64/32 50000h-52FFFFh 228000h-22F SA60 011010xx 64/32 30000h-34FFFFh 18000h-14FFFFh SA101 101110xxx 64/32 55000h-52FFFFh 228000h-22F SA61 011010xx 64/32 350000h-37FFFh 18000h-18FFFFh SA101 101111xxx 64/32 55000h-52FFFFh 28000h-38 SA63 011101xxx 64/32 38000h-38FFFFh 18000h-18FFFFh SA103 110000xxx 64/32 60000h-62FFFFh 38000h-38 SA64 011101xxx 64/32 38000h-38FFFFFh 18000h-18FFFFh SA100 110100xxx 64/32 60000h-62FFFFh 380000h-38FFFFFh 38000h-38FFFFFh	Sector	A21–A15	Size (KB/ Kwords)	Address Range	Address Range		-	Size (KB/ Kwords)	Address Range	Address Range
SA56 011001xxx 64/32 31000h-32FFFFh 18000h-187FFFh SA97 101101xxx 64/32 58000h-54FFFh 20000h-207 SA57 0110011xxx 64/32 33000h-33FFFFh 19000h-197FFFh SA99 101110xxx 64/32 550000h-55FFFFh 2E8000h-22F SA58 010101xxx 64/32 330000h-33FFFFh 18000h-197FFFh SA100 101110xxx 64/32 550000h-55FFFFh 2E8000h-22F SA60 011011xxx 64/32 30000h-37FFFFh 18000h-187FFFh SA100 101110xxx 64/32 55000h-5FFFFh 2E8000h-22F SA61 011011xxx 64/32 30000h-37FFFFh 18000h-187FFFh SA101 1101010xxx 64/32 60000h-6FFFFh 28000h-32F SA63 011001xx 64/32 30000h-38FFFFh 12000h-17FFFh SA103 110000xxx 64/32 60000h-6FFFFh 38000h-39F SA63 011101xxx 64/32 30000h-38FFFFh 12000h-27FFFh SA10 11001xxx 64/32 60000h-6FFFFH 38000h-33F SA64		0101111xxx					1011000xxx			2C0000h-2C7FFFh
SA57 0110010xxx 64/32 32000h-32FFFFh 19000h-19FFFFh SA98 1011011xxx 64/32 55000h-56FFFh 25000h-22F SA58 0110011xxx 64/32 330000h-33FFFFh 198000h-147FFFh SA99 101110xxx 64/32 550000h-56FFFFh 25000h-22F SA60 0110101xxx 64/32 350000h-36FFFFh 18000h-147FFFh SA101 1011110xxx 64/32 55000h-56FFFFh 25000h-22F SA61 011010xxx 64/32 350000h-36FFFFh 18000h-117FFFh SA101 101110xxx 64/32 65000h-56FFFFh 25000h-32F SA63 0111001xxx 64/32 38000h-38FFFFh 126000h-12FFFh SA104 110000xxx 64/32 63000h-36FFFFh 38000h-38F SA64 011101xxx 64/32 380000h-38FFFFh 12600h-12FFFh SA104 110001xxx 64/32 63000h-63FFFFh 38000h-33F SA64 011101xxx 64/32 30000h-38FFFFFh 12600h-12FFFh SA104 110010xxx 64/32 63000h-63FFFFh 38000h-33F <td< td=""><td>SA55</td><td>0110000xxx</td><td></td><td></td><td>180000h-187FFFh</td><td></td><td></td><td></td><td></td><td>2C8000h-2CFFFFh</td></td<>	SA55	0110000xxx			180000h-187FFFh					2C8000h-2CFFFFh
SA58 0110011xxx 64/32 330000h-33FFFFh 149000h-19FFFFh SA09 1011100xxx 64/32 SC0000h-SCFFFFh 2E8000h-2EF SA60 0110101xxx 64/32 350000h-33FFFFh 1A8000h-1A7FFFh SA1001 1011110xxx 64/32 550000h-SCFFFFh 2E8000h-2EF SA60 011011xxx 64/32 350000h-33FFFFh 180000h-1B7FFFFh SA101 1101111xxx 64/32 550000h-SCFFFFh 2E8000h-2FF SA63 011100xxx 64/32 380000h-33FFFFh 18000h-1CFFFFh SA103 110001xxx 64/32 610000h-61FFFh 30000h-33FFFFh SA64 011101xx 64/32 380000h-33FFFFh 18000h-1CFFFFh SA106 110001xxx 64/32 620000h-62FFFFh 30000h-33FFFFh SA65 011101xxx 64/32 380000h-33FFFFh 18000h-1EFFFFh SA106 110010xxx 64/32 660000h-66FFFFh 30000h-33F SA66 011101xxx 64/32 30000h-33FFFFh 18000h-2FFFF SA106 110010xxx 64/32 660000h-66FFFFh 38000h-33F	SA56	0110001xxx			188000h-18FFFFh					2D0000h-2D7FFFh
SA59 0100100xx 64/32 34000h-34FFFFh 1A0000h-1A7FFFh SA100 1011111xxx 64/32 5D000h-5EFFFh 2E800h-2EF SA60 011010xxx 64/32 350000h-35FFFFh 1B8000h-1AFFFFh SA101 1011111xxx 64/32 5E0000h-5FFFFFh 2F8000h-2FF SA61 011010xxx 64/32 370000h-37FFFFh 1B8000h-1BFFFFh SA102 1011111xxx 64/32 60000h-6FFFFFh 30000h-30F SA63 0111001xxx 64/32 380000h-33FFFFh 1C8000h-1CFFFFh SA104 110001xxx 64/32 62000h-62FFFFh 30000h-30F SA64 0111011xxx 64/32 380000h-33FFFFh 1C8000h-1CFFFFh SA107 110011xx 64/32 630000h-63FFFFh 30000h-33F SA66 0111011xx 64/32 30000h-33FFFFh 126000h-12FFFh SA107 110011xx 64/32 650000h-63FFFFh 30000h-33F SA60 011101xx 64/32 30000h-33FFFFh 12600h-12FFFh SA107 1100101xx 64/32 650000h-63FFFFh 30000h-33F	SA57	0110010xxx			190000h-197FFFh	SA98	1011011xxx		5B0000h-5BFFFFh	2D8000h-2DFFFFh
SA60 0110101xxx 64/32 35000h-35FFFFh 148000h-18FFFFh SA101 1011110xxx 64/32 35000h-3FFFFFh 278000h-2FF SA61 011011xxx 64/32 360000h-36FFFFh 180000h-18FFFFh SA102 1011111xxx 64/32 550000h-3FFFFFh 278000h-37FFFFh 110000xxx 64/32 600000h-0FFFFh 300000h-30F SA64 0111001xxx 64/32 30000h-33FFFFh 118000h-1CFFFFh SA105 110001xxx 64/32 630000h-63FFFFh 30000h-30F SA65 011101xxx 64/32 30000h-33FFFFh 118000h-1CFFFFh SA106 1100011xxx 64/32 63000h-63FFFFh 32000h-327 SA66 011101xxx 64/32 30000h-33FFFFh 18000h-1EFFFFh SA108 110011xxx 64/32 66000h-63FFFFh 32000h-337 SA67 0111110xx 64/32 30000h-33FFFFh 18000h-1EFFFFh SA110 1100101xx 64/32 66000h-63FFFFh 33000h-337 SA70 0111110xx 64/32 30000h-33FFFFFh 18000h-27FFFh SA110 1100101										2E0000h-2E7FFFh
SA61 0110110xxx 64/32 36000h-36FFFFh 18000h-187FFFh SA102 101111xxx 64/32 56000h-58FFFFh 278000h-37 SA63 011011xxx 64/32 30000h-387FFFh 110000xx 64/32 60000h-68FFFFh 30000h-307 SA64 0111001xxx 64/32 30000h-387FFFh 110000h-127FFFh SA104 110001xxx 64/32 63000h-68FFFFh 308000h-307 SA65 0111011xxx 64/32 30000h-38FFFFh 10000h-127FFFh SA104 110001xxx 64/32 63000h-68FFFFh 30000h-377 SA66 0111011xxx 64/32 30000h-38FFFFh 10000h-127FFFh SA107 110010xxx 64/32 66000h-68FFFFh 32000h-327 SA67 0111110xx 64/32 30000h-36FFFFh 15000h-17FFFFh SA100 1100110xx 64/32 66000h-68FFFFh 32000h-337 SA67 0111110xx 64/32 30000h-36FFFFh 15000h-17FFFFh SA110 1100110xx 64/32 68000h-68FFFFh 32000h-337 SA70 0111110xx 64/32 <td>SA59</td> <td></td> <td></td> <td></td> <td></td> <td>SA100</td> <td>1011101xxx</td> <td></td> <td>5D0000h-5DFFFFh</td> <td>2E8000h-2EFFFFh</td>	SA59					SA100	1011101xxx		5D0000h-5DFFFFh	2E8000h-2EFFFFh
SA62 0110111xxx 64/32 370000h-37FFFFh 1B8000h-1BFFFFh SA103 110000xxx 64/32 60000h-60FFFFh 30000n-307 SA64 0111001xxx 64/32 380000h-38FFFFh 1C0000h-1CFFFFh SA105 1100010xxx 64/32 63000h-63FFFFh 308000h-37F SA64 011101xxx 64/32 380000h-38FFFFh 1D000h-1D7FFFh SA106 110001xxx 64/32 63000h-63FFFFh 318000h-37F SA65 011101xxx 64/32 380000h-38FFFFh 1D8000h-1D7FFFh SA108 110011xxx 64/32 640000h-63FFFFh 328000h-32F SA67 011110xxx 64/32 380000h-32FFFFh 1E8000h-1E7FFFh SA109 110011xxx 64/32 660000h-63FFFFh 338000h-337 SA69 0111111xxx 64/32 38000h-34FFFFh SA100 110100xxx 64/32 660000h-63FFFFh 338000h-337 SA70 0111111xxx 64/32 38000h-34FFFFh SA110 1101000xxx 64/32 680000h-63FFFFh 338000h-34F SA71 1000001xxx	SA60	0110101xxx	64/32	350000h-35FFFFh	1A8000h-1AFFFFh	SA101	1011110xxx	64/32	5E0000h-5EFFFFh	2F0000h-2FFFFFh
SA63 0111000xxx 64/32 380000h-38FFFh 1C0000h-107FFFh SA104 110001xxx 64/32 61000h-62FFFFh 30000h-39FFFh SA64 0111001xxx 64/32 30000h-39FFFh 1C8000h-107FFFh SA106 1100011xxx 64/32 63000h-62FFFFh 310000h-37F SA65 0111010xxx 64/32 30000h-37FFFh 1E8000h-10FFFFh SA107 1100101xxx 64/32 66000h-64FFFFh 320000h-337 SA67 0111101xxx 64/32 30000h-37FFFh 1E8000h-116FFFFh SA109 1100110xxx 64/32 66000h-65FFFFh 32000h-337 SA69 0111110xxx 64/32 30000h-37FFFFh 18000h-116FFFFh SA109 1100110xxx 64/32 66000h-66FFFFh 33000h-337 SA70 0111111xx 64/32 30000h-37FFFh 18000h-207FFFh SA112 1101010xx 64/32 68000h-68FFFFh 34000h-347 SA71 1000001xxx 64/32 40000h-41FFFh 20000h-207FFFh SA113 110101xx 64/32 68000h-68FFFFh 34000h-347	SA61	0110110xxx				SA102	10111111xxx			2F8000h-2FFFFFh
SA64 0111001xxx 64/32 39000h-39FFFh 10800h-1CFFFFh SA105 110001xxx 64/32 62000h-62FFFFh 31000h-317 SA65 0111001xxx 64/32 30000h-38FFFh 10000h-1DFFFFh SA107 110010xxx 64/32 63000h-63FFFFh 318000h-32F SA67 0111101xxx 64/32 30000h-32FFFFh IS000h-12FFFFh SA107 110010xxx 64/32 66000h-65FFFFh 33000h-32F SA67 011110xxx 64/32 30000h-32FFFFh IE8000h-1EFFFFFh SA109 1100110xxx 64/32 66000h-65FFFFh 33000h-33F SA69 0111110xxx 64/32 30000h-37FFFh IE8000h-17FFFFh SA110 1101011xxx 64/32 68000h-68FFFFh 330000h-33F SA70 011111xx 64/32 30000h-37FFFh IE8000h-20FFFFh SA111 1101001xxx 64/32 68000h-68FFFFh 34000h-33F SA71 1000001xxx 64/32 40000h-44FFFFh 20000h-20FFFFh SA113 1101001xxx 64/32 68000h-68FFFFh 34000h-33F <		0110111xxx			1B8000h-1BFFFFh				600000h-60FFFFh	300000h-307FFFh
SA65 0111010xxx 64/32 3A0000h-3AFFFFh 1D0000h-1D7FFFh SA106 110011xxx 64/32 630000h-3FFFFh 318000h-3F SA66 0111011xxx 64/32 3B0000h-3BFFFFh 1D0000h-1DFFFFh SA107 1100100xxx 64/32 640000h-3FFFFh 32000h-327 SA67 0111100xxx 64/32 3D0000h-3DFFFFh 1B000h-1FFFFFh SA109 1100110xxx 64/32 660000h-6FFFFh 33000h-337 SA69 0111110xxx 64/32 3E0000h-3EFFFFh 1F0000h-1FFFFFh SA110 1100110xxx 64/32 670000h-6FFFFh 330000h-337 SA70 0111111xxx 64/32 3E0000h-3FFFFh 1F0000h-1FFFFh SA111 1101001xxx 64/32 69000h-68FFFFh 34000h-347 SA71 1000001xxx 64/32 400000h-41FFFh 20000h-20FFFh SA111 1101001xxx 64/32 69000h-68FFFFh 34000h-347 SA72 1000011xxx 64/32 42000h-44FFFFh 20000h-27FFFh SA113 1101011xx 64/32 600000h-68FFFFh 360000h-377	SA63	0111000xxx	64/32			SA104	1100001xxx		610000h-61FFFFh	308000h-30FFFFh
SA66 0111011xxx 64/32 3B000h-3BFFFh 1D8000h-1DFFFh SA107 1100100xxx 64/32 64000h-64FFFFh 32000h-32F SA67 0111100xxx 64/32 3C0000h-3CFFFFh 1E0000h-1E7FFFh SA108 1100110xxx 64/32 650000h-63FFFFh 320000h-32F SA68 0111110xxx 64/32 3D000h-3EFFFFh 1E0000h-1E7FFFh SA110 1100111xxx 64/32 66000h-67FFFFh 33000h-337 SA69 01111110xxx 64/32 3E0000h-3EFFFFh 1E0000h-1FFFFFh SA110 1100111xxx 64/32 68000h-68FFFFh 33000h-347 SA71 1000001xxx 64/32 410000h-41FFFFh 20000h-20FFFFh SA112 1101010xx 64/32 68000h-68FFFFh 35000h-35F SA73 1000011xxx 64/32 410000h-43FFFFh 210000h-21FFFh SA111 110101xx 64/32 6B000h-68FFFFh 35000h-35F SA74 1000010xxx 64/32 420000h-43FFFFh 210000h-22FFFFh SA111 110110xx 64/32 6D000h-68FFFFh 36000h-36F	SA64			390000h-39FFFFh	1C8000h-1CFFFFh	SA105			620000h-62FFFFh	310000h-317FFFh
SA67 0111100xxx 64/32 3C0000h-3CFFFFh 1E0000h-1E7FFFh SA108 1100101xxx 64/32 650000h-65FFFFh 328000h-32F SA69 0111101xxx 64/32 3D0000h-33FFFFh 1E8000h-1E7FFFh SA109 1100110xxx 64/32 660000h-66FFFFh 338000h-33F SA70 0111111xx 64/32 3E0000h-3FFFFh 1F0000h-1F7FFFh SA110 1100111xxx 64/32 680000h-68FFFFh 338000h-34F SA71 10000001xx 64/32 400000h-40FFFFh 20000h-207FFFh SA111 1101010xxx 64/32 680000h-68FFFFh 34000h-34F SA73 1000010xx 64/32 40000h-44FFFFh 20000h-207FFFh SA111 110101xxx 64/32 680000h-68FFFFh 38000h-35F SA73 1000010xx 64/32 43000h-43FFFFh 218000h-22FFFFh SA115 1101101xxx 64/32 60000h-6DFFFFh 38000h-35F SA74 1000101xxx 64/32 440000h-44FFFFh 22000h-237FFFh SA116 1101111xxx 64/32 60000h-6DFFFFh 38000h-35F	SA65	0111010xxx	64/32	3A0000h-3AFFFFh	1D0000h-1D7FFFh	SA106			630000h-63FFFFh	318000h-31FFFFh
SA68 0111101xxx 64/32 3D000h-3DFFFFh 1E8000h-1EFFFFh SA109 1100110xxx 64/32 66000h-66FFFh 33000h-337 SA69 0111110xxx 64/32 3E0000h-3EFFFFh 1F0000h-1F7FFFh SA110 1100011xxx 64/32 670000h-67FFFh 38000h-347 SA71 1000001xxx 64/32 40000h-40FFFh SA111 1101001xx 64/32 680000h-68FFFFh 340000h-347 SA72 1000001xxx 64/32 410000h-41FFFFh 20000h-20FFFh SA111 110101xx 64/32 680000h-68FFFFh 35000h-357 SA73 1000011xx 64/32 420000h-42FFFFh 210000h-217FFFh SA114 1101010xx 64/32 66000h-68FFFFh 35000h-357 SA73 1000010xxx 64/32 43000h-43FFFFh 218000h-217FFFh SA115 110110xx 64/32 60000h-60FFFFh 36000h-367 SA75 100010xxx 64/32 440000h-44FFFFh 22000h-227FFFh SA116 1101101xx 64/32 6E0000h-60FFFFh 38000h-367 SA76 100	SA66	0111011xxx	64/32	3B0000h-3BFFFFh	1D8000h-1DFFFFh	SA107			640000h-64FFFFh	320000h-327FFFh
SA69 0111110xxx 64/32 3E0000h-3EFFFFh 1F0000h-1F7FFFh SA110 1100111xxx 64/32 670000h-67FFFFh 33800h-33F SA71 100000xxx 64/32 3F0000h-3FFFFFFh 1F8000h-1FFFFFh SA111 110100xxx 64/32 680000h-68FFFFh 340000h-347 SA71 1000001xxx 64/32 400000h-40FFFFh 20000h-207FFFh SA113 110101xxx 64/32 680000h-68FFFFh 348000h-347 SA73 100001xxx 64/32 40000h-41FFFFh 20800h-207FFFh SA114 110101xx 64/32 680000h-68FFFFh 358000h-35F SA73 1000011xx 64/32 420000h-43FFFFh 218000h-217FFFh SA114 1101011xx 64/32 660000h-68FFFFh 35800h-35F SA75 1000101xxx 64/32 430000h-43FFFFh 22000h-227FFFh SA115 1101101xx 64/32 660000h-66FFFFh 36000h-377 SA75 1000110xxx 64/32 450000h-45FFFFh 228000h-23FFFFh SA117 1101110xxx 64/32 660000h-6FFFFFh 38000h-387	SA67	0111100xxx			1E0000h-1E7FFFh				650000h-65FFFFh	328000h-32FFFFh
SA70 0111111xxx 64/32 3F000h-3FFFFh 1F800h-1FFFFh SA111 1101000xxx 64/32 68000h-68FFFFh 34000h-347 SA71 1000000xx 64/32 40000h-40FFFh 20000h-207FFFh SA112 1101011xxx 64/32 69000h-68FFFFh 34000h-34F SA72 1000011xxx 64/32 41000h-41FFFh 20800h-20FFFh SA113 110101xxx 64/32 6A000h-68FFFFh 35000h-35F SA73 1000011xxx 64/32 42000h-42FFFFh 21800h-21FFFh SA114 1101101xxx 64/32 6C000h-60FFFFh 36000h-36F SA74 1000101xx 64/32 43000h-43FFFh 21800h-22FFFh SA114 110110xxx 64/32 6D000h-60FFFFh 36000h-36F SA75 1000100xx 64/32 45000h-45FFFh 22800h-22FFFh SA117 110110xx 64/32 6D000h-60FFFFh 36000h-36F SA75 1000101xx 64/32 46000h-45FFFFh 228000h-22FFFh SA117 110110xx 64/32 70000h-70FFFh 378000h-37F SA73	SA68	0111101xxx	64/32	3D0000h-3DFFFFh	1E8000h-1EFFFFh	SA109	1100110xxx	64/32	660000h-66FFFFh	330000h-337FFFh
SA71 100000xxx 64/32 40000h-40FFFFh 20000h-207FFFh SA112 110101xx 64/32 69000h-69FFFFh 34800h-34F SA72 100001xxx 64/32 41000h-41FFFFh 20800h-20FFFFh SA113 110101xx 64/32 6A000h-6AFFFFh 35000h-357 SA73 1000010xxx 64/32 42000h-43FFFFh 21800h-21FFFFh SA114 1101011xx 64/32 6C000h-6AFFFFh 35800h-357 SA75 100010xxx 64/32 43000h-43FFFFh 218000h-227FFFh SA115 1101101xx 64/32 6C000h-6EFFFFh 36000h-367 SA75 1000101xx 64/32 45000h-45FFFh 228000h-227FFFh SA117 1101101xx 64/32 6E000h-6EFFFFh 36000h-367 SA75 100011xx 64/32 46000h-46FFFFh 238000h-23FFFh SA118 1101111xx 64/32 6F000h-6FFFFh 37800h-377 SA77 100010xx 64/32 48000h-48FFFFh 238000h-23FFFFh SA119 110000xx 64/32 70000h-70FFFFh 38000h-387 SA79	SA69	0111110xxx	64/32	3E0000h-3EFFFFh	1F0000h-1F7FFFh	SA110	1100111xxx	64/32	670000h-67FFFFh	338000h-33FFFFh
SA72 100001xxx 64/32 41000h-41FFFh 20800h-20FFFh SA113 110101xxx 64/32 6A000h-6AFFFFh 35000h-357 SA73 1000010xxx 64/32 42000h-42FFFh 21000h-217FFh SA114 110101xxx 64/32 6B000h-6EFFFH 35800h-35F SA74 1000011xxx 64/32 44000h-43FFFFh 21800h-217FFFh SA115 110110xxx 64/32 6C000h-6EFFFFh 35800h-36F SA75 100010xxx 64/32 44000h-44FFFFh 228000h-22FFFFh SA116 110110xxx 64/32 6E000h-6EFFFFh 36000h-36F SA77 100010xx 64/32 46000h-45FFFFh 228000h-23FFFFh SA118 110111xxx 64/32 6F000h-6EFFFFh 37800h-37F SA77 1000101xx 64/32 46000h-47FFFFh 23800h-23FFFFh SA119 111000xx 64/32 70000h-70FFFFh 38000h-38F SA80 100101xx 64/32 49000h-48FFFFh 24000h-24FFFFh SA120 111001xxx 64/32 73000h-73FFFFh 38800h-38F SA81	SA70	01111111xxx	64/32	3F0000h-3FFFFFh	1F8000h-1FFFFFh	SA111	1101000xxx	64/32	680000h-68FFFFh	340000h-347FFFh
SA73 100010xxx 64/32 42000h-42FFFh 21000h-217FFFh SA114 1101011xxx 64/32 6B000h-6BFFFh 35800h-35F SA74 100011xxx 64/32 43000h-43FFFh 21800h-21FFFh SA115 110110xxx 64/32 6C000h-6CFFFh 36000h-367 SA75 100010xxx 64/32 44000h-44FFFFh 22000h-22FFFh SA116 110110xxx 64/32 6D000h-6EFFFh 38000h-367 SA76 100011xxx 64/32 45000h-43FFFFh 22800h-22FFFh SA117 110110xxx 64/32 6E000h-6EFFFFh 378000h-377 SA78 1000111xxx 64/32 47000h-47FFFh 23800h-23FFFh SA118 110111xxx 64/32 70000h-70FFFh 38000h-387 SA79 100100xxx 64/32 48000h-48FFFh 24000h-247FFFh SA120 111001xx 64/32 70000h-71FFFh 38000h-387 SA80 100100xxx 64/32 40000h-44FFFFh 24000h-24FFFFh SA120 111001xxx 64/32 70000h-72FFFFh 38000h-387 SA81	SA71	1000000xxx	64/32	400000h-40FFFFh	200000h-207FFFh	SA112	1101001xxx	64/32	690000h-69FFFFh	348000h-34FFFFh
SA74 1000011xxx 64/32 43000h-43FFFFh 21800h-21FFFh SA115 1101100xxx 64/32 6C000h-6CFFFFh 36000h-367 SA75 100010xxx 64/32 44000h-44FFFFh 22000h-227FFFh SA116 1101101xx 64/32 6D000h-6DFFFFh 36800h-36F SA76 1000101xxx 64/32 45000h-45FFFFh 22800h-22FFFh SA117 1101101xx 64/32 6E0000h-6EFFFFh 37000h-377 SA77 1000110xxx 64/32 46000h-46FFFFh 23000h-23FFFFh SA118 1101111xx 64/32 6F0000h-6FFFFh 37000h-37F SA78 100011xxx 64/32 47000h-47FFFFh 23800h-23FFFFh SA119 111000xxx 64/32 70000h-70FFFFh 38000h-38F SA81 100101xxx 64/32 48000h-48FFFFh 24000h-24FFFFh SA120 111001xx 64/32 70000h-71FFFFh 38000h-397 SA81 100101xxx 64/32 48000h-44FFFFh 248000h-24FFFFh SA120 111001xx 64/32 70000h-73FFFFh 38000h-397 SA81<	SA72	1000001xxx	64/32	410000h-41FFFFh	208000h-20FFFFh	SA113	1101010xxx	64/32	6A0000h-6AFFFFh	350000h-357FFFh
SA75 1000100xxx 64/32 44000h-44FFFh 22000h-227FFFh SA116 1101101xxx 64/32 6D000h-6DFFFh 36800h-36F SA76 1000101xxx 64/32 45000h-45FFFh 22800h-22FFFh SA117 1101110xxx 64/32 6E000h-6EFFFh 37000h-377 SA77 1000110xxx 64/32 46000h-46FFFh 23000h-237FFFh SA118 1101111xxx 64/32 6F000h-6FFFFh 37000h-377 SA78 1000100xxx 64/32 47000h-47FFFh 23800h-23FFFh SA119 1110000xxx 64/32 70000h-70FFFFh 38000h-387 SA79 1001000xxx 64/32 48000h-48FFFh 24000h-247FFFh SA120 1110010xx 64/32 71000h-71FFFh 38000h-387 SA81 100101xx 64/32 48000h-48FFFh 24800h-24FFFh SA120 1110010xx 64/32 72000h-73FFFh 38000h-397 SA81 1001011xx 64/32 48000h-4FFFFh 25800h-25FFFh SA123 1110011xx 64/32 73000h-73FFFFh 38000h-387 SA83	SA73	1000010xxx	64/32	420000h-42FFFFh	210000h-217FFFh	SA114	1101011xxx	64/32	6B0000h-6BFFFFh	358000h-35FFFFh
SA76 1000101xxx 64/32 45000h-45FFFh 22800h-22FFFh SA117 1101110xxx 64/32 6E000h-6EFFFh 37000h-377 SA77 1000110xxx 64/32 46000h-46FFFh 23000h-237FFh SA118 1101111xxx 64/32 6F000h-6FFFFh 37800h-37F SA78 1000111xxx 64/32 47000h-47FFFh 23800h-23FFFh SA119 1110001xxx 64/32 70000h-7FFFFh 38000h-38F SA79 100100xxx 64/32 48000h-48FFFh 24000h-247FFFh SA120 1110001xxx 64/32 71000h-71FFFh 38000h-38F SA80 100101xxx 64/32 48000h-48FFFh 24800h-24FFFh SA121 111001xx 64/32 72000h-72FFFh 39800h-397 SA81 100101xxx 64/32 48000h-48FFFh 25000h-257FFFh SA122 111001xx 64/32 73000h-73FFFFh 39800h-397 SA83 100101xxx 64/32 40000h-44FFFFh 25000h-257FFFh SA122 111001xx 64/32 74000h-74FFFFh 38000h-387 SA83	SA74	1000011xxx	64/32	430000h-43FFFFh	218000h-21FFFFh	SA115	1101100xxx	64/32	6C0000h-6CFFFFh	360000h-367FFFh
SA77 1000110xxx 64/32 460000h-46FFFFh 23000h-237FFFh SA118 1101111xxx 64/32 6F0000h-6FFFFFh 378000h-37F SA78 1000111xxx 64/32 470000h-47FFFh 23800h-23FFFh SA119 1110000xxx 64/32 70000h-70FFFh 38000h-387 SA79 100100xxx 64/32 48000h-48FFFh 24000h-247FFFh SA120 111001xxx 64/32 71000h-71FFFh 38000h-387 SA80 100101xxx 64/32 49000h-49FFFh 24800h-24FFFh SA121 111001xxx 64/32 72000h-72FFFh 38000h-397 SA81 100101xxx 64/32 40000h-44FFFh 25000h-257FFFh SA121 111001xx 64/32 73000h-73FFFh 39800h-397 SA82 100111xxx 64/32 40000h-44FFFFh 25000h-257FFFh SA123 111011xxx 64/32 74000h-74FFFFh 38000h-387 SA83 100110xxx 64/32 40000h-40FFFFh 25800h-26FFFh SA124 111011xxx 64/32 76000h-76FFFFh 38000h-387 SA84	SA75	1000100xxx	64/32	440000h-44FFFFh	220000h-227FFFh	SA116	1101101xxx	64/32	6D0000h-6DFFFFh	368000h-36FFFFh
SA78 1000111xxx 64/32 470000h-47FFFFh 238000h-23FFFFh SA119 1110000xxx 64/32 70000h-70FFFFh 38000h-387 SA79 100100xxx 64/32 48000h-48FFFh 24000h-247FFFh SA120 1110001xxx 64/32 71000h-71FFFh 38800h-38F SA80 100101xxx 64/32 49000h-49FFFh 24800h-24FFFh SA121 111001xxx 64/32 72000h-72FFFh 39000h-397 SA81 100101xxx 64/32 40000h-44FFFFh 25000h-257FFFh SA122 111001xxx 64/32 73000h-73FFFFh 39000h-397 SA81 100101xxx 64/32 40000h-44FFFFh 25000h-257FFFh SA123 111001xxx 64/32 73000h-73FFFFh 38000h-347 SA83 100110xxx 64/32 40000h-40FFFFh 258000h-267FFFh SA124 111011xxx 64/32 76000h-76FFFFh 38000h-387 SA83 100110xxx 64/32 40000h-40FFFFh 268000h-26FFFFh SA124 111011xxx 64/32 76000h-76FFFFh 38000h-387 SA84<	SA76	1000101xxx	64/32	450000h-45FFFFh	228000h-22FFFFh	SA117	1101110xxx	64/32	6E0000h-6EFFFFh	370000h-377FFFh
SA79 1001000xxx 64/32 48000h-48FFFh 24000h-247FFFh SA120 1110001xxx 64/32 71000h-71FFFh 38800h-38F SA80 1001001xxx 64/32 49000h-49FFFh 24800h-24FFFh SA121 111001xxx 64/32 72000h-72FFFh 39000h-397 SA81 100101xxx 64/32 40000h-44FFFFh 25000h-257FFFh SA122 111001xxx 64/32 73000h-73FFFFh 39800h-39F SA82 100101xxx 64/32 40000h-44FFFFh 25000h-257FFFh SA123 111001xxx 64/32 73000h-73FFFFh 39800h-38F SA83 100110xxx 64/32 40000h-44FFFFh 25000h-25FFFh SA124 111010xxx 64/32 75000h-74FFFFh 3A800h-34F SA83 100110xxx 64/32 40000h-40FFFFh 26000h-26FFFh SA125 111011xxx 64/32 76000h-76FFFFh 3B800h-38F SA84 100111xxx 64/32 40000h-4EFFFFh 268000h-26FFFFh SA126 111011xxx 64/32 76000h-76FFFFh 3B8000h-38F SA84	SA77	1000110xxx	64/32	460000h-46FFFFh	230000h-237FFFh	SA118	1101111xxx	64/32	6F0000h-6FFFFh	378000h-37FFFFh
SA80 1001001xxx 64/32 490000h-49FFFh 248000h-24FFFh SA121 1110010xxx 64/32 720000h-72FFFh 39000h-397 SA81 100101xxx 64/32 4A0000h-4AFFFFh 25000h-257FFFh SA122 1110011xxx 64/32 73000h-73FFFFh 39800h-39F SA82 100101xxx 64/32 4A0000h-4AFFFFh 25000h-25FFFh SA123 111001xxx 64/32 74000h-74FFFFh 39800h-34F SA83 100110xxx 64/32 4B0000h-4DFFFFh 258000h-267FFFh SA124 111010xxx 64/32 75000h-75FFFh 3A8000h-3AF SA84 100110xxx 64/32 4D000h-4DFFFFh 268000h-267FFFh SA125 111011xxx 64/32 76000h-76FFFFh 38800h-38F SA85 1001110xxx 64/32 4E0000h-4EFFFFh 270000h-277FFFh SA126 1110111xxx 64/32 77000h-77FFFh 38800h-38F SA85 100111xxx 64/32 4E0000h-4FFFFh 278000h-277FFFh SA126 111011xxx 64/32 78000h-78FFFFh 38000h-38F	SA78	1000111xxx	64/32	470000h-47FFFFh	238000h-23FFFFh	SA119	1110000xxx	64/32	700000h-70FFFFh	380000h-387FFFh
SA81 1001010xxx 64/32 4A0000h-4AFFFFh 250000h-257FFFh SA122 1110011xxx 64/32 730000h-73FFFFh 398000h-39F SA82 1001011xxx 64/32 4B0000h-4BFFFh 258000h-25FFFh SA123 1110100xxx 64/32 740000h-74FFFFh 3A000h-3A7 SA83 100110xxx 64/32 4C0000h-4CFFFFh 260000h-267FFFh SA124 1110101xxx 64/32 750000h-75FFFh 3A8000h-3A7 SA84 1001101xxx 64/32 4D0000h-4DFFFFh 268000h-267FFFh SA125 1110110xxx 64/32 760000h-75FFFh 3A8000h-387 SA85 1001110xxx 64/32 4E0000h-4EFFFh 268000h-27FFFh SA126 1110110xxx 64/32 760000h-76FFFh 3B8000h-387 SA85 1001110xxx 64/32 4E0000h-4EFFFFh 278000h-27FFFh SA126 1110110xxx 64/32 78000h-78FFFFh 3B8000h-387 SA85 1001111xxx 64/32 4E0000h-4FFFFh 278000h-27FFFh SA126 1110110xxx 64/32 780000h-78FFFFh 3C8000h-30F	SA79	1001000xxx	64/32	480000h-48FFFFh	240000h-247FFFh	SA120	1110001xxx	64/32	710000h-71FFFFh	388000h-38FFFFh
SA82 1001011xxx 64/32 4B000h-4BFFFh 25800h-25FFFh SA123 1110100xxx 64/32 74000h-74FFFh 3A000h-3A7 SA83 100110xxx 64/32 4C000h-4CFFFFh 26000h-267FFFh SA124 1110101xxx 64/32 75000h-75FFFh 3A800h-3AF SA84 1001101xxx 64/32 4C0000h-4DFFFh 26000h-267FFFh SA124 1110101xxx 64/32 75000h-75FFFh 3A800h-3AF SA84 1001101xxx 64/32 4D000h-4DFFFh 268000h-26FFFh SA125 1110110xxx 64/32 76000h-76FFFh 3B8000h-3BF SA85 1001111xxx 64/32 4E0000h-4EFFFh 270000h-27FFFh SA126 1110111xxx 64/32 76000h-76FFFh 3B8000h-3BF SA86 1001111xxx 64/32 4E0000h-4EFFFFh 278000h-27FFFh SA127 1111001xxx 64/32 78000h-78FFFFh 3C8000h-3C7 SA87 101000xxx 64/32 50000h-50FFFh 28000h-28FFFFh SA128 111101xxx 64/32 78000h-78FFFFh 3C8000h-3C7	SA80	1001001xxx	64/32	490000h-49FFFFh	248000h-24FFFFh	SA121	1110010xxx	64/32	720000h-72FFFFh	390000h-397FFFh
SA83 1001100xxx 64/32 4C0000h-4CFFFFh 260000h-267FFFh SA124 1110101xxx 64/32 750000h-75FFFFh 3A8000h-3AF SA84 1001101xxx 64/32 4D0000h-4DFFFFh 268000h-26FFFFh SA125 1110110xxx 64/32 760000h-75FFFFh 3B000h-3B7 SA85 1001110xxx 64/32 4E0000h-4EFFFFh 270000h-27FFFh SA126 1110111xxx 64/32 760000h-76FFFFh 3B000h-3B7 SA85 1001110xxx 64/32 4E0000h-4EFFFFh 270000h-27FFFFh SA126 1110111xxx 64/32 770000h-77FFFFh 3B8000h-3B7 SA86 1001111xxx 64/32 4E0000h-4EFFFFh 278000h-27FFFFh SA127 1111001xxx 64/32 78000h-78FFFFh 3C8000h-367 SA87 101000xxx 64/32 500000h-50FFFFh 28000h-28FFFFh SA128 1111011xxx 64/32 78000h-78FFFFh 3C8000h-30F SA88 101001xxx 64/32 510000h-51FFFh 288000h-28FFFFh SA129 1111010xxx 64/32 780000h-78FFFFh 3D8000h-30F <	SA81	1001010xxx	64/32	4A0000h-4AFFFFh	250000h-257FFFh	SA122	1110011xxx	64/32	730000h-73FFFFh	398000h-39FFFFh
SA84 1001101xxx 64/32 4D0000h-4DFFFFh 268000h-26FFFFh SA125 1110110xxx 64/32 760000h-76FFFFh 3B000h-3B7 SA85 1001110xxx 64/32 4E0000h-4EFFFFh 270000h-277FFFh SA126 1110111xxx 64/32 770000h-77FFFFh 3B8000h-3B7 SA86 1001111xxx 64/32 4E0000h-4EFFFFh 270000h-27FFFFh SA126 1110111xxx 64/32 770000h-77FFFFh 3B8000h-3B7 SA86 1001111xxx 64/32 4E0000h-4FFFFFh 278000h-27FFFFh SA127 1111001xxx 64/32 78000h-78FFFFh 3C8000h-3C7 SA87 101000xxx 64/32 500000h-50FFFFh 28000h-28FFFFh SA128 1111011xxx 64/32 78000h-78FFFFh 3C8000h-3C7 SA88 101001xxx 64/32 510000h-51FFFFh 288000h-28FFFFh SA129 1111010xxx 64/32 780000h-78FFFFh 3D8000h-3D7 SA89 101001xxx 64/32 520000h-53FFFFh 290000h-29FFFFh SA130 1111011xxx 64/32 780000h-78FFFFh 3D8000h-3D7	SA82	1001011xxx	64/32	4B0000h-4BFFFFh	258000h-25FFFFh	SA123	1110100xxx	64/32	740000h-74FFFFh	3A0000h-3A7FFFh
SA85 1001110xxx 64/32 4E0000h-4EFFFh 270000h-277FFFh SA126 1110111xxx 64/32 770000h-77FFFh 3B8000h-3BF SA86 1001111xxx 64/32 4F0000h-4FFFFh 278000h-27FFFh SA127 1111000xxx 64/32 780000h-77FFFFh 3B8000h-3BF SA87 101000xxx 64/32 4F0000h-4FFFFh 278000h-27FFFh SA127 111100xxx 64/32 780000h-78FFFFh 3C000h-3C7 SA87 101000xx 64/32 500000h-50FFFh 28000h-28FFFFh SA128 1111001xxx 64/32 790000h-79FFFFh 3C8000h-3CF SA88 101001xx 64/32 510000h-51FFFh 28000h-28FFFFh SA129 111101xxx 64/32 740000h-74FFFFh 3D8000h-3D7 SA89 101001xxx 64/32 520000h-52FFFh 290000h-297FFFh SA130 111101xxx 64/32 7B0000h-78FFFFh 3D8000h-3D7 SA90 101001xxx 64/32 530000h-53FFFh 298000h-29FFFFh SA130 111101xxx 64/32 7C0000h-7CFFFFh 3E8000h-3E7	SA83	1001100xxx	64/32	4C0000h-4CFFFFh	260000h-267FFFh	SA124	1110101xxx	64/32	750000h-75FFFFh	3A8000h-3AFFFFh
SA86 1001111xxx 64/32 4F0000h-4FFFFh 278000h-27FFFh SA127 111100xxx 64/32 780000h-78FFFh 3C000h-3C7 SA87 1010000xxx 64/32 500000h-50FFFh 28000h-28FFFh SA128 1111001xxx 64/32 79000h-79FFFh 3C8000h-3CF SA88 1010001xxx 64/32 50000h-50FFFh 28000h-28FFFh SA129 111101xxx 64/32 79000h-79FFFh 3C800h-3CF SA88 101001xxx 64/32 51000h-51FFFh 28800h-28FFFh SA129 111101xxx 64/32 74000h-74FFFh 3D000h-3D7 SA89 101001xxx 64/32 52000h-52FFFh 29000h-297FFFh SA130 111101xxx 64/32 78000h-78FFFh 3D800h-3DF SA90 101001xxx 64/32 530000h-53FFFh 29800h-29FFFh SA131 111100xxx 64/32 7C000h-7CFFFh 3E8000h-3EF SA91 101010xxx 64/32 540000h-54FFFFh 28000h-247FFFh SA132 111101xxx 64/32 7D0000h-7CFFFFh 3E8000h-3EF SA91	SA84	1001101xxx	64/32	4D0000h-4DFFFFh	268000h-26FFFFh	SA125	1110110xxx	64/32	760000h-76FFFFh	3B0000h-3B7FFFh
SA87 1010000xxx 64/32 50000h-50FFFh 28000h-28FFFh SA128 1111001xxx 64/32 79000h-79FFFh 3C800h-3CF SA88 1010001xxx 64/32 51000h-51FFFh 28800h-28FFFh SA128 1111001xxx 64/32 74000h-79FFFh 3C800h-3CF SA89 101001xxx 64/32 51000h-51FFFh 28800h-28FFFh SA129 111101xxx 64/32 74000h-7AFFFFh 3D000h-3D7 SA89 101001xxx 64/32 52000h-52FFFh 29000h-297FFFh SA130 111101xxx 64/32 7B000h-7BFFFH 3D800h-3DF SA90 101001xxx 64/32 53000h-53FFFh 29800h-29FFFFh SA131 111100xxx 64/32 7C000h-7CFFFH 3D800h-3EF SA91 101010xxx 64/32 54000h-54FFFFh 24000h-247FFFh SA132 111101xxx 64/32 7D000h-7CFFFFh 3E800h-3EF SA91 101010xxx 64/32 54000h-54FFFFh 24000h-247FFFh SA132 111101xxx 64/32 7D000h-7DFFFFh 3E800h-3EF	SA85	1001110xxx	64/32	4E0000h-4EFFFFh	270000h-277FFFh	SA126	1110111xxx	64/32	770000h-77FFFFh	3B8000h-3BFFFFh
SA88 1010001xxx 64/32 510000h–51FFFh 288000h–28FFFFh SA129 1111010xxx 64/32 7A0000h–7AFFFFh 3D0000h–3D7 SA89 1010010xxx 64/32 520000h–52FFFh 290000h–297FFFh SA130 1111011xxx 64/32 7B0000h–7BFFFFh 3D8000h–3D7 SA90 1010011xxx 64/32 530000h–53FFFFh 298000h–29FFFFh SA131 111101xxx 64/32 7C0000h–7EFFFh 3D8000h–3E7 SA91 1010100xxx 64/32 540000h–54FFFFh 240000h–2A7FFFh SA132 1111101xxx 64/32 7D0000h–7CFFFFh 3E8000h–3E7 SA91 1010100xxx 64/32 540000h–54FFFFh 2A0000h–2A7FFFh SA132 1111101xxx 64/32 7D0000h–7CFFFFh 3E8000h–3E7	SA86	1001111xxx	64/32	4F0000h-4FFFFFh	278000h-27FFFFh	SA127	1111000xxx	64/32	780000h-78FFFFh	3C0000h-3C7FFFh
SA89 1010010xxx 64/32 520000h-52FFFh 290000h-297FFFh SA130 1111011xxx 64/32 7B0000h-7BFFFh 3D8000h-3DF SA90 1010011xxx 64/32 530000h-53FFFh 298000h-29FFFh SA131 111101xxx 64/32 7C0000h-7EFFFh 3D8000h-3EF SA91 101010xxx 64/32 530000h-53FFFh 298000h-29FFFh SA131 111100xxx 64/32 7C0000h-7CFFFh 3E000h-3EF SA91 1010100xxx 64/32 540000h-54FFFFh 2A0000h-2A7FFFh SA132 1111101xxx 64/32 7D0000h-7DFFFFh 3E8000h-3EF	SA87	1010000xxx	64/32	500000h-50FFFFh	280000h-28FFFFh	SA128	1111001xxx	64/32	790000h-79FFFFh	3C8000h-3CFFFFh
SA89 1010010xxx 64/32 520000h-52FFFh 290000h-297FFFh SA130 1111011xxx 64/32 7B0000h-7BFFFh 3D8000h-3DF SA90 1010011xxx 64/32 530000h-53FFFh 298000h-29FFFh SA131 111101xxx 64/32 7C0000h-7CFFFFh 3E000h-3E7 SA91 1010100xxx 64/32 540000h-54FFFFh 28000h-247FFFh SA132 111101xxx 64/32 7C0000h-7CFFFFh 3E000h-3E7 SA91 1010100xxx 64/32 540000h-54FFFFh 2A0000h-2A7FFFh SA132 111101xxx 64/32 7D0000h-7DFFFFh 3E8000h-3E7	SA88	1010001xxx	64/32	510000h-51FFFFh	288000h-28FFFFh	SA129	1111010xxx	64/32	7A0000h-7AFFFFh	3D0000h-3D7FFFh
SA90 1010011xxx 64/32 530000h–53FFFh 298000h–29FFFh SA131 1111100xxx 64/32 7C0000h–7CFFFh 3E0000h–3E7 SA91 1010100xxx 64/32 540000h–54FFFh 240000h–247FFFh SA132 1111101xxx 64/32 7D0000h–7CFFFh 3E8000h–3E7	SA89	1010010xxx	64/32			SA130		64/32	7B0000h-7BFFFFh	3D8000h-3DFFFFh
SA91 1010100xxx 64/32 540000h-54FFFh 2A000h-2A7FFFh SA132 1111101xxx 64/32 7D0000h-7DFFFh 3E8000h-3EF	SA90		64/32	530000h-53FFFFh	298000h-29FFFFh	SA131	1111100xxx	64/32	7C0000h-7CFFFh	3E0000h-3E7FFFh
	SA91	1010100xxx	64/32	540000h-54FFFFh	2A0000h-2A7FFFh		1111101xxx	64/32	7D0000h-7DFFFFh	3E8000h-3EFFFFh
SA92 1010101xxx 64/32 550000h-55FFFFh 2A8000h-2AFFFFh SA133 1111110xxx 64/32 7E0000h-7EFFFFh 3F000h-3F7	SA92	1010101xxx	64/32	550000h-55FFFFh	2A8000h-2AFFFFh	SA133	1111110xxx	64/32	7E0000h-7EFFFh	3F0000h-3F7FFFh
SA93 1010110xxx 64/32 560000h-56FFFh 2B0000h-2B7FFFh SA134 1111111000 64/32 7F0000h-7FFFFFh 3F8000h-3FF	SA93	1010110xxx	64/32	560000h-56FFFFh	2B0000h-2B7FFFh	SA134	1111111000	64/32	7F0000h-7FFFFFh	3F8000h-3FFFFFh
SA94 10101111xxx 64/32 570000h-57FFFh 2B8000h-2BFFFFh	SA94	1010111xxx	64/32	570000h-57FFFFh	2B8000h-2BFFFFh	-		•		I

Table I0. S29GL064A (Model R5) Sector Addresses (Sheet I of 2)

Sector	A21–A15	16-bit Address Range	Sector	A21–A15	16-bit Address Range
SA0	0000000	000000-007FFF	SA21	0010101	0A8000-0AFFFF
SA1	0000001	008000-00FFFF	SA22	0010110	0B0000-0B7FFF
SA2	0000010	010000-017FFF	SA23	0010111	0B8000–0BFFFF
SA3	0000011	018000-01FFFF	SA24	0011000	0C0000-0C7FFF
SA4	0000100	020000-027FFF	SA25	0011001	0C8000-0CFFFF
SA5	0000101	028000-02FFFF	SA26	0011010	0D0000-0D7FFF
SA6	0000110	030000-037FFF	SA27	0011011	0D8000-0DFFFF
SA7	0000111	038000-03FFFF	SA28	0011100	0E0000-0E7FFF
SA8	0001000	040000-047FFF	SA29	0011101	0E8000-0EFFFF
SA9	0001001	048000-04FFFF	SA30	0011110	OF0000–OF7FFF
SA10	0001010	050000-057FFF	SA31	0011111	OF8000-OFFFFF
SA11	0001011	058000-05FFFF	SA32	0100000	200000-207FFF
SA12	0001100	060000-067FFF	SA33	0100001	208000-20FFFF
SA13	0001101	068000-06FFFF	SA34	0100010	210000-217FFF
SA14	0001110	070000-077FFF	SA35	0100011	218000-21FFFF
SA15	0001111	078000-07FFFF	SA36	0100100	220000-227FFF
SA16	0010000	080000-087FFF	SA37	0100101	228000-22FFFF
SA17	0010001	088000-08FFFF	SA38	0100110	230000-237FFF
SA18	0010010	090000-097FFF	SA39	0100111	238000-23FFFF
SA19	0010011	098000-09FFFF	SA40	0101000	240000-247FFF
SA20	0010100	0A0000-0A7FFF	SA41	0101001	248000-24FFFF



Sector	A21–A15	16-bit Address Range	Sector	A21–A15	16-bit Address Range
SA42	0101010	250000-257FFF	SA85	1010101	1A8000–1AFFFF
SA43	0101011	258000-25FFFF	SA86	1010110	1B0000–1B7FFF
SA44	0101100	260000-267FFF	SA87	1010111	1B8000–1BFFFF
SA45	0101101	268000-26FFFF	SA88	1011000	1C0000-1C7FFF
SA46	0101110	270000-277FFF	SA89	1011001	1C8000-1CFFFF
SA47	0101111	278000-27FFFF	SA90	1011010	1D0000–1D7FFF
SA48	0110000	280000-287FFF	SA91	1011011	1D8000–1DFFFF
SA49	0110001	288000-28FFFF	SA92	1011100	1E0000–1E7FFF
SA50	0110010	290000-297FFF	SA93	1011101	1E8000–1EFFFF
SA51	0110011	298000-29FFFF	SA94	1011110	1F0000–1F7FFF
SA52	0110100	2A0000–2A7FFF	SA95	1011111	1F8000–1FFFFF
SA53	0110101	2A8000–2AFFFF	SA96	1100000	300000-307FFF
SA54	0110110	2B0000-2B7FFF	SA97	1100001	308000-30FFFF
SA55	0110111	2B8000-2BFFFF	SA98	1100010	310000–317FFF
SA56	0111000	2C0000-2C7FFF	SA99	1100011	318000–31FFFF
SA57	0111001	2C8000-2CFFFF	SA100	1100100	320000-327FFF
SA58	0111010	2D0000-2D7FFF	SA101	1100101	328000-32FFFF
SA59	0111011	2D8000-2DFFFF	SA102	1100110	330000-337FFF
SA60	0111100	2E0000-2E7FFF	SA103	1100111	338000–33FFFF
SA61	0111101	2E8000-2EFFFF	SA104	1101000	340000-347FFF
SA62	0111110	2F0000-2F7FFF	SA105	1101001	348000–34FFFF
SA63	0111111	2F8000-2FFFFF	SA106	1101010	350000-357FFF
SA64	1000000	100000-107FFF	SA107	1101011	358000-35FFFF
SA65	1000001	108000-10FFFF	SA108	1101100	360000-367FFF
SA66	1000010	110000–117FFF	SA109	1101101	368000–36FFFF
SA67	1000011	118000–11FFFF	SA110	1101110	370000–377FFF
SA68	1000100	120000–127FFF	SA111	1101111	378000–37FFFF
SA69	1000101	128000–12FFFF	SA112	1110000	380000–387FFF
SA70	1000110	130000–137FFF	SA113	1110001	388000–38FFFF
SA71	1000111	138000–13FFFF	SA114	1110010	390000-397FFF
SA72	1001000	140000–147FFF	SA115	1110011	398000–39FFFF
SA73	1001001	148000–14FFFF	SA116	1110100	3A0000–3A7FFF
SA74	1001010	150000–157FFF	SA117	1110101	3A8000–3AFFFF
SA75	1001011	158000–15FFFF	SA118	1110110	3B0000–3B7FFF
SA76	1001100	160000–167FFF	SA119	1110111	3B8000–3BFFFF
SA77	1001101	168000–16FFFF	SA120	1111000	3C0000-3C7FFF
SA78	1001110	170000–177FFF	SA121	1111001	3C8000-3CFFFF
SA79	1001111	178000–17FFFF	SA122	1111010	3D0000–3D7FFF
SA80	1010000	180000–187FFF	SA123	1111011	3D8000–3DFFFF
SA81	1010001	188000–18FFFF	SA124	1111100	3E0000-3E7FFF
SA82	1010010	190000–197FFF	SA125	1111101	3E8000–3EFFFF
SA83	1010011	198000–19FFFF	SA126	1111110	3F0000–3F7FFF
SA84	1010100	1A0000–1A7FFF	SA127	1111111	3F8000–3FFFFF

Table I0. S29GL064A (Model R5) Sector Addresses (Sheet 2 of 2)

Table II. S29GL064A (Models R6, R7) Sector Addresses (Sheet I of 2)

Sector	A21–A15	16-bit Address Range	Sector	A21–A15	16-bit Address Range
SA0	0000000	000000-007FFF	SA21	0010101	0A8000–0AFFFF
SA1	0000001	008000-00FFFF	SA22	0010110	0B0000-0B7FFF
SA2	0000010	010000-017FFF	SA23	0010111	0B8000–0BFFFF
SA3	0000011	018000-01FFFF	SA24	0011000	0C0000-0C7FFF
SA4	0000100	020000-027FFF	SA25	0011001	0C8000-0CFFFF
SA5	0000101	028000-02FFFF	SA26	0011010	0D0000-0D7FFF
SA6	0000110	030000-037FFF	SA27	0011011	0D8000-0DFFFF
SA7	0000111	038000-03FFFF	SA28	0011100	OEOOOO-OE7FFF
SA8	0001000	040000-047FFF	SA29	0011101	0E8000-0EFFFF
SA9	0001001	048000-04FFFF	SA30	0011110	OF0000–OF7FFF
SA10	0001010	050000-057FFF	SA31	0011111	OF8000–OFFFFF
SA11	0001011	058000-05FFFF	SA32	0100000	200000-207FFF
SA12	0001100	060000-067FFF	SA33	0100001	208000-20FFFF
SA13	0001101	068000-06FFFF	SA34	0100010	210000-217FFF
SA14	0001110	070000-077FFF	SA35	0100011	218000–21FFFF
SA15	0001111	078000-07FFFF	SA36	0100100	220000-227FFF
SA16	0010000	080000-087FFF	SA37	0100101	228000-22FFFF
SA17	0010001	088000-08FFFF	SA38	0100110	230000-237FFF
SA18	0010010	090000-097FFF	SA39	0100111	238000-23FFFF
SA19	0010011	098000-09FFFF	SA40	0101000	240000-247FFF
SA20	0010100	0A0000-0A7FFF	SA41	0101001	248000-24FFFF

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Sector	A21–A15	16-bit Address	Sector	A21–A15	16-bit Address
		Range			Range
SA42	0101010	250000-257FFF	SA85	1010101	1A8000–1AFFFF
SA43	0101011	258000-25FFFF	SA86	1010110	1B0000–1B7FFF
SA44	0101100	260000-267FFF	SA87	1010111	1B8000–1BFFFF
SA45	0101101	268000-26FFFF	SA88	1011000	1C0000-1C7FFF
SA46	0101110	270000-277FFF	SA89	1011001	1C8000-1CFFFF
SA47	0101111	278000–27FFFF	SA90	1011010	1D0000–1D7FFF
SA48	0110000	280000-287FFF	SA91	1011011	1D8000–1DFFFF
SA49	0110001	288000-28FFFF	SA92	1011100	1E0000–1E7FFF
SA50	0110010	290000-297FFF	SA93	1011101	1E8000–1EFFFF
SA51	0110011	298000-29FFFF	SA94	1011110	1F0000–1F7FFF
SA52	0110100	2A0000–2A7FFF	SA95	1011111	1F8000–1FFFFF
SA53	0110101	2A8000–2AFFFF	SA96	1100000	30000-307FFF
SA54	0110110	2B0000-2B7FFF	SA97	1100001	308000-30FFFF
SA55	0110111	2B8000-2BFFFF	SA98	1100010	310000–317FFF
SA56	0111000	2C0000-2C7FFF	SA99	1100011	318000–31FFFF
SA57	0111001	2C8000-2CFFFF	SA100	1100100	320000-327FFF
SA58	0111010	2D0000-2D7FFF	SA101	1100101	328000-32FFFF
SA59	0111011	2D8000-2DFFFF	SA102	1100110	330000–337FFF
SA60	0111100	2E0000-2E7FFF	SA103	1100111	338000–33FFFF
SA61	0111101	2E8000-2EFFFF	SA104	1101000	340000-347FFF
SA62	0111110	2F0000-2F7FFF	SA105	1101001	348000-34FFFF
SA63	0111111	2F8000-2FFFFF	SA106	1101010	350000-357FFF
SA64	1000000	100000-107FFF	SA107	1101011	358000-35FFFF
SA65	1000001	108000-10FFFF	SA108	1101100	360000–367FFF
SA66	1000010	110000–117FFF	SA109	1101101	368000–36FFFF
SA67	1000011	118000–11FFFF	SA110	1101110	370000–377FFF
SA68	1000100	120000–127FFF	SA111	1101111	378000–37FFFF
SA69	1000101	128000–12FFFF	SA112	1110000	380000–387FFF
SA70	1000110	130000–137FFF	SA113	1110001	388000-38FFFF
SA71	1000111	138000–13FFFF	SA114	1110010	390000–397FFF
SA72	1001000	140000–147FFF	SA115	1110011	398000-39FFFF
SA73	1001001	148000–14FFFF	SA116	1110100	3A0000–3A7FFF
SA74	1001010	150000–157FFF	SA117	1110101	3A8000–3AFFFF
SA75	1001011	158000–15FFFF	SA118	1110110	3B0000–3B7FFF
SA76	1001100	160000–167FFF	SA119	1110111	3B8000–3BFFFF
SA77	1001101	168000–16FFFF	SA120	1111000	3C0000-3C7FFF
SA78	1001110	170000–177FFF	SA121	1111001	3C8000-3CFFFF
SA79	1001111	178000–17FFFF	SA122	1111010	3D0000–3D7FFF
SA80	1010000	180000–187FFF	SA123	1111011	3D8000–3DFFFF
SA81	1010001	188000–18FFFF	SA124	1111100	3E0000–3E7FFF
SA82	1010010	190000–197FFF	SA125	1111101	3E8000–3EFFFF
SA83	1010011	198000–19FFFF	SA126	1111110	3F0000–3F7FFF
SA84	1010100	1A0000–1A7FFF	SA127	1111111	3F8000–3FFFFF

Table II. S29GL064A (Models R6, R7) Sector Addresses (Sheet 2 of 2)

Autoselect Mode

The autoselect mode provides manufacturer and device identification, and sector group protection verification, through identifier codes output on DQ7–DQ0. This mode is primarily intended for programming equipment to automatically match a device to be programmed with its corresponding programming algorithm. However, the autoselect codes can also be accessed in-system through the command register.

When using programming equipment, the autoselect mode requires V_{ID} on address pin A9. Address pins A6, A3, A2, A1, and A0 must be as shown in Table 12. In addition, when verifying sector protection, the sector address must appear on the appropriate highest order address bits (see Table 4-Table 20). Table 12 shows the remaining address bits that are don't care. When all necessary bits have been set as required, the programming equipment may then read the corresponding identifier code on DQ7–DQ0.

To access the autoselect codes in-system, the host system can issue the autoselect command via the command register, as shown in Table 25 and Table 26. This



method does not require V_{ID} . Refer to the Autoselect Command Sequence section for more information.

		1		1												DQ7 to DQ0	
					A14		A8		A5	A3				o DQ15	l	Model Number	
Description	CE#	OE#	WE#	to A15	to A10	A9	to A7	A6	to A4	to A2	A1	A 0	BYTE# = V _{IH}	BYTE# = V _{IL}	R1, R2, R8, R9	R3, R4	R5, R6, R7
Manufacturer ID: Spansion Products	L	L	н	х	х	V_{ID}	х	L	х	L	L	L	00	х	01h	01h	01h
Cycle 1										L	L	Н	22	Х	7Eh	7Eh	7Eh
Cycle 2										Н	Н	L	22	Х	0Ch	10h	13h
Cycle 3 Cycle 3	L	L	Н	х	х	V _{ID}	х	L	х	Н	Н	Н	22	х	01h	00h (-R4, bottom boot) 01h (-R3, top boot)	01h
S Cycle 1										L	L	Н	22	Х	7Eh	7Eh	
Cycle 2										Н	Н	L	22	Х	1Dh	1Ah	
Cycle 1 Cycle 2 Cycle 2 Cycle 3 Cycle 3	L	L	Н	х	х	V _{ID}	х	L	х	Н	Н	Η	22	х	00h	00h (-R4, bottom boot) 01h (-R3, top boot)	
Sector Group Protection Verification	L	L	н	SA	х	V_{ID}	х	L	х	L	Н	L	х	х		1h (protected), h (unprotected))
Secured Silicon Sector Indicator Bit (DQ7), WP# protects highest address sector	L	L	Н	х	х	V _{ID}	х	L	х	L	Н	Н	х	х		(factory locked not factory lock	
Secured Silicon Sector Indicator Bit (DQ7), WP# protects lowest address sector	L	L	Н	x	x	V _{ID}	х	L	x	L	Н	Н	x	х		(factory locked not factory lock	

Table 12.	Autoselect Codes,	(High	Voltage	Method)
Table 14.	Autosciece Coues,	(1181	voicage	i icciiou)

Legend: $L = Logic Low = V_{IL}$, $H = Logic High = V_{IH}$, SA = Sector Address, X = Don't care.

Sector Group Protection and Unprotection

The hardware sector group protection feature disables both program and erase operations in any sector group (see Table 11-Table 20). The hardware sector group unprotection feature re-enables both program and erase operations in previously protected sector groups. Sector group protection/unprotection can be implemented via two methods.

Sector protection/unprotection requires V_{ID} on the RESET# pin only, and can be implemented either in-system or via programming equipment. Figure 2 shows the algorithms and Figure 24 shows the timing diagram. This method uses standard microprocessor bus cycle timing. For sector group unprotect, all unprotected sector groups must first be protected prior to the first sector group unprotect write cycle.

The device is shipped with all sector groups unprotected. Spansion offers the option of programming and protecting sector groups at its factory prior to shipping the device through Spansion Programming Service. Contact a Spansion representative for details.

It is possible to determine whether a sector group is protected or unprotected. See the Autoselect Mode section for details.



Table I3. S29GL032A (Models RI, R2) Sector Group Protection/Unprotection Addresses

Sector Group	A20–A15						
SA0	000000	SA12–SA15	0011xx	SA36–SA39	1001xx	SA56-SA59	1110xx
SA1	000001	SA16-SA19	0100xx	SA40-SA43	1010xx	SA60	111100
SA2	000010	SA20–SA23	0101xx	SA44–SA47	1011xx	SA61	111101
SA3	000011	SA24–SA27	0110xx	SA48-SA51	1100xx	SA62	111110
SA4–SA7	0001xx	SA28–SA31	0111xx	SA52–SA55	1101xx	SA63	111111
SA8-SA11	0010xx	SA32–SA35	1000xx				

Table I4. S29GL032A (Models R3) Sector Group Protection/Unprotection Address Table

Sector	A20–A12	Sector/Sector Block Size (Kbytes)	Sector	A20–A12	Sector/Sector Block Size (Kbytes)	Sector	A20–A12	Sector/Sector Block Size (Kbytes)
SAO-SA3	0000XXXXXh	256 (4x64)	SA36-SA39	1001XXXXXh	256 (4x64)	SA63	111111000h	8
SA4-SA7	0001XXXXXh	256 (4x64)	SA40-SA43	1010XXXXXh	256 (4x64)	SA64	111111001h	8
SA8-SA11	0010XXXXXh	256 (4x64)	SA44-SA47	1011XXXXXh	256 (4x64)	SA65	111111010h	8
SA12-SA15	0011XXXXXh	256 (4x64)	SA48-SA51	1100XXXXXh	256 (4x64)	SA66	111111011h	8
SA16-SA19	0100XXXXXh	256 (4x64)	SA52-SA55	1101XXXXXh	256 (4x64)	SA67	111111100h	8
SA20-SA23	0101XXXXXh	256 (4x64)	SA56-SA59	1110XXXXXh	256 (4x64)	SA68	111111101h	8
SA24-SA27	0110XXXXXh	256 (4x64)		111100XXXh		SA69	111111110h	8
SA28-SA31	0111XXXXXh	256 (4x64)	SA60-SA62	111101XXXh	192 (3x64)	SA70	1111111111h	8
SA32-SA35	1000XXXXXh	256 (4x64)		111110XXXh				

Table I5. S29GL032A (Models R4) Sector Group Protection/Unprotection Address Table

Sector	A20–A12	Sector/Sector Block Size (Kbytes)	Sector	A20–A12	Sector/Sector Block Size (Kbytes)	Sector	A20–A12	Sector/Sector Block Size (Kbytes)
SA0	000000000h	8		000001XXXh		SA35-SA38	0111XXXXXh	256 (4x64)
SA1	00000001h	8	SA8–SA10	000010XXXh	192 (3x64)	SA39-SA42	1000XXXXXh	256 (4x64)
SA2	000000010h	8		000011XXXh		SA43-SA46	1001XXXXXh	256 (4x64)
SA3	000000011h	8	SA11-SA14	0001XXXXXh	256 (4x64)	SA47-SA50	1010XXXXXh	256 (4x64)
SA4	000000100h	8	SA15-SA18	0010XXXXXh	256 (4x64)	SA51-SA54	1011XXXXXh	256 (4x64)
SA5	000000101h	8	SA19-SA22	0011XXXXXh	256 (4x64)	SA55-SA58	1100XXXXXh	256 (4x64)
SA6	000000110h	8	SA23–SA26	0100XXXXXh	256 (4x64)	SA59-SA62	1101XXXXXh	256 (4x64)
SA7	000000111h	8	SA27-SA30	0101XXXXXh	256 (4x64)	SA63-SA66	1110XXXXXh	256 (4x64)
			SA31-SA34	0110XXXXXh	256 (4x64)	SA67-SA70	1111XXXXXh	256 (4x64)

Table I6. S29GL064A (Models RI, R2, R8, R9) Sector Group Protection/Unprotection Addresses

Sector Group	A21–A15						
SA0	0000000	SA28–SA31	00111xx	SA68–SA71	10001xx	SA108-SA111	11011xx
SA1	0000001	SA32–SA35	01000xx	SA72–SA75	10010xx	SA112-SA115	11100xx
SA2	0000010	SA36-SA39	01001xx	SA76-SA79	10011xx	SA116-SA119	11101xx
SA3	0000011	SA40-SA43	01010xx	SA80-SA83	10100xx	SA120-SA123	11110xx
SA4–SA7	00001xx	SA44–SA47	01011xx	SA84–SA87	10101xx	SA124	1111100
SA8–SA11	00010xx	SA48-SA51	01100xx	SA88–SA91	10110xx	SA125	1111101
SA12-SA15	00011xx	SA52–SA55	01101xx	SA92-SA95	10111xx	SA126	1111110
SA16-SA19	00100xx	SA56-SA59	01110xx	SA96-SA99	11000xx	SA127	1111111
SA20-SA23	00101xx	SA60-SA63	01111xx	SA100-SA103	11001xx		
SA24–SA27	00110xx	SA64-SA67	10000xx	SA104-SA107	11010xx		



Table I7. S29GL064A (Model R3) Top Boot Sector Protection/Unprotection Addresses

Sector	A21–A12	Sector/Sector Block Size (Kbytes)	Sector	A20–A12	Sector/Sector Block Size (Kbytes)	Sector	A20–A12	Sector/Sector Block Size (Kbytes)
SA0-SA3	00000XXXXX	256 (4x64)	SA56-SA59	01110XXXXX	256 (4x64)	SA112-SA115	11100XXXXX	256 (4x64)
SA4-SA7	00001XXXXX	256 (4x64)	SA60-SA63	01111XXXXX	256 (4x64)	SA116-SA119	11101XXXXX	256 (4x64)
SA8-SA11	00010XXXXX	256 (4x64)	SA64-SA67	10000XXXXX	256 (4x64)	SA120-SA123	11110XXXXX	256 (4x64)
SA12-SA15	00011XXXXX	256 (4x64)	SA68-SA71	10001XXXXX	256 (4x64)	SA124-SA126	1111100XXX 1111101XXX 1111110XXX	192 (3x64)
SA16-SA19	00100XXXXX	256 (4x64)	SA72-SA75	10010XXXXX	256 (4x64)	SA127	1111111000	8
SA20-SA23	00101XXXXX	256 (4x64)	SA76-SA79	10011XXXXX	256 (4x64)	SA128	1111111001	8
SA24-SA27	00110XXXXX	256 (4x64)	SA80-SA83	10100XXXXX	256 (4x64)	SA129	1111111010	8
SA28-SA31	00111XXXXX	256 (4x64)	SA84-SA87	10101XXXXX	256 (4x64)	SA130	1111111011	8
SA32-SA35	01000XXXXX	256 (4x64)	SA88-SA91	10110XXXXX	256 (4x64)	SA131	1111111100	8
SA36-SA39	01001XXXXX	256 (4x64)	SA92-SA95	10111XXXXX	256 (4x64)	SA132	1111111101	8
SA40-SA43	01010XXXXX	256 (4x64)	SA96-SA99	11000XXXXX	256 (4x64)	SA133	1111111110	8
SA44-SA47	01011XXXXX	256 (4x64)	SA100-SA103	11001XXXXX	256 (4x64)	SA134	1111111111	8
SA48-SA51	01100XXXXX	256 (4x64)	SA104-SA107	11010XXXXX	256 (4x64)			
SA52-SA55	01101XXXXX	256 (4x64)	SA108-SA111	11011XXXXX	256 (4x64)	1		

Table I8. S29GL064A (Model R4) Bottom Boot Sector Protection/Unprotection Addresses

Sector	A21–A12	Sector/Sector Block Size (Kbytes)	Sector	A20–A12	Sector/Sector Block Size (Kbytes)	Sector	A20–A12	Sector/Sector Block Size (Kbytes)
SA0	0000000000	8	SA31-SA34	00110XXXXX	256 (4x64)	SA87–SA90	10100XXXXX	256 (4x64)
SA1	000000001	8	SA35-SA38	00111XXXXX	256 (4x64)	SA91–SA94	10101XXXXX	256 (4x64)
SA2	000000010	8	SA39-SA42	01000XXXXX	256 (4x64)	SA95–SA98	10110XXXXX	256 (4x64)
SA3	000000011	8	SA43-SA46	01001XXXXX	256 (4x64)	SA99–SA102	10111XXXXX	256 (4x64)
SA4	000000100	8	SA47-SA50	01010XXXXX	256 (4x64)	SA103-SA106	11000XXXXX	256 (4x64)
SA5	000000101	8	SA51-SA54	01011XXXXX	256 (4x64)	SA107–SA110	11001XXXXX	256 (4x64)
SA6	000000110	8	SA55-SA58	01100XXXXX	256 (4x64)	SA111-SA114	11010XXXXX	256 (4x64)
SA7	000000111	8	SA59–SA62	01101XXXXX	256 (4x64)	SA115-SA118	11011XXXXX	256 (4x64)
SA8-SA10	0000001XXX, 0000010XXX, 0000011XXX,	192 (3x64)	SA63-SA66	01110XXXXX	256 (4x64)	SA119-SA122	11100XXXXX	256 (4x64)
SA11-SA14	00001XXXXX	256 (4x64)	SA67-SA70	01111XXXXX	256 (4x64)	SA123-SA126	11101XXXXX	256 (4x64)
SA15-SA18	00010XXXXX	256 (4x64)	SA71-SA74	10000XXXXX	256 (4x64)	SA127-SA130	11110XXXXX	256 (4x64)
SA19-SA22	00011XXXXX	256 (4x64)	SA75-SA78	10001XXXXX	256 (4x64)	SA131-SA134	11111XXXXX	256 (4x64)
SA23-SA26	00100XXXXX	256 (4x64)	SA79–SA82	10010XXXXX	256 (4x64)			
SA27-SA30	00101XXXXX	256 (4x64)	SA83-SA86	10011XXXXX	256 (4x64)			

Table I9. S29GL064A (Model R5) Sector Group Protection/Unprotection Addresses

Sector Group	A21–A15						
SA0–SA3	00000	SA32–SA35	01000	SA64–SA67	10000	SA96-SA99	11000
SA4–SA7	00001	SA36–SA39	01001	SA68–SA71	10001	SA100-SA103	11001
SA8–SA11	00010	SA40-SA43	01010	SA72–SA75	10010	SA104-SA107	11010
SA12–SA15	00011	SA44–SA47	01011	SA76–SA79	10011	SA108-SA111	11011
SA16-SA19	00100	SA48–SA51	01100	SA80–SA83	10100	SA112-SA115	11100
SA20–SA23	00101	SA52–SA55	01101	SA84–SA87	10101	SA116-SA119	11101
SA24–SA27	00110	SA56-SA59	01110	SA88–SA91	10110	SA120-SA123	11110
SA28–SA31	00111	SA60-SA63	01111	SA92-SA95	10111	SA124-SA127	11111

Note: All sector groups are 128 Kwords in size.

Table 20. S29GL064A (Models R6, R7) Sector Group Protection/Unprotection Addresses

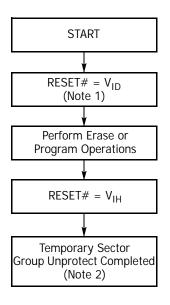
Sector Group	A21–A15						
SA0–SA3	00000	SA32–SA35	01000	SA64–SA67	10000	SA96-SA99	11000
SA4–SA7	00001	SA36–SA39	01001	SA68–SA71	10001	SA100-SA103	11001
SA8–SA11	00010	SA40–SA43	01010	SA72–SA75	10010	SA104-SA107	11010
SA12-SA15	00011	SA44–SA47	01011	SA76–SA79	10011	SA108-SA111	11011
SA16-SA19	00100	SA48–SA51	01100	SA80–SA83	10100	SA112-SA115	11100
SA20–SA23	00101	SA52–SA55	01101	SA84–SA87	10101	SA116-SA119	11101
SA24–SA27	00110	SA56-SA59	01110	SA88–SA91	10110	SA120-SA123	11110
SA28–SA31	00111	SA60–SA63	01111	SA92–SA95	10111	SA124-SA127	11111

Note: All sector groups are 128 Kwords in size.



Temporary Sector Group Unprotect

This feature allows temporary unprotection of previously protected sector groups to change data in-system. The Sector Group Unprotect mode is activated by setting the RESET# pin to V_{ID}. During this mode, formerly protected sector groups can be programmed or erased by selecting the sector group addresses. Once V_{ID} is removed from the RESET# pin, all the previously protected sector groups are protected again. Figure 1 shows the algorithm, and Figure 22 shows the timing diagrams, for this feature.

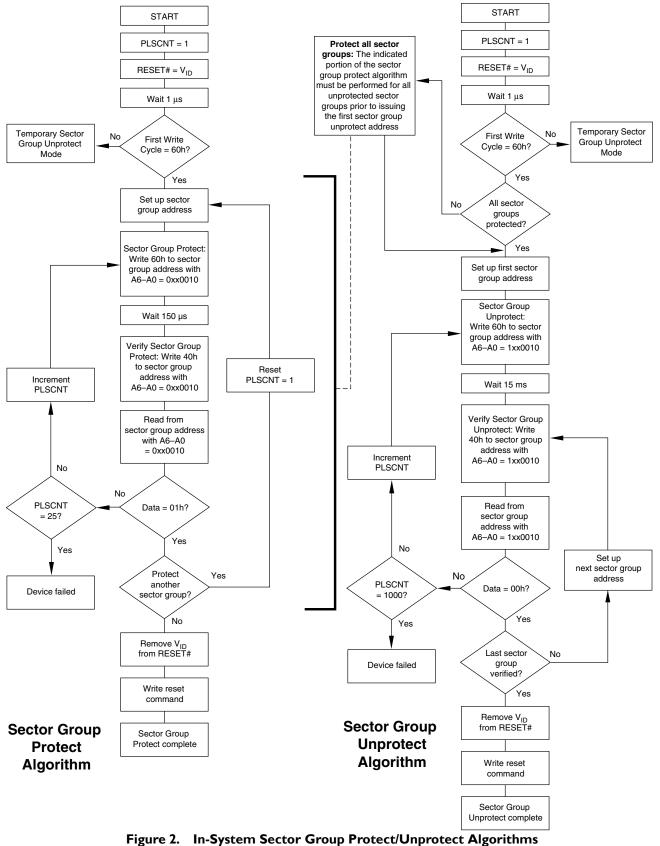


Notes:

- 1. All protected sector groups unprotected (If $WP\# = V_{IL}$, the highest or lowest address sector will remain protected for uniform sector devices; the top or bottom two address sectors will remain protected for boot sector devices).
- 2. All previously protected sector groups are protected once again.

Figure I. Temporary Sector Group Unprotect Operation





January 28, 2005 S29GLxxxA_00_A2



Secured Silicon Sector Flash Memory Region

The Secured Silicon Sector feature provides a Flash memory region that enables permanent part identification through an Electronic Serial Number (ESN). The Secured Silicon Sector is 256 bytes in length, and uses a Secured Silicon Sector Indicator Bit (DQ7) to indicate whether or not the Secured Silicon Sector is locked when shipped from the factory. This bit is permanently set at the factory and cannot be changed, which prevents cloning of a factory locked part. This ensures the security of the ESN once the product is shipped to the field.

The factory offers the device with the Secured Silicon Sector either customer lockable (standard shipping option) or factory locked (contact a Spansion sales representative for ordering information). The customer-lockable version is shipped with the Secured Silicon Sector unprotected, allowing customers to program the sector after receiving the device. The customer-lockable version also has the Secured Silicon Sector Indicator Bit permanently set to a "0." The factory-locked version is always protected when shipped from the factory, and has the Secured Silicon Sector Indicator Bit permanently set to a "1." Thus, the Secured Silicon Sector Indicator Bit permanently set to a "1." Thus, the Secured Silicon Sector Indicator Bit permanently set to a "1." Thus, the Secured Silicon Sector Indicator Bit prevents customer-lockable devices from being used to replace devices that are factory locked. *Note that the ACC function and unlock bypass modes are not available when the Secured Silicon Sector is enabled.*

Secured Silicon Sec	ctor Address Range			
x16	x8	Standard Factory Locked	ExpressFlash Factory Locked	Customer Lockable
000000h–000007h	000000h-00000Fh	ESN	ESN or determined by customer	Determined by customer
000008h-00007Fh	000010h-0000FFh	Unavailable	Determined by customer	

The Secured Silicon sector address space in this device is allocated as follows:

The system accesses the Secured Silicon Sector through a command sequence (see "Write Protect (WP#)"). After the system has written the Enter Secured Silicon Sector command sequence, it may read the Secured Silicon Sector by using the addresses normally occupied by the first sector (SAO). This mode of operation continues until the system issues the Exit Secured Silicon Sector command sequence, or until power is removed from the device. On power-up, or following a hardware reset, the device reverts to sending commands to sector SAO.

Customer Lockable: Secured Silicon Sector NOT Programmed or Protected At the Factory

Unless otherwise specified, the device is shipped such that the customer may program and protect the 256-byte Secured Silicon sector.

The system may program the Secured Silicon Sector using the write-buffer, accelerated and/or unlock bypass methods, in addition to the standard programming command sequence. See "Command Definitions" .

Programming and protecting the Secured Silicon Sector must be used with caution since, once protected, there is no procedure available for unprotecting the Secured Silicon Sector area and none of the bits in the Secured Silicon Sector memory space can be modified in any way.

The Secured Silicon Sector area can be protected using one of the following procedures:

Write the three-cycle Enter Secured Silicon Sector Region command sequence, and then follow the in-system sector protect algorithm as shown in



Figure 2, except that *RESET# may be at either* V_{IH} or V_{ID} . This allows in-system protection of the Secured Silicon Sector without raising any device pin to a high voltage. Note that this method is only applicable to the Secured Silicon Sector.

Write the three-cycle Enter Secured Silicon Sector Region command sequence, and then use the alternate method of sector protection described in the "Sector Group Protection and Unprotection" section.

Once the Secured Silicon Sector is programmed, locked and verified, the system must write the Exit Secured Silicon Sector Region command sequence to return to reading and writing within the remainder of the array.

Factory Locked: Secured Silicon Sector Programmed and Protected At the Factory

In devices with an ESN, the Secured Silicon Sector is protected when the device is shipped from the factory. The Secured Silicon Sector cannot be modified in any way. An ESN Factory Locked device has an 16-byte random ESN at addresses 000000h–000007h. Please contact your sales representative for details on ordering ESN Factory Locked devices.

Customers may opt to have their code programmed by the factory through the Spansion programming service (Customer Factory Locked). The devices are then shipped from the factory with the Secured Silicon Sector permanently locked. Contact your sales representative for details on using the Spansion programming service.

Write Protect (WP#)

The Write Protect function provides a hardware method of protecting the first or last sector group without using V_{ID} . Write Protect is one of two functions provided by the WP#/ACC input.

If the system asserts V_{IL} on the WP#/ACC pin, the device disables program and erase functions in the first or last sector group independently of whether those sector groups were protected or unprotected. Note that if WP#/ACC is at V_{IL} when the device is in the standby mode, the maximum input load current is increased. See the table in "DC Characteristics" section on page 65.

If the system asserts V_{IH} on the WP#/ACC pin, the device reverts to whether the first or last sector was previously set to be protected or unprotected using the method described in "Sector Group Protection and Unprotection". Note that WP# has an internal pullup; when unconnected, WP# is at V_{IH} .

Hardware Data Protection

The command sequence requirement of unlock cycles for programming or erasing provides data protection against inadvertent writes (refer to Table 25 and Table 26 for command definitions). In addition, the following hardware data protection measures prevent accidental erasure or programming, which might otherwise be caused by spurious system level signals during V_{CC} power-up and power-down transitions, or from system noise.

Low V_{CC} Write Inhibit

When V_{CC} is less than V_{LKO} , the device does not accept any write cycles. This protects data during V_{CC} power-up and power-down. The command register and all internal program/erase circuits are disabled, and the device resets to the read



mode. Subsequent writes are ignored until V_{CC} is greater than $V_{LKO}.$ The system must provide the proper signals to the control pins to prevent unintentional writes when V_{CC} is greater than $V_{LKO}.$

Write Pulse "Glitch" Protection

Noise pulses of less than 3 ns (typical) on OE#, CE# or WE# do not initiate a write cycle.

Logical Inhibit

Write cycles are inhibited by holding any one of OE# = V_{IL} , CE# = V_{IH} or WE# = V_{IH} . To initiate a write cycle, CE# and WE# must be a logical zero while OE# is a logical one.

Power-Up Write Inhibit

If WE# = CE# = V_{IL} and OE# = V_{IH} during power up, the device does not accept commands on the rising edge of WE#. The internal state machine is automatically reset to the read mode on power-up.



Common Flash Memory Interface (CFI)

The Common Flash Interface (CFI) specification outlines device and host system software interrogation handshake, which allows specific vendor-specified software algorithms to be used for entire families of devices. Software support can then be device-independent, JEDEC ID-independent, and forward- and backward-compatible for the specified flash device families. Flash vendors can standardize their existing interfaces for long-term compatibility.

This device enters the CFI Query mode when the system writes the CFI Query command, 98h, to address 55h, any time the device is ready to read array data. The system can read CFI information at the addresses given in Table 21-Table 24. To terminate reading CFI data, the system must write the reset command.

The system can also write the CFI query command when the device is in the autoselect mode. The device enters the CFI query mode, and the system can read CFI data at the addresses given in Table 21-Table 24. The system must write the reset command to return the device to reading array data.

For further information, please refer to the CFI Specification and CFI Publication 100. Alternatively, contact your sales representative for copies of these documents.

Addresses (x16)	Addresses (x8)	Data	Description
10h	20h	0051h	Query Unique ASCII string "QRY"
11h	22h	0052h	
12h	24h	0059h	
13h	26h	0002h	Primary OEM Command Set
14h	28h	0000h	
15h	2Ah	0040h	Address for Primary Extended Table
16h	2Ch	0000h	
17h	2Eh	0000h	Alternate OEM Command Set (00h = none exists)
18h	30h	0000h	
19h	32h	0000h	Address for Alternate OEM Extended Table (00h = none exists)
1Ah	34h	0000h	

Table 2I. CFI Query Identification String



Addresses (x16)	Addresses (x8)	Data	Description
1Bh	36h	0027h	V _{CC} Min. (write/erase) D7–D4: volt, D3–D0: 100 millivolt
1Ch	38h	0036h	V _{CC} Max. (write/erase) D7–D4: volt, D3–D0: 100 millivolt
1Dh	3Ah	0000h	V _{PP} Min. voltage (00h = no V _{PP} pin present)
1Eh	3Ch	0000h	V_{PP} Max. voltage (00h = no V_{PP} pin present)
1Fh	3Eh	0007h	Reserved for future use
20h	40h	0007h	Typical timeout for Min. size buffer write $2^{N} \mu s$ (00h = not supported)
21h	42h	000Ah	Typical timeout per individual block erase 2 [№] ms
22h	44h	0000h	Typical timeout for full chip erase 2^{N} ms (00h = not supported)
23h	46h	0001h	Reserved for future use
24h	48h	0005h	Max. timeout for buffer write 2 ^N times typical
25h	4Ah	0004h	Max. timeout per individual block erase 2 ^N times typical
26h	4Ch	0000h	Max. timeout for full chip erase 2^{N} times typical (00h = not supported)

Table 22. System Interface String

Note: CFI data related to V_{CC} and time-outs may differ from actual V_{CC} and time-outs of the product. Please consult the Ordering Information tables to obtain the V_{CC} range for particular part numbers. Please consult the Erase and Programming Performance table for typical timeout specifications.



Addresses	Addresses	Data	Description
(x16)	(x8)	Data	Description
27h	4Eh	00xxh	Device Size = 2^{N} byte
2711	4611	UUXXII	0017h = 64 Mb, 0016h = 32Mb
			Flash Device Interface description (refer to CFI publication 100)
28h	50h	000xh	0000h = x8-only bus devices
29h	52h	0000h	0001h = x16-only bus devices
			0002h = x8/x16 bus devices
2Ah	54h	0005h	Max. number of byte in multi-byte write = 2^{N}
2Bh	56h	0000h	(00h = not supported)
2Ch	58h	00xxh	Number of Erase Block Regions within device (01h = uniform device,
2011	5011	UUXXII	02h = boot device)
			Erase Block Region 1 Information
2Dh	5Ah	00xxh	(refer to the CFI specification or CFI publication 100)
2Eh	5Ch	000xh	007Fh, 0000h, 0020h, 0000h = 32 Mb (-R1, -R2)
2Fh 30h	5Eh 60h	00x0h 000xh	003Fh, 0000h, 0001h = 32 Mb (-R3, R4) 007Fh, 0000h, 0020h, 0000h = 64 Mb (-R1, -R2, -R8, -R9)
3011	0011	UUUXII	007Fh, 0000h, 0020h, 0000h = 64 Mb (-R1, -R2, -R6, -R9) 007Fh, 0000h, 0000h, 0001h = 64 Mb (-R3, -R4, -R5, -R6, -R7)
31h	60h	00xxh	Erase Block Region 2 Information (refer to CFI publication 100)
32h	64h	0000h	003Eh, 0000h, 0000h, 0001h = 32 Mb (-R1, -R2)
33h	66h	0000h	007Eh, 0000h, 0000h, 0001h = 64 Mb (-R1, -R2, -R8, -R9)
34h	68h	000xh	0000h, 0000h, 0000h, 0000h = all others
35h	6Ah	0000h	
36h	6Ch	0000h	Erase Block Region 3 Information (refer to CFI publication 100)
37h	6Eh	0000h	Lidse block Region 3 million atom (refer to or r publication roo)
38h	70h	0000h	
39h	72h	0000h	
3Ah	74h	0000h	Erase Block Region 4 Information (refer to CFI publication 100)
3Bh	76h	0000h	
3Ch	78h	0000h	

Table 23.	Device	Geometry	Definition
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Table 24.	Primary Vendor-Specific Extended Query
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Addresses (x16)	Addresses (x8)	Data	Description
40h 41h 42h	80h 82h 84h	0050h 0052h 0049h	Query-unique ASCII string "PRI"
43h	86h	0031h	Major version number, ASCII
44h	88h	0033h	Minor version number, ASCII
45h	8Ah	000xh	Address Sensitive Unlock (Bits 1-0) 0 = Required, 1 = Not Required Process Technology (Bits 7-2) 0010b = 200 nm MirrorBit 0009h = x8-only bus devices 0008h = all other devices
46h	8Ch	0002h	Erase Suspend 0 = Not Supported, 1 = To Read Only, 2 = To Read & Write
47h	8Eh	0001h	Sector Protect 0 = Not Supported, X = Number of sectors in per group
48h	90h	0001h	Sector Temporary Unprotect 00 = Not Supported, 01 = Supported
49h	92h	0004h	Sector Protect/Unprotect scheme 0004h = Standard Mode (Refer to Text)
4Ah	94h	0000h	Simultaneous Operation 00 = Not Supported, X = Number of Sectors in Bank
4Bh	96h	0000h	Burst Mode Type 00 = Not Supported, 01 = Supported
4Ch	98h	0001h	Page Mode Type 00 = Not Supported, 01 = 4 Word Page, 02 = 8 Word Page
4Dh	9Ah	00B5h	ACC (Acceleration) Supply Minimum 00h = Not Supported, D7-D4: Volt, D3-D0: 100 mV
4Eh	9Ch	00C5h	ACC (Acceleration) Supply Maximum 00h = Not Supported, D7-D4: Volt, D3-D0: 100 mV
4Fh	9Eh	00xxh	Top/Bottom Boot Sector Flag 02h = Bottom Boot Device, 03h = Top Boot Device, 04h = Uniform sectors bottom WP# protect, 05h = Uniform sectors top WP# protect
50h	A0h	0001h	Program Suspend 00h = Not Supported, 01h = Supported



Command Definitions

Writing specific address and data commands or sequences into the command register initiates device operations. Table 25 and Table 26 define the valid register command sequences. *Writing incorrect address and data values or writing them in the improper sequence may place the device in an unknown state.* A reset command is then required to return the device to reading array data.

All addresses are latched on the falling edge of WE# or CE#, whichever happens later. All data is latched on the rising edge of WE# or CE#, whichever happens first. Refer to the AC Characteristics section for timing diagrams.

Reading Array Data

The device is automatically set to reading array data after device power-up. No commands are required to retrieve data. The device is ready to read array data after completing an Embedded Program or Embedded Erase algorithm.

After the device accepts an Erase Suspend command, the device enters the erase-suspend-read mode, after which the system can read data from any nonerase-suspended sector. After completing a programming operation in the Erase Suspend mode, the system may once again read array data with the same exception. See the Erase Suspend/Erase Resume Commands section for more information.

The system *must* issue the reset command to return the device to the read (or erase-suspend-read) mode if DQ5 goes high during an active program or erase operation, or if the device is in the autoselect mode. See the next section, Reset Command, for more information.

See also Requirements for Reading Array Data in the Device Bus Operations section for more information. The Read-Only Operations—"AC Characteristics" section on page 67 provides the read parameters, and Figure 13 shows the timing diagram.

Reset Command

Writing the reset command resets the device to the read or erase-suspend-read mode. Address bits are don't cares for this command.

The reset command may be written between the sequence cycles in an erase command sequence before erasing begins. This resets the device to the read mode. Once erasure begins, however, the device ignores reset commands until the operation is complete.

The reset command may be written between the sequence cycles in a program command sequence before programming begins. This resets the device to the read mode. If the program command sequence is written while the device is in the Erase Suspend mode, writing the reset command returns the device to the erase-suspend-read mode. Once programming begins, however, the device ignores reset commands until the operation is complete.

The reset command may be written between the sequence cycles in an autoselect command sequence. Once in the autoselect mode, the reset command must be written to return to the read mode. If the device entered the autoselect mode while in the Erase Suspend mode, writing the reset command returns the device to the erase-suspend-read mode.



If DQ5 goes high during a program or erase operation, writing the reset command returns the device to the read mode (or erase-suspend-read mode if the device was in Erase Suspend).

Note that if DQ1 goes high during a Write Buffer Programming operation, the system must write the Write-to-Buffer-Abort Reset command sequence to reset the device for the next operation.

Autoselect Command Sequence

The autoselect command sequence allows the host system to read several identifier codes at specific addresses:

I dentifier Code	A7:A0 (x16)	A6:A-1 (x8)
Manufacturer ID	00h	00h
Device ID, Cycle 1	01h	02h
Device ID, Cycle 2	0Eh	1Ch
Device ID, Cycle 3	OFh	1Eh
Secured Silicon Sector Factory Protect	03h	06h
Sector Protect Verify	(SA)02h	(SA)04h

Note: The device ID is read over three cycles. SA = Sector Address

The autoselect command sequence is initiated by first writing two unlock cycles. This is followed by a third write cycle that contains the autoselect command. The device then enters the autoselect mode. The system may read at any address any number of times without initiating another autoselect command sequence:

The system must write the reset command to return to the read mode (or erasesuspend-read mode if the device was previously in Erase Suspend).

Enter Secured Silicon Sector/Exit Secured Silicon Sector Command Sequence

The Secured Silicon Sector region provides a secured data area containing an 8word/16-byte random Electronic Serial Number (ESN). The system can access the Secured Silicon Sector region by issuing the three-cycle Enter Secured Silicon Sector command sequence. The device continues to access the Secured Silicon Sector region until the system issues the four-cycle Exit Secured Silicon Sector command sequence. The Exit Secured Silicon Sector command sequence returns the device to normal operation. Table 25 and Table 26 show the address and data requirements for both command sequences. See also "Secured Silicon Sector Flash Memory Region" for further information. *Note that the ACC function and unlock bypass modes are not available when the Secured Silicon Sector is enabled.*

Word Program Command Sequence

Programming is a four-bus-cycle operation. The program command sequence is initiated by writing two unlock write cycles, followed by the program set-up command. The program address and data are written next, which in turn initiate the Embedded Program algorithm. The system is not required to provide further controls or timings. The device automatically provides internally generated program pulses and verifies the programmed cell margin. Table 25 and Table 26 show the address and data requirements for the word program command sequence, respectively.



When the Embedded Program algorithm is complete, the device then returns to the read mode and addresses are no longer latched. The system can determine the status of the program operation by using DQ7 or DQ6. Refer to the Write Operation Status section for information on these status bits. Any commands written to the device during the Embedded Program Algorithm are ignored. *Note that the Secured Silicon Sector, autoselect, and CFI functions are unavailable when a program operation is in progress.* Note that a **hardware reset** immediately terminates the program operation. The program command sequence should be reinitiated once the device has returned to the read mode, to ensure data integrity.

Programming is allowed in any sequence of address locations and across sector boundaries. Programming to the same word address multiple times without intervening erases (incremental bit programming) requires a modified programming method. For such application requirements, please contact your local Spansion representative. Word programming is supported for backward compatibility with existing Flash driver software and for occasional writing of individual words. Use of write buffer programming (see below) is strongly recommended for general programming use when more than a few words are to be programmed. The effective word programming time using write buffer programming is approximately four times shorter than the single word programming time.

Any bit in a word cannot be programmed from "O" back to a "1." Attempting to do so may cause the device to set DQ5=1, or cause DQ7 and DQ6 status bits to indicate the operation was successful. However, a succeeding read will show that the data is still "O." Only erase operations can convert a "O" to a "1."

Unlock Bypass Command Sequence

The unlock bypass feature allows the system to program words to the device faster than using the standard program command sequence. The unlock bypass command sequence is initiated by first writing two unlock cycles. This is followed by a third write cycle containing the unlock bypass command, 20h. The device then enters the unlock bypass mode. A two-cycle unlock bypass mode command sequence is all that is required to program in this mode. The first cycle in this sequence contains the unlock bypass program command, A0h; the second cycle contains the program address and data. Additional data is programmed in the same manner. This mode dispenses with the initial two unlock cycles required in the standard program command sequence, resulting in faster total programming time. Table 25 and Table 26 show the requirements for the command sequence.

During the unlock bypass mode, only the Unlock Bypass Program and Unlock Bypass Reset commands are valid. To exit the unlock bypass mode, the system must issue the two-cycle unlock bypass reset command sequence. The first cycle must contain the data 90h. The second cycle must contain the data 00h. The device then returns to the read mode.

Write Buffer Programming

Write Buffer Programming allows the system write to a maximum of 16 words/32 bytes in one programming operation. This results in faster effective programming time than the standard programming algorithms. The Write Buffer Programming command sequence is initiated by first writing two unlock cycles. This is followed by a third write cycle containing the Write Buffer Load command written at the Sector Address in which programming will occur. The fourth cycle writes the sector address and the number of word locations, minus one, to be programmed. For



example, if the system will program 6 unique address locations, then 05h should be written to the device. This tells the device how many write buffer addresses will be loaded with data and therefore when to expect the Program Buffer to Flash command. The number of locations to program cannot exceed the size of the write buffer or the operation will abort.

The fifth cycle writes the first address location and data to be programmed. The write-buffer-page is selected by address bits A_{MAX} - A_4 . All subsequent address/ data pairs must fall within the selected-write-buffer-page. The system then writes the remaining address/data pairs into the write buffer. Write buffer locations may be loaded in any order.

The write-buffer-page address must be the same for all address/data pairs loaded into the write buffer. (This means Write Buffer Programming cannot be performed across multiple write-buffer pages.) This also means that Write Buffer Programming cannot be performed across multiple sectors. If the system attempts to load programming data outside of the selected write-buffer page, the operation will abort.

Note that if a Write Buffer address location is loaded multiple times, the address/ data pair counter will be decremented for every data load operation. The host system must therefore account for loading a write-buffer location more than once. The counter decrements for each data load operation, not for each unique write-buffer-address location. Note also that if an address location is loaded more than once into the buffer, the final data loaded for that address will be programmed.

Once the specified number of write buffer locations have been loaded, the system must then write the Program Buffer to Flash command at the sector address. Any other address and data combination aborts the Write Buffer Programming operation. The device then begins programming. Data polling should be used while monitoring the last address location loaded into the write buffer. DQ7, DQ6, DQ5, and DQ1 should be monitored to determine the device status during Write Buffer Programming.

The write-buffer programming operation can be suspended using the standard program suspend/resume commands. Upon successful completion of the Write Buffer Programming operation, the device is ready to execute the next command.

The Write Buffer Programming Sequence can be aborted in the following ways:

- Load a value that is greater than the page buffer size during the Number of Locations to Program step.
- Write to an address in a sector different than the one specified during the Write-Buffer-Load command.
- Write an Address/Data pair to a different write-buffer-page than the one selected by the Starting Address during the write buffer data loading stage of the operation.
- Write data other than the Confirm Command after the specified number of data load cycles.

The abort condition is indicated by DQ1 = 1, DQ7 = DATA# (for the last address location loaded), DQ6 = toggle, and DQ5=0. A Write-to-Buffer-Abort Reset command sequence must be written to reset the device for the next operation.

Note that the Secured Silicon Sector, autoselect, and CFI functions are unavailable when a program operation is in progress. This flash device is capable of handling multiple write buffer programming operations on the same write buffer address range without intervening erases. For applications requiring incremental



bit programming, a modified programming method is required; please contact your local Spansion representative. **Any bit in a write buffer address range cannot be programmed from "O" back to a "1."** Attempting to do so may cause the device to set DQ5=1, of cause the DQ7 and DQ6 status bits to indicate the operation was successful. However, a succeeding read will show that the data is still "O." Only erase operations can convert a "O" to a "1."

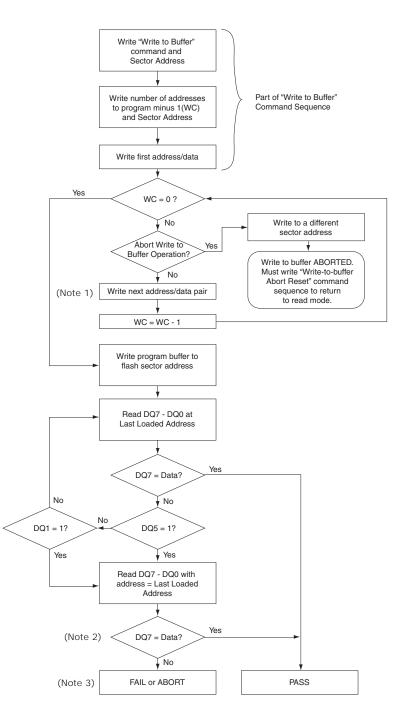
Accelerated Program

The device offers accelerated program operations through the WP#/ACC or ACC pin depending on the particular product. When the system asserts V_{HH} on the WP#/ACC or ACC pin. The device uses the higher voltage on the WP#/ACC or ACC pin to accelerate the operation. *Note that the* WP#/ACC *pin must not be at* V_{HH} *for operations other than accelerated programming, or device damage may result.* WP# has an internal pullup; when unconnected, WP# is at V_{HH} .

Figure 3 illustrates the algorithm for the program operation. Refer to the Erase and Program Operations—"AC Characteristics" section on page 67 section for parameters, and Figure 14 for timing diagrams.

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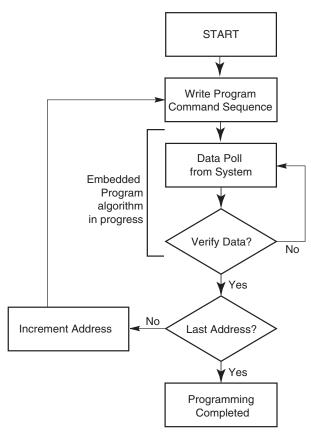


Notes:

- 1. When Sector Address is specified, any address in the selected sector is acceptable. However, when loading Write-Buffer address locations with data, all addresses must fall within the selected Write-Buffer Page.
- 2. DQ7 may change simultaneously with DQ5. Therefore, DQ7 should be verified.
- 3. If this flowchart location was reached because DQ5= "1", then the device FAILED. If this flowchart location was reached because DQ1= "1", then the Write to Buffer operation was ABORTED. In either case, the proper reset command must be written before the device can begin another operation. If DQ1=1, write the Write-Buffer-Programming-Abort-Reset command. if DQ5=1, write the Reset command.
- 4. See Table 25 and Table 26 for command sequences required for write buffer programming.

Figure 3. Write Buffer Programming Operation





*Note:*See *Table 25* and *Table 26* for program command sequence.

Figure 4. Program Operation

Program Suspend/Program Resume Command Sequence

The Program Suspend command allows the system to interrupt a programming operation or a Write to Buffer programming operation so that data can be read from any non-suspended sector. When the Program Suspend command is written during a programming process, the device halts the program operation within 15 μ s maximum (5 μ s typical) and updates the status bits. Addresses are not required when writing the Program Suspend command.

After the programming operation has been suspended, the system can read array data from any non-suspended sector. The Program Suspend command may also be issued during a programming operation while an erase is suspended. In this case, data may be read from any addresses not in Erase Suspend or Program Suspend. If a read is needed from the Secured Silicon Sector area (One-time Program area), then user must use the proper command sequences to enter and exit this region. Note that the Secured Silicon Sector, autoselect, and CFI functions are unavailable when a program operation is in progress.

The system may also write the autoselect command sequence when the device is in the Program Suspend mode. The system can read as many autoselect codes as required. When the device exits the autoselect mode, the device reverts to the Program Suspend mode, and is ready for another valid operation. See Autoselect Command Sequence for more information.



After the Program Resume command is written, the device reverts to programming. The system can determine the status of the program operation using the DQ7 or DQ6 status bits, just as in the standard program operation. See Write Operation Status for more information.

The system must write the Program Resume command (address bits are don't care) to exit the Program Suspend mode and continue the programming operation. Further writes of the Resume command are ignored. Another Program Suspend command can be written after the device has resumed programming.

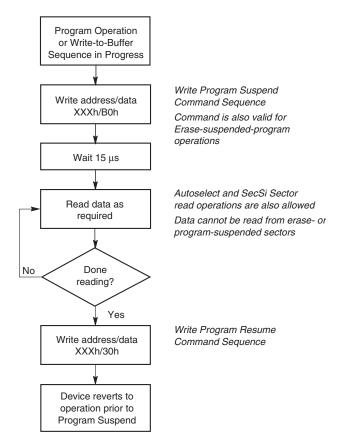


Figure 5. Program Suspend/Program Resume

Chip Erase Command Sequence

Chip erase is a six bus cycle operation. The chip erase command sequence is initiated by writing two unlock cycles, followed by a set-up command. Two additional unlock write cycles are then followed by the chip erase command, which in turn invokes the Embedded Erase algorithm. The device does *not* require the system to preprogram prior to erase. The Embedded Erase algorithm automatically preprograms and verifies the entire memory for an all zero data pattern prior to electrical erase. The system is not required to provide any controls or timings during these operations. Table 25 and Table 26 show the address and data requirements for the chip erase command sequence.

When the Embedded Erase algorithm is complete, the device returns to the read mode and addresses are no longer latched. The system can determine the status of the erase operation by using DQ7, DQ6, or DQ2. Refer to the Write Operation Status section for information on these status bits.



Any commands written during the chip erase operation are ignored. However, note that a **hardware reset** immediately terminates the erase operation. If that occurs, the chip erase command sequence should be reinitiated once the device has returned to reading array data, to ensure data integrity.

Figure 6 illustrates the algorithm for the erase operation. Refer to the Erase and Program Operations table in the AC Characteristics section for parameters, and Figure 18 section for timing diagrams.



Sector Erase Command Sequence

Sector erase is a six bus cycle operation. The sector erase command sequence is initiated by writing two unlock cycles, followed by a set-up command. Two additional unlock cycles are written, and are then followed by the address of the sector to be erased, and the sector erase command. Table 25 and Table 26 shows the address and data requirements for the sector erase command sequence.

The device does *not* require the system to preprogram prior to erase. The Embedded Erase algorithm automatically programs and verifies the entire memory for an all zero data pattern prior to electrical erase. The system is not required to provide any controls or timings during these operations.

After the command sequence is written, a sector erase time-out of 50 µs occurs. During the time-out period, additional sector addresses and sector erase commands may be written. Loading the sector erase buffer may be done in any sequence, and the number of sectors may be from one sector to all sectors. The time between these additional cycles must be less than 50 µs, otherwise erasure may begin. Any sector erase address and command following the exceeded time-out may or may not be accepted. It is recommended that processor interrupts be disabled during this time to ensure all commands are accepted. The interrupts can be re-enabled after the last Sector Erase Command is written. Any command other than Sector Erase or Erase Suspend during the time-out period resets the device to the read mode. Note that the Secured Silicon Sector, autoselect, and CFI functions are unavailable when an erase operation is in progress. The system must rewrite the command sequence and any additional addresses and commands.

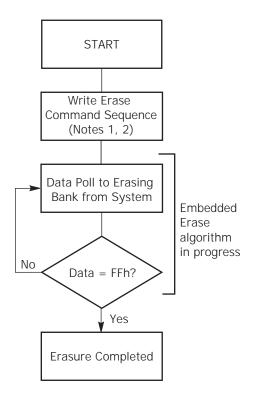
The system can monitor DQ3 to determine if the sector erase timer has timed out (See the section on DQ3: Sector Erase Timer.). The time-out begins from the rising edge of the final WE# pulse in the command sequence.

When the Embedded Erase algorithm is complete, the device returns to reading array data and addresses are no longer latched. The system can determine the status of the erase operation by reading DQ7, DQ6, or DQ2 in the erasing sector. Refer to the Write Operation Status section for information on these status bits.

Once the sector erase operation has begun, only the Erase Suspend command is valid. All other commands are ignored. However, note that a **hardware reset** immediately terminates the erase operation. If that occurs, the sector erase command sequence should be reinitiated once the device has returned to reading array data, to ensure data integrity.

Figure 6 illustrates the algorithm for the erase operation. Refer to the Erase and Program Operations table in the AC Characteristics section for parameters, and Figure 18 section for timing diagrams.





Notes:

- 1. See Table 25 and Table 26 for program command sequence.
- 2. See the section on DQ3 for information on the sector erase timer.

Figure 6. Erase Operation

Erase Suspend/Erase Resume Commands

The Erase Suspend command, B0h, allows the system to interrupt a sector erase operation and then read data from, or program data to, any sector not selected for erasure. This command is valid only during the sector erase operation, including the 50 μ s time-out period during the sector erase command sequence. The Erase Suspend command is ignored if written during the chip erase operation or Embedded Program algorithm.

When the Erase Suspend command is written during the sector erase operation, the device requires a typical of 5 μ s (maximum of 20 μ s) to suspend the erase operation. However, when the Erase Suspend command is written during the sector erase time-out, the device immediately terminates the time-out period and suspends the erase operation.

After the erase operation has been suspended, the device enters the erase-suspend-read mode. The system can read data from or program data to any sector not selected for erasure. (The device "erase suspends" all sectors selected for erasure.) Reading at any address within erase-suspended sectors produces status information on DQ7–DQ0. The system can use DQ7, or DQ6 and DQ2 together, to determine if a sector is actively erasing or is erase-suspended. Refer to the Write Operation Status section for information on these status bits.

After an erase-suspended program operation is complete, the device returns to the erase-suspend-read mode. The system can determine the status of the program operation using the DQ7 or DQ6 status bits, just as in the standard word



program operation. Refer to the Write Operation Status section for more information.

In the erase-suspend-read mode, the system can also issue the autoselect command sequence. Refer to the "Autoselect Mode" section on page 30 and "Autoselect Command Sequence" section on page 44 sections for details.

To resume the sector erase operation, the system must write the Erase Resume command. Further writes of the Resume command are ignored. Another Erase Suspend command can be written after the chip has resumed erasing.

Note:During an erase operation, this flash device performs multiple internal operations which are invisible to the system. When an erase operation is suspended, any of the internal operations that were not fully completed must be restarted. As such, if this flash device is continually issued suspend/resume commands in rapid succession, erase progress will be impeded as a function of the number of suspends. The result will be a longer cumulative erase time than without suspends. Note that the additional suspends do not affect device reliability or future performance. In most systems rapid erase/suspend activity occurs only briefly. In such cases, erase performance will not be significantly impacted.



Command Definitions

Command Sequence		ŝ					Bu	s Cycle	s (Notes 2	2–5)				
		Cycles	First		Second		Third		Fourth		Fifth		Sixth	
	(Note 1)	S	Addr	Data	Addr	Data	Addr	Data	Addr	Data	Addr	Data	Addr	Data
Read	d (Note 6)	1	RA	RD										
Rese	et (Note 7)	1	XXX	F0										
8)	Manufacturer ID	4	555	AA	2AA	55	555	90	X00	0001				
(Note	Device ID (Note 9)	4	555	AA	2AA	55	555	90	X01	227E	X0E	(Note 18)	X0F	(Note 18)
elect (Secured Silicon Sector Factory Protect (Note 10)	4	555	AA	2AA	55	555	90	X03	(Note 10)				
Autoselect	Sector Group Protect Verify (Note 12)	4	555	AA	2AA	55	555	90	(SA)X02	00/01				
Ente	r Secured Silicon Sector Region	3	555	AA	2AA	55	555	88						
Exit	Secured Silicon Sector Region	4	555	AA	2AA	55	555	90	XXX	00				
Prog	Iram	4	555	AA	2AA	55	555	A0	PA	PD				
Write	e to Buffer (Note 11)	3	555	AA	2AA	55	SA	25	SA	WC	PA	PD	WBL	PD
Prog	ram Buffer to Flash	1	SA	29										
Write	e to Buffer Abort Reset (Note 13)	3	555	AA	2AA	55	555	F0						
Unlo	ck Bypass	3	555	AA	2AA	55	555	20						
Unlo	ck Bypass Program (Note 14)	2	XXX	A0	PA	PD								
Unlo	ock Bypass Reset (Note 15)	2	XXX	90	XXX	00								
Chip Erase		6	555	AA	2AA	55	555	80	555	AA	2AA	55	555	10
Sect	Sector Erase		555	AA	2AA	55	555	80	555	AA	2AA	55	SA	30
Prog	ram/Erase Suspend (Note 16)	1	XXX	B0										
Prog	ram/Erase Resume (Note 17)	1	XXX	30										
CFI	Query (Note 18)	1	55	98										

Table 25. Command Definitions (xI6 Mode, BYTE# = VIH)

Legend:

X = Don't care

- RA = Read Address of memory location to be read.
- RD = Read Data read from location RA during read operation.

PA = Program Address. Addresses latch on falling edge of WE# or CE# pulse, whichever happens later.

Notes:

- 1. See Table 3 for description of bus operations.
- 2. All values are in hexadecimal.
- 3. Shaded cells indicate read cycles. All others are write cycles.
- 4. During unlock and command cycles, when lower address bits are 555 or 2AA as shown in table, address bits above A11 and data bits above DQ7 are don't care.
- 5. No unlock or command cycles required when device is in read mode.
- Reset command is required to return to read mode (or to erasesuspend-read mode if previously in Erase Suspend) when device is in autoselect mode, or if DQ5 goes high while device is providing status information.
- 7. Fourth cycle of the autoselect command sequence is a read cycle. Data bits DQ15–DQ8 are don't care. Except for RD, PD and WC. See Autoselect Command Sequence section for more information.
- 8. Device ID must be read in three cycles.
- If WP# protects highest address sector, data is 98h for factory locked and 18h for not factory locked. If WP# protects lowest address sector, data is 88h for factory locked and 08h for not factor locked.

PD = *Program Data for location PA. Data latches on rising edge of WE# or CE# pulse, whichever happens first.*

SA = Sector Address of sector to be verified (in autoselect mode) or erased. Address bits A21–A15 uniquely select any sector.

WBL = Write Buffer Location. Address must be within same write buffer page as PA.

WC = Word Count. Number of write buffer locations to load minus 1.

- 10. Data is 00h for an unprotected sector group and 01h for a protected sector group.
- 11. Total number of cycles in command sequence is determined by number of words written to write buffer. Maximum number of cycles in command sequence is 21, including "Program Buffer to Flash" command.
- 12. Command sequence resets device for next command after aborted write-to-buffer operation.
- 13. Unlock Bypass command is required prior to Unlock Bypass Program command.
- 14. Unlock Bypass Reset command is required to return to read mode when device is in unlock bypass mode.
- 15. System may read and program in non-erasing sectors, or enter autoselect mode, when in Erase Suspend mode. Erase Suspend command is valid only during a sector erase operation.
- 16. Erase Resume command is valid only during Erase Suspend mode.
- 17. Command is valid when device is ready to read array data or when device is in autoselect mode.
- 18. Refer to Table 12, AutoSelect Codes for individual Device IDs per device density and model number.



	Command	s						Bus C	ycles (No	otes 2–5)				
	Sequence		First		Sec	Second Third			Fo	urth	Fifth		Sixth	
	(Note 1)	Cycles	Addr	Data	Addr	Data	Addr	Data	Addr	Data	Addr	Data	Addr	Data
Rea	ad (Note 6)	1	RA	RD										
Res	set (Note 7)	1	XXX	F0										
8)	Manufacturer ID	4	AAA	AA	555	55	AAA	90	X00	01				
ote	Device ID (Note 9)	4	AAA	AA	555	55	AAA	90	X02	7E	X1C	(Note 17)	X1E	(Note 17)
S	Secured Silicon Sector Factory Protect (Note 10)	4	AAA	AA	555	55	AAA	90	X06	(Note 10)				
Autoselect	Sector Group Protect Verify (Note 12)	4	ААА	AA	555	55	AAA	90	(SA)X04	00/01				
Ent	er Secured Silicon Sector Region	3	AAA	AA	555	55	AAA	88						
Exit	Secured Silicon Sector Region	4	AAA	AA	555	55	AAA	90	XXX	00				
Wri	te to Buffer (Note 11)	3	AAA	AA	555	55	SA	25	SA	BC	PA	PD	WBL	PD
Pro	gram Buffer to Flash	1	SA	29										
Wri	te to Buffer Abort Reset (Note 13)	3	AAA	AA	555	55	AAA	F0						
Chi	p Erase	6	AAA	AA	555	55	AAA	80	AAA	AA	555	55	AAA	10
Sector Erase		6	AAA	AA	555	55	AAA	80	AAA	AA	555	55	SA	30
Pro	gram/Erase Suspend (Note 14)	1	XXX	B0										
Pro	gram/Erase Resume (Note 15)	1	XXX	30										
CFI	Query (Note 16)	1	AA	98										

Table 26. Command Definitions (x8 Mode, BYTE# = VIL)

Legend:

X = Don't care

RA = Read Address of memory location to be read.

RD = Read Data read from location RA during read operation.

PA = *Program Address. Addresses latch on falling edge of WE# or CE# pulse, whichever happens later.*

Notes:

- 1. See Table 3 for description of bus operations.
- 2. All values are in hexadecimal.
- 3. Shaded cells indicate read cycles. All others are write cycles.
- 4. During unlock and command cycles, when lower address bits are 555 or AAA as shown in table, address bits above A11 are don't care.
- 5. Unless otherwise noted, address bits A21–A11 are don't cares.
- 6. No unlock or command cycles required when device is in read mode.
- 7. Reset command is required to return to read mode (or to erasesuspend-read mode if previously in Erase Suspend) when device is in autoselect mode, or if DQ5 goes high while device is providing status information.
- 8. Fourth cycle of autoselect command sequence is a read cycle. Data bits DQ15–DQ8 are don't care. See Autoselect Command Sequence section or more information.
- 9. Device ID must be read in three cycles.

PD = Program Data for location PA. Data latches on rising edge of WE# or CE# pulse, whichever happens first.

SA = Sector Address of sector to be verified (in autoselect mode) or erased. Address bits A21–A15 uniquely select any sector.

WBL = Write Buffer Location. Address must be within same write buffer page as PA.

BC = Byte Count. Number of write buffer locations to load minus 1.

- 10. If WP# protects highest address sector, data is 98h for factory locked and 18h for not factory locked. If WP# protects lowest address sector, data is 88h for factory locked and 08h for not factor locked.
- 11. Data is 00h for an unprotected sector group and 01h for a protected sector group.
- 12. Total number of cycles in command sequence is determined by number of bytes written to write buffer. Maximum number of cycles in command sequence is 37, including "Program Buffer to Flash" command.
- 13. Command sequence resets device for next command after aborted write-to-buffer operation.
- 14. System may read and program in non-erasing sectors, or enter autoselect mode, when in Erase Suspend mode. Erase Suspend command is valid only during a sector erase operation.
- 15. Erase Resume command is valid only during Erase Suspend mode.
- Command is valid when device is ready to read array data or when device is in autoselect mode.
- 17. Refer to Table 12, AutoSelect Codes for individual Device IDs per device density and model number.



Write Operation Status

The device provides several bits to determine the status of a program or erase operation: DQ2, DQ3, DQ5, DQ6, and DQ7. Table 27 and the following subsections describe the function of these bits. DQ7 and DQ6 each offer a method for determining whether a program or erase operation is complete or in progress. The device also provides a hardware-based output signal, RY/BY#, to determine whether an Embedded Program or Erase operation is in progress or has been completed.

DQ7: Data# Polling

The Data# Polling bit, DQ7, indicates to the host system whether an Embedded Program or Erase algorithm is in progress or completed, or whether the device is in Erase Suspend. Data# Polling is valid after the rising edge of the final WE# pulse in the command sequence.

During the Embedded Program algorithm, the device outputs on DQ7 the complement of the datum programmed to DQ7. This DQ7 status also applies to programming during Erase Suspend. When the Embedded Program algorithm is complete, the device outputs the datum programmed to DQ7. The system must provide the program address to read valid status information on DQ7. If a program address falls within a protected sector, Data# Polling on DQ7 is active for approximately 1 μ s, then the device returns to the read mode.

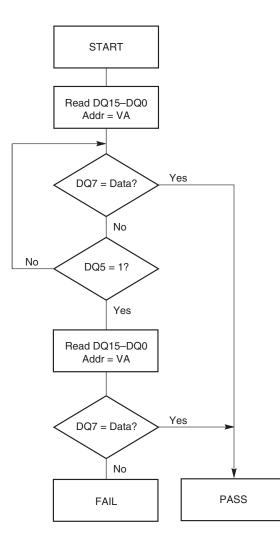
During the Embedded Erase algorithm, Data# Polling produces a "0" on DQ7. When the Embedded Erase algorithm is complete, or if the device enters the Erase Suspend mode, Data# Polling produces a "1" on DQ7. The system must provide an address within any of the sectors selected for erasure to read valid status information on DQ7.

After an erase command sequence is written, if all sectors selected for erasing are protected, Data# Polling on DQ7 is active for approximately 100 μ s, then the device returns to the read mode. If not all selected sectors are protected, the Embedded Erase algorithm erases the unprotected sectors, and ignores the selected sectors that are protected. However, if the system reads DQ7 at an address within a protected sector, the status may not be valid.

Just prior to the completion of an Embedded Program or Erase operation, DQ7 may change asynchronously with DQ0–DQ6 while Output Enable (OE#) is asserted low. That is, the device may change from providing status information to valid data on DQ7. Depending on when the system samples the DQ7 output, it may read the status or valid data. Even if the device has completed the program or erase operation and DQ7 has valid data, the data outputs on DQ0–DQ6 may be still invalid. Valid data on DQ0–DQ7 will appear on successive read cycles.

Table 27 shows the outputs for Data# Polling on DQ7. Figure 7 shows the Data# Polling algorithm. Figure 19 in the AC Characteristics section shows the Data# Polling timing diagram.





Notes:

- 1. VA = Valid address for programming. During a sector erase operation, a valid address is any sector address within the sector being erased. During chip erase, a valid address is any non-protected sector address.
- 2. DQ7 should be rechecked even if DQ5 = "1" because DQ7 may change simultaneously with DQ5.

Figure 7. Data# Polling Algorithm

RY/BY#: Ready/Busy#

The RY/BY# is a dedicated, open-drain output pin which indicates whether an Embedded Algorithm is in progress or complete. The RY/BY# status is valid after the rising edge of the final WE# pulse in the command sequence. Since RY/BY# is an open-drain output, several RY/BY# pins can be tied together in parallel with a pull-up resistor to V_{CC}.

If the output is low (Busy), the device is actively erasing or programming. (This includes programming in the Erase Suspend mode.) If the output is high (Ready), the device is in the read mode, the standby mode, or in the erase-suspend-read mode. Table 27 shows the outputs for RY/BY#.



DQ6: Toggle Bit I

Toggle Bit I on DQ6 indicates whether an Embedded Program or Erase algorithm is in progress or complete, or whether the device has entered the Erase Suspend mode. Toggle Bit I may be read at any address, and is valid after the rising edge of the final WE# pulse in the command sequence (prior to the program or erase operation), and during the sector erase time-out.

During an Embedded Program or Erase algorithm operation, successive read cycles to any address cause DQ6 to toggle. The system may use either OE# or CE# to control the read cycles. When the operation is complete, DQ6 stops toggling.

After an erase command sequence is written, if all sectors selected for erasing are protected, DQ6 toggles for approximately 100 μ s, then returns to reading array data. If not all selected sectors are protected, the Embedded Erase algorithm erases the unprotected sectors, and ignores the selected sectors that are protected.

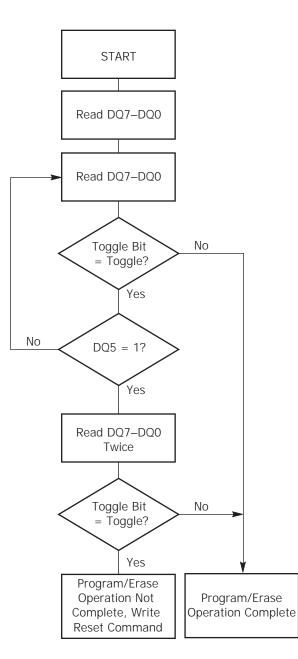
The system can use DQ6 and DQ2 together to determine whether a sector is actively erasing or is erase-suspended. When the device is actively erasing (that is, the Embedded Erase algorithm is in progress), DQ6 toggles. When the device enters the Erase Suspend mode, DQ6 stops toggling. However, the system must also use DQ2 to determine which sectors are erasing or erase-suspended. Alternatively, the system can use DQ7 (see the subsection on DQ7: Data# Polling).

If a program address falls within a protected sector, DQ6 toggles for approximately 1 μ s after the program command sequence is written, then returns to reading array data.

DQ6 also toggles during the erase-suspend-program mode, and stops toggling once the Embedded Program algorithm is complete.

Table 27 shows the outputs for Toggle Bit I on DQ6. Figure 8 shows the toggle bit algorithm. Figure 20 in the "AC Characteristics" section shows the toggle bit timing diagrams. Figure 21 shows the differences between DQ2 and DQ6 in graphical form. See also the subsection on DQ2: Toggle Bit II.





Notes:

1. The system should recheck the toggle bit even if DQ5 = "1" because the toggle bit may stop toggling as DQ5 changes to "1." See the subsections on DQ6 and DQ2 for more information.

Figure 8. Toggle Bit Algorithm



DQ2: Toggle Bit II

The "Toggle Bit II" on DQ2, when used with DQ6, indicates whether a particular sector is actively erasing (that is, the Embedded Erase algorithm is in progress), or whether that sector is erase-suspended. Toggle Bit II is valid after the rising edge of the final WE# pulse in the command sequence.

DQ2 toggles when the system reads at addresses within those sectors that have been selected for erasure. (The system may use either OE# or CE# to control the read cycles.) But DQ2 cannot distinguish whether the sector is actively erasing or is erase-suspended. DQ6, by comparison, indicates whether the device is actively erasing, or is in Erase Suspend, but cannot distinguish which sectors are selected for erasure. Thus, both status bits are required for sector and mode information. Refer to Table 27 to compare outputs for DQ2 and DQ6.

Figure 8 shows the toggle bit algorithm in flowchart form, and the section "DQ2: Toggle Bit II" explains the algorithm. See also the RY/BY#: Ready/Busy# subsection. Figure 20 shows the toggle bit timing diagram. Figure 21 shows the differences between DQ2 and DQ6 in graphical form.

Reading Toggle Bits DQ6/DQ2

Refer to Figure 8 for the following discussion. Whenever the system initially begins reading toggle bit status, it must read DQ7–DQ0 at least twice in a row to determine whether a toggle bit is toggling. Typically, the system would note and store the value of the toggle bit after the first read. After the second read, the system would compare the new value of the toggle bit with the first. If the toggle bit is not toggling, the device has completed the program or erase operation. The system can read array data on DQ7–DQ0 on the following read cycle.

However, if after the initial two read cycles, the system determines that the toggle bit is still toggling, the system also should note whether the value of DQ5 is high (see the section on DQ5). If it is, the system should then determine again whether the toggle bit is toggling, since the toggle bit may have stopped toggling just as DQ5 went high. If the toggle bit is no longer toggling, the device has successfully completed the program or erase operation. If it is still toggling, the device did not completed the operation successfully, and the system must write the reset command to return to reading array data.

The remaining scenario is that the system initially determines that the toggle bit is toggling and DQ5 has not gone high. The system may continue to monitor the toggle bit and DQ5 through successive read cycles, determining the status as described in the previous paragraph. Alternatively, it may choose to perform other system tasks. In this case, the system must start at the beginning of the algorithm when it returns to determine the status of the operation (top of Figure 8).

DQ5: Exceeded Timing Limits

DQ5 indicates whether the program, erase, or write-to-buffer time has exceeded a specified internal pulse count limit. Under these conditions DQ5 produces a "1," indicating that the program or erase cycle was not successfully completed.

The device may output a "1" on DQ5 if the system tries to program a "1" to a location that was previously programmed to "0." **Only an erase operation can change a "0" back to a "1."** Under this condition, the device halts the operation, and when the timing limit has been exceeded, DQ5 produces a "1."



In all these cases, the system must write the reset command to return the device to the reading the array (or to erase-suspend-read if the device was previously in the erase-suspend-program mode).

DQ3: Sector Erase Timer

After writing a sector erase command sequence, the system may read DQ3 to determine whether or not erasure has begun. (The sector erase timer does not apply to the chip erase command.) If additional sectors are selected for erasure, the entire time-out also applies after each additional sector erase command. When the time-out period is complete, DQ3 switches from a "0" to a "1." If the time between additional sector erase commands from the system can be assumed to be less than 50 μ s, the system need not monitor DQ3. See also the Sector Erase Command Sequence section.

After the sector erase command is written, the system should read the status of DQ7 (Data# Polling) or DQ6 (Toggle Bit I) to ensure that the device has accepted the command sequence, and then read DQ3. If DQ3 is "1," the Embedded Erase algorithm has begun; all further commands (except Erase Suspend) are ignored until the erase operation is complete. If DQ3 is "0," the device will accept additional sector erase commands. To ensure the command has been accepted, the system software should check the status of DQ3 prior to and following each subsequent sector erase command. If DQ3 is high on the second status check, the last command might not have been accepted.

Table 27 shows the status of DQ3 relative to the other status bits.

DQI: Write-to-Buffer Abort

DQ1 indicates whether a Write-to-Buffer operation was aborted. Under these conditions DQ1 produces a "1". The system must issue the Write-to-Buffer-Abort-Reset command sequence to return the device to reading array data. See Write Buffer section for more details.



	Stat	us	DQ7 (Note 2)	DQ6	DQ5 (Note 1)	DQ3	DQ2 (Note 2)	DQ1	RY/ BY#
Standard	Embedded F	Program Algorithm	DQ7#	Toggle	0	N/A	No toggle	0	0
Mode	Embedded	Erase Algorithm	0	Toggle	0	1	Toggle	N/A	0
Program Program-		Program-Suspended Sector		I	nvalid (not	allowed)			1
Suspend Mode	Suspend Read	Non-Program Suspended Sector	Data						
	Erase-	Erase-Suspended Sector	1	No toggle	0	N/A	Toggle	N/A	1
Erase Suspend Mode	Suspend Read	Non-Erase Suspended Sector			Data	3			1
	Erase-Susp (Embedded	end-Program Program)	DQ7#	Toggle	0	N/A	N/A	N/A	0
Write-to-	Busy (Note	3)	DQ7#	Toggle	0	N/A	N/A	0	0
Buffer	Abort (Note	e 4)	DQ7#	Toggle	0	N/A	N/A	1	0

Table 27	Write	Operation	Status
Table 17.	VVIIC	operation	Juarus

Notes:

1. DQ5 switches to '1' when an Embedded Program, Embedded Erase, or Write-to-Buffer operation has exceeded the maximum timing limits. Refer to the section on DQ5 for more information.

2. DQ7 and DQ2 require a valid address when reading status information. Refer to the appropriate subsection for further details.

3. The Data# Polling algorithm should be used to monitor the last loaded write-buffer address location.

4. DQ1 switches to '1' when the device has aborted the write-to-buffer operation.



Absolute Maximum Ratings

Storage Temperature, Plastic Packages65°C to +150°C
Ambient Temperature with Power Applied
Voltage with Respect to Ground:
V _{CC} (Note 1)0.5 V to +4.0 V
A9, OE#, ACC and RESET# (Note 2)
All other pins (Note 1)
Output Short Circuit Current (Note 3)

Notes:

- 1. Minimum DC voltage on input or I/Os is -0.5 V. During voltage transitions, inputs or I/Os may overshoot V_{SS} to -2.0 V for periods of up to 20 ns. See Figure 9. Maximum DC voltage on input or I/Os is V_{CC} + 0.5 V. During voltage transitions, input or I/O pins may overshoot to V_{CC} + 2.0 V for periods up to 20 ns. See Figure 10.
- Minimum DC input voltage on pins A9, OE#, ACC, and RESET# is -0.5 V. During voltage transitions, A9, OE#, ACC, and RESET# may overshoot V_{SS} to -2.0 V for periods of up to 20 ns. See Figure 9. Maximum DC input voltage on pin A9, OE#, ACC, and RESET# is +12.5 V which may overshoot to +14.0V for periods up to 20 ns.
- 3. No more than one output may be shorted to ground at a time. Duration of the short circuit should not be greater than one second.
- 4. Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational sections of this data sheet is not implied. Exposure of the device to absolute maximum rating conditions for extended periods may affect device reliability.

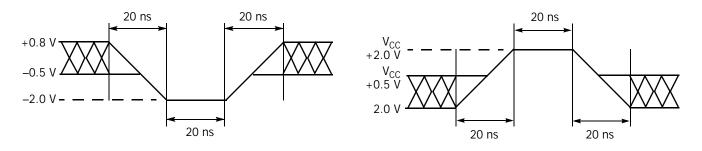


Figure 9. Maximum Negative Overshoot Waveform

Figure I0. Maximum Positive Overshoot Waveform

Operating Ranges

Note: Operating ranges define those limits between which the functionality of the device is guaranteed.



DC Characteristics

CMOS Compatible

Parameter Symbol	Parameter Description (Notes)	Test Cond	Min	Тур	Max	Unit	
I _{LI}	Input Load Current (Note 1)					±1.0	μA
I _{LIT}	A9, ACC Input Load Current	V _{CC} = V _{CC max} ; A9 = 12.5 V	-40°C to 0°C			250	μA
'LII		12.5 V 0°C to 85°C				35	μΛ
I _{LR}	Reset Leakage Current	$V_{CC} = V_{CC max}; RESE$	T# = 12.5 V			35	μΑ
I _{LO}	Output Leakage Current	$V_{OUT} = V_{SS}$ to V_{CC} , $V_{CC} = V_{CC max}$				±1.0	μΑ
			1 MHz		5	20	
I _{CC1}	V _{CC} Initial Read Current (Notes 2, 3)	$CE\# = V_{IL} OE\# = V_{IH}$	5 MHz		18	25	mA
			10 MHz		35	50	
1	V _{CC} Intra-Page Read Current (Notes 2, 3)	CE# = V _{IL} , OE# = V _{IH}	10 MHz		5	20	mA
I _{CC2}		$CL_{\#} = V_{IL}, OL_{\#} = V_{IH}$	40 MHz		10	40	
I _{CC3}	V _{CC} Active Write Current (Note 3)	$CE\# = V_{IL}, OE\# = V_{II}$	Н		50	60	mA
I _{CC4}	V _{CC} Standby Current (Note 3)	CE#, RESET# = V_{CC} = WP# = V_{IH}	CE#, RESET# = $V_{CC} \pm 0.3 V$, WP# = V_{IH}		1	5	μA
I _{CC5}	V _{CC} Reset Current (Note 3)	$RESET\# = V_{SS}\pm 0.3V$	V, WP# = V_{IH}		1	5	μA
I _{CC6}	Automatic Sleep Mode (Notes 3, 5)		$P\# = V_{IH}$		1	5	μΑ
V _{IL}	Input Low Voltage 1 (Note 6)			-0.5		0.8	V
V _{IH}	Input High Voltage 1 (Note 6)			0.7 V _{CC}		$V_{CC} + 0.5$	V
V _{HH}	Voltage for ACC Program Acceleration	$V_{CC} = 2.7 - 3.6 V$		11.5	12.0	12.5	V
V _{ID}	Voltage for Autoselect and Temporary Sector Unprotect	V _{CC} = 2.7 –3.6 V 11.			12.0	12.5	v
V _{OL}	Output Low Voltage (Note 6)	I_{OL} = 4.0 mA, V_{CC} = $V_{CC min}$				0.45	V
V _{OH1}	Output High Voltage	$I_{OH} = -2.0 \text{ mA}, V_{CC} = V_{CC \text{ min}}$		0.85 V _{CC}			V
V _{OH2}	Output High Voltage	$I_{OH} = -100 \ \mu\text{A}, \ V_{CC} = V_{CC \ min}$ V		V _{CC} -0.4			V
V _{LKO}	Low V _{CC} Lock-Out Voltage (Note 7)	2.3				2.5	V

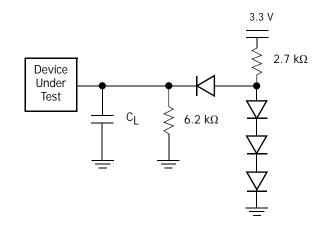
Notes:

1. On the WP#/ACC pin only, the maximum input load current when WP# = V_{IL} is \pm 5.0 μ A.

- 2. The I_{CC} current listed is typically less than 3.5 mA/MHz, with OE# at V_{IH}.
- 3. Maximum I_{CC} specifications are tested with $V_{CC} = V_{CC}max$.
- 4. I_{CC} active while Embedded Erase or Embedded Program is in progress.
- 5. Automatic sleep mode enables the low power mode when addresses remain stable for t_{ACC} + 30 ns.
- 6. V_{CC} voltage requirements.
- 7. Not 100% tested.



Test Conditions



Test Condition	All Speeds	Unit		
Output Load	1 TTL gate			
Output Load Capacitance, C _L (including jig capacitance)	30	рF		
Input Rise and Fall Times	5	ns		
Input Pulse Levels	0.0 or V_{CC}	V		
Input timing measurement reference levels (See Note)	0.5 V _{CC}	V		
Output timing measurement reference levels	0.5 V _{CC}	V		

Table 28. Test Specifications

Note: Diodes are IN3064 or equivalent.

Figure II. Test Setup

Key to Switching Waveforms

Waveform	Inputs	Outputs				
		Steady				
	Cha	inging from H to L				
	Cha	anging from L to H				
XXXXXX	Don't Care, Any Change Permitted	Changing, State Unknown				
$\square $	Does Not Apply Center Line is High Impedance State (High Z)					



Figure I2. Input Waveforms and Measurement Levels



AC Characteristics Read-Only Operations-S29GL064A only

Param	eter					Speed Options			
JEDEC	Std.	Des	scription	Test Setup		90	10	11	Unit
t _{AVAV}	t _{RC}	Read Cycle Time (Note 1)			Min	90	100	110	ns
t _{AVQV}	t _{ACC}	Address to Output Delay		CE#, OE# = V_{IL}	Max	90	100	110	ns
t _{ELQV}	t _{CE}	Chip Enable to Output Delay		$OE\# = V_{IL}$	Max	90	100	110	ns
	t _{PACC}	Page Access Time			Max	25	30	30	ns
t _{GLQV}	t _{OE}	Output Enable to Output Delay			Max	25	30	30	ns
t _{EHQZ}	t _{DF}	Chip Enable to Output High Z (Note 1)			Max		16		ns
t _{GHQZ}	t _{DF}	Output Enable to Output High	Z (Note 1)		Max	16			ns
t _{AXQX}	t _{OH}	Output Hold Time From Addres First	ses, CE# or OE#, Whichever Occurs		Min	0		ns	
		Output Enable Hold Time	Read		Min		0		ns
	t _{OEH} (Note 1)	Toggle and Data# Polling		Min		10		ns	

Notes:

1. Not 100% tested.

2. See Figure 11 and Table 28 for test specifications.

Read-Only Operations-S29GL032A only

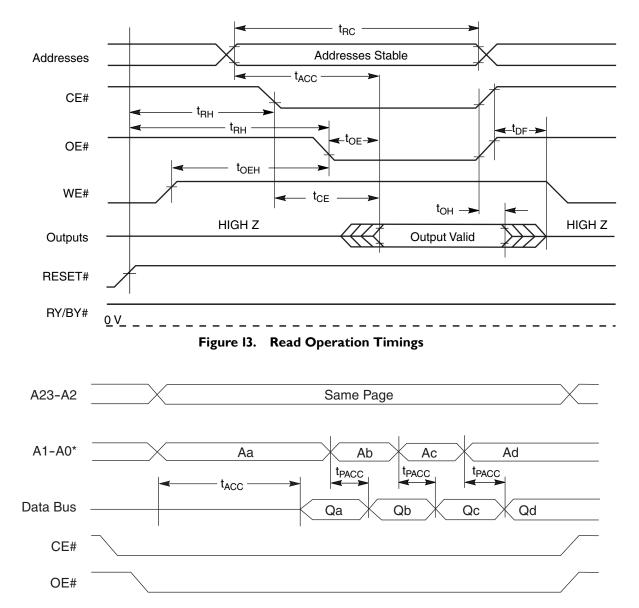
Param	neter					Sp	eed Opt	ions	
JEDEC	Std.	Description		Test Setup		90	10	11	Unit
t _{AVAV}	t _{RC}	Read Cycle Time (Note 1)			Min	90	100	110	ns
t _{AVQV}	t _{ACC}	Address to Output Delay		CE#, OE# = V_{IL}	Max	90	100	110	ns
t _{ELQV}	t _{CE}	Chip Enable to Output Delay		OE# = V _{IL}	Max	90	100	110	ns
	t _{PACC}	Page Access Time			Max	25	30	30	ns
t _{GLQV}	t _{OE}	Output Enable to Output Delay			Мах	25	30	30	ns
t _{EHQZ}	t _{DF}	Chip Enable to Output High Z (Note 1)			Max 16			ns	
t _{GHQZ}	t _{DF}	Output Enable to Output High Z (Note 1)			Max 16			ns	
t _{AXQX}	t _{ОН}	Output Hold Time From Addresses, CE# or OE#, Whichever Occurs First			Min 0			ns	
		Read			Min		0		ns
	^t оен	Output Enable Hold Time (Note 1)	old Time (Note 1) Toggle and Data# Polling		Min		10		ns

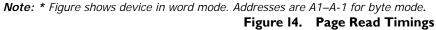
Notes:

1. Not 100% tested.

2. See Figure 11 and Table 28 for test specifications.





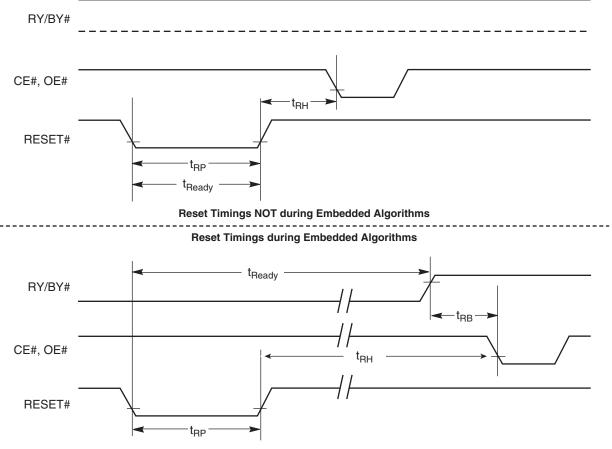




Hardware Reset (RESET#)

Paran	neter				
JEDEC	Std.	Description	Description		Unit
	t _{Ready}	RESET# Pin Low (During Embedded Algorithms) to Read Mode (See Note)	Max	20	μS
	t _{Ready}	RESET# Pin Low (NOT During Embedded Algorithms) to Read Mode (See Note)	Max	500	ns
	t _{RP}	RESET# Pulse Width	Min	500	ns
	t _{RH}	Reset High Time Before Read (See Note)	Min	50	ns
	t _{RPD}	RESET# Input Low to Standby Mode (See Note)	Min	20	μs
	t _{RB}	RY/BY# Output High to CE#, OE# pin Low	Min	0	ns

Note:Not 100% tested.



Notes:

- 1. Not 100% tested.
- 2. See the "Erase and Programming Performance" section for more information.
- 3. For 1–16 words/1–32 bytes programmed.



Erase and Program Operations-S29GL064A Only

Para	meter			S	peed Option	าร	
JEDEC	Std.	Description		90	10	11	Unit
t _{AVAV}	t _{WC}	Write Cycle Time (Note 1)	Min	90	100	110	ns
t _{AVWL}	t _{AS}	Address Setup Time	Min		0		ns
	t _{ASO}	Address Setup Time to OE# low during toggle bit polling	Min		15		ns
t _{WLAX}	t _{AH}	Address Hold Time	Min		45		ns
	t _{AHT}	Address Hold Time From CE# or OE# high during toggle bit polling	Min		0		ns
t _{DVWH}	t _{DS}	Data Setup Time	Min		35		ns
t _{WHDX}	t _{DH}	Data Hold Time	Min		0		ns
	t _{CEPH}	CE# High during toggle bit polling	Min		20		ns
	t _{OEPH}	OE# High during toggle bit polling	Min	20			ns
t _{GHWL}	t _{GHWL}	Read Recovery Time Before Write (OE# High to WE# Low)	Min	0		ns	
t _{ELWL}	t _{CS}	CE# Setup Time	Min	0		ns	
t _{WHEH}	t _{CH}	CE# Hold Time	Min		0		ns
t _{WLWH}	t _{WP}	Write Pulse Width	Min		35		ns
t _{WHDL}	t _{WPH}	Write Pulse Width High	Min		30		ns
		Write Buffer Program Operation (Notes 2, 3)	Тур		240		
t _{WHWH1}	t _{WHWH1}	Single Word Program Operation (Note 2)	Тур		60		μs
		Accelerated Single Word Program Operation (Note 2)	Тур		54		
t _{WHWH2}	t _{WHWH2}	Sector Erase Operation (Note 2)	Тур	0.5		sec	
	t _{VHH}	V _{HH} Rise and Fall Time (Note 1)	Min		250		ns
	t _{VCS}	V _{CC} Setup Time (Note 1)	Min	50		μs	
	t _{BUSY}	WE# High to RY/BY# Low	Min	90	100	110	ns
	t _{POLL}	Program Valid before Status Polling	Max		4		μs

Notes:

1. Not 100% tested.

- 2. See the "Erase and Programming Performance" section for more information.
- 3. For 1–16 words/1–32 bytes programmed.
- 4. If a program suspend command is issued within t_{POLL}, the device requires t_{POLL} before reading status data, once programming has resumed (that is, the program resume command has been written). If the suspend command was issued after t_{POLL}, status data is available immediately after programming has resumed. See Figure 16.



Erase and Program Operations-S29GL032A Only

Parameter				S	peed Opti	ions	
JEDEC	Std.	Description		90	10	11	Unit
t _{AVAV}	t _{WC}	Write Cycle Time (Note 1)	Min	90	100	110	ns
t _{AVWL}	t _{AS}	Address Setup Time	Min		0		ns
	t _{ASO}	Address Setup Time to OE# low during toggle bit polling	Min		15		ns
t _{WLAX}	t _{AH}	Address Hold Time	Min		45		ns
	t _{AHT}	Address Hold Time From CE# or OE# high during toggle bit polling	Min		0		ns
t _{DVWH}	t _{DS}	Data Setup Time	Min		35		ns
t _{WHDX}	t _{DH}	Data Hold Time	Min		0		ns
	t _{CEPH}	CE# High during toggle bit polling Min					ns
	t _{OEPH}	OE# High during toggle bit polling	Min 20				ns
t _{GHWL}	t _{GHWL}	Read Recovery Time Before Write (OE# High to WE# Low)	Min	n 0			ns
t _{ELWL}	t _{CS}	CE# Setup Time	Min	in O			ns
t _{WHEH}	t _{CH}	CE# Hold Time	Min	Min 0			ns
t _{WLWH}	t _{WP}	Write Pulse Width	Min	Vin 35			ns
t _{WHDL}	t _{WPH}	Write Pulse Width High	Min		30		ns
		Write Buffer Program Operation (Notes 2, 3)	Тур	/p 240			
t _{WHWH1}	t _{WHWH1}	Single Word Program Operation (Note 2)	Тур	60			μs
		Accelerated Single Word Program Operation (Note 2) Typ			54		
t _{WHWH2}	t _{WHWH2}	Sector Erase Operation (Note 2) Typ 0.5				sec	
	t _{VHH}	V _{HH} Rise and Fall Time (Note 1)	Min	Min 250			ns
	t _{VCS}	V _{CC} Setup Time (Note 1)	Min 50			μs	
	t _{BUSY}	WE# High to RY/BY# Low	Min	90	100	110	ns
	t _{POLL}	Program Valid before Status Polling Max 4					μs

Notes:

1. Not 100% tested.

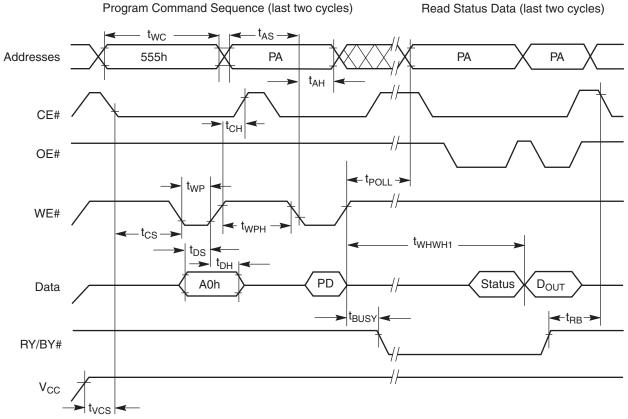
2. See "Erase And Programming Performance" for more information

3. For 1–16 words/1–32 bytes programmed.

4. Effective write buffer specification is based upon a 16-word/32-byte write buffer operation.

5. If a program suspend command is issued within t_{POLL}, the device requires t_{POLL} before reading status data, once programming resumes (that is, the program resume command has been written). If the suspend command was issued after t_{POLL}, status data is available immediately after programming resumes. See Figure 16.





Notes:

- 1. PA = program address, PD = program data, D_{OUT} is the true data at the program address.
- 2. Illustration shows device in word mode.



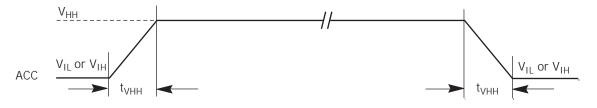
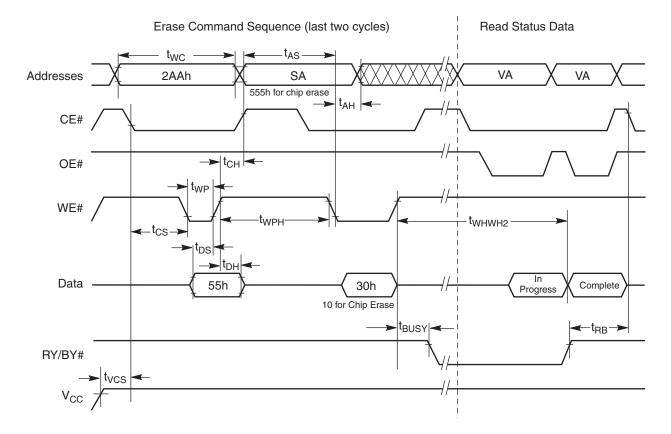


Figure I7. Accelerated Program Timing Diagram





Notes:

1. SA = sector address (for Sector Erase), VA = Valid Address for reading status data (see "Write Operation Status".)

2. Illustration shows device in word mode.

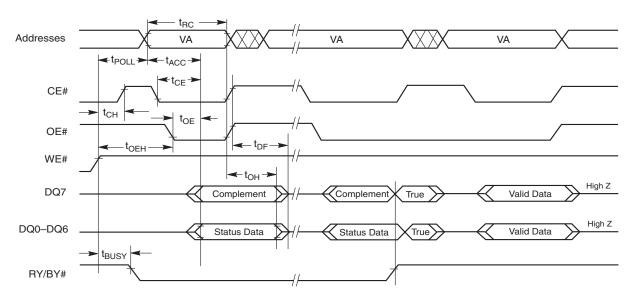


Figure 18. Chip/Sector Erase Operation Timings

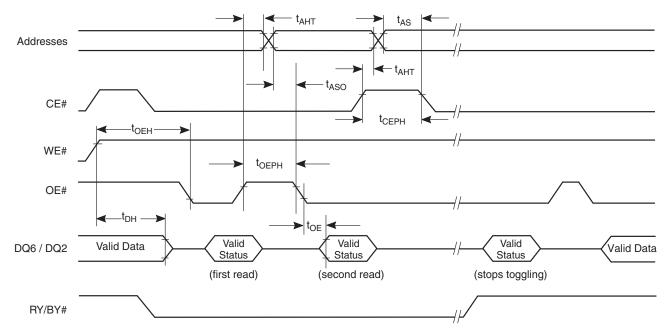
Note: VA = Valid address. Illustration shows first status cycle after command sequence, last status read cycle, and array data read cycle.

Figure 19. Data# Polling Timings (During Embedded Algorithms)

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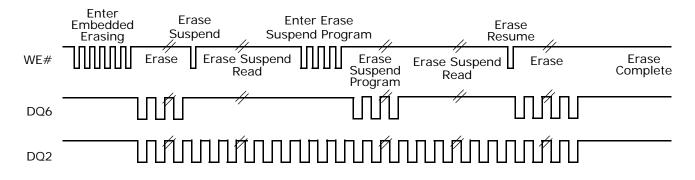
73





Note: VA = Valid address; not required for DQ6. Illustration shows first two status cycle after command sequence, last status read cycle, and array data read cycle.





Note: DQ2 toggles only when read at an address within an erase-suspended sector. The system may use OE# or CE# to toggle DQ2 and DQ6.

Figure 2I. DQ2 vs. DQ6



Temporary Sector Unprotect

Parameter					
JEDEC	Std	Description		All Speed Options	Unit
	t _{VIDR}	V _{ID} Rise and Fall Time (See Note)	Min	500	ns
	t _{RSP}	RESET# Setup Time for Temporary Sector Unprotect	Min	4	μs

Notes:

1. Not 100% tested.

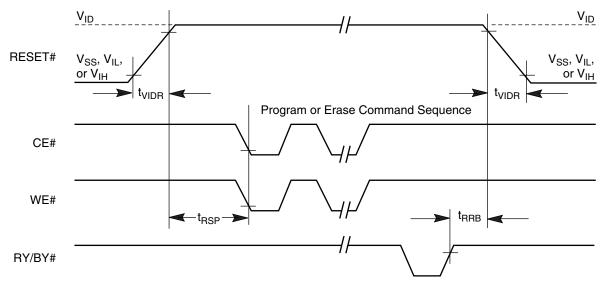
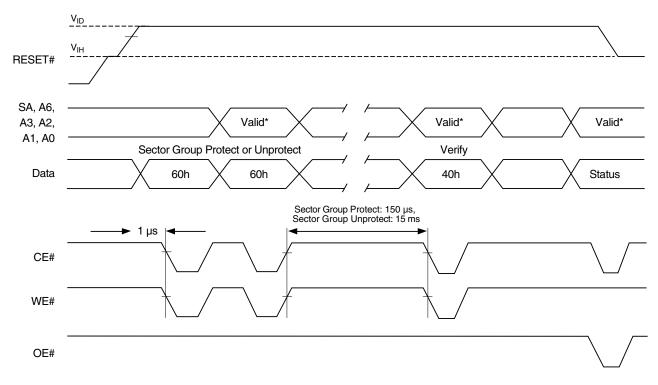


Figure 22. Temporary Sector Group Unprotect Timing Diagram





Note: For sector group protect, A6:A0 = 0xx0010. For sector group unprotect, A6:A0 = 1xx0010.

Figure 23. Sector Group Protect and Unprotect Timing Diagram



AC Characteristics Alternate CE# Controlled Erase and Program Operations-S29GL064A

Parameter				Spe	eed Opti	ons	
JEDEC	Std.	Description		90 10 11		Unit	
t _{AVAV}	t _{WC}	Write Cycle Time (Note 1)	Min	90	100	110	ns
t _{AVWL}	t _{AS}	Address Setup Time	Min		0		ns
t _{ELAX}	t _{AH}	Address Hold Time	Min		45		ns
t _{DVEH}	t _{DS}	Data Setup Time	Min		35		ns
t _{EHDX}	t _{DH}	Data Hold Time	Min		0		ns
t _{GHEL}	t _{GHEL}	Read Recovery Time Before Write (OE# High to WE# Low)	Min	0			ns
t _{WLEL}	t _{WS}	WE# Setup Time	Min	0			ns
t _{EHWH}	t _{WH}	WE# Hold Time	Min	0			ns
t _{ELEH}	t _{CP}	CE# Pulse Width	Min 35			ns	
t _{EHEL}	t _{CPH}	CE# Pulse Width High	Min		25		ns
		Write Buffer Program Operation (Notes 2, 3)	Тур		240		
t _{WHWH1}	t _{WHWH1}	Single Word Program Operation (Note 2)	Тур		60		μs
		Accelerated Single Word Program Operation (Note 2) Typ			54		
t _{WHWH2}	t _{WHWH2}	Sector Erase Operation (Note 2) Typ 0.5			sec		
	t _{RH}	RESET# High Time Before Write	Min	50			ns
	t _{POLL}	Program Valid before Status Polling (Note 5)	Max		4		μs

Notes:

1. Not 100% tested.

- 2. See the "Erase and Programming Performance" section for more information.
- 3. For 1–16 words/1–32 bytes programmed.
- 4. If a program suspend command is issued within t_{POLL}, the device requires t_{POLL} before reading status data, once programming has resumed (that is, the program resume command has been written). If the suspend command was issued after t_{POLL}, status data is available immediately after programming has resumed. See Figure 24.

Alternate CE# Controlled Erase and Program Operations-S29GL032A

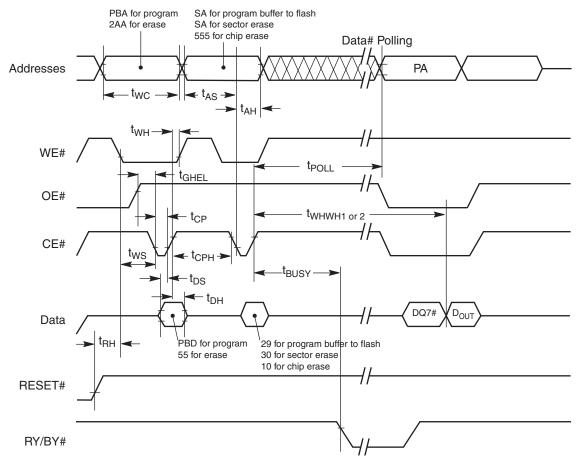
Parameter					Speed Optic	ons	
JEDEC	Std.	Description		90 10 11		11	Unit
t _{AVAV}	t _{WC}	Write Cycle Time (Note 1)	Min	90	100	110	ns
t _{AVWL}	t _{AS}	Address Setup Time Min 0				ns	
t _{ELAX}	t _{AH}	Address Hold Time	Min		45		ns
t _{DVEH}	t _{DS}	Data Setup Time	Min		35		ns
t _{EHDX}	t _{DH}	Data Hold Time	Min		0		ns
t _{GHEL}	t _{GHEL}	Read Recovery Time Before Write (OE# High to WE# Low) Min 0					ns
t _{WLEL}	t _{WS}	WE# Setup Time	Min	0			ns
t _{EHWH}	t _{WH}	WE# Hold Time	Min	0			ns
t _{ELEH}	t _{CP}	CE# Pulse Width	Min	35			ns
t _{EHEL}	t _{CPH}	CE# Pulse Width High	Min		25		ns
		Write Buffer Program Operation (Notes 2, 3)	Тур		240		
t _{WHWH1}	t _{WHWH1}	Single Word Program Operation (Note 2)	Тур	60		μs	
		Accelerated Single Word Program Operation (Note 2) Typ		54			
t _{WHWH2}	t _{WHWH2}	Sector Erase Operation (Note 2)	ation (Note 2) Typ 0.5		sec		
	t _{RH}	RESET# High Time Before Write	Min		50		ns
	t _{POLL}	Program Valid before Status Polling (Note 4) Max 4					μs

Notes:

1. Not 100% tested.

- 2. See "Erase And Programming Performance" for more information
- 3. For 1–16 words/1–32 bytes programmed.
- 4. If a program suspend command is issued within t_{POLL}, the device requires t_{POLL} before reading status data, once programming resumes (that is, the program resume command has been written). If the suspend command was issued after t_{POLL}, status data is available immediately after programming resumes. See Figure 24.





Notes:

- 1. Figure indicates last two bus cycles of a program or erase operation.
- 2. PA = program address, SA = sector address, PD = program data.
- 3. DQ7# is the complement of the data written to the device. D_{OUT} is the data written to the device.
- 4. Illustration shows device in word mode.

Figure 24. Alternate CE# Controlled Write (Erase/Program) Operation Timings



Erase And Programming Performance

Parameter	Typ (Note 1)	Max (Note 2)	Unit	Comments	
Sector Erase Time		0.5	3.5		Excludes 00h
Chin Franc Time	S29GL032A	32	64	sec	programming prior to erasure
Chip Erase Time	S29GL064A	64	128		(Note 6)
Total Write Buffer Program Time (Notes 3,	5)	240		μs	
Total Accelerated Effective Write Buffer Program Time (Notes 4, 5)		200		μs	Excludes system level overhead
Chin Drogram Time	S29GL032A			600	(Note 7)
Chip Program Time	S29GL064A	63		sec	

Notes:

- 1. Typical program and erase times assume the following conditions: $25^{\circ}C$, $V_{CC} = 3.0V$, 10,000 cycles; checkerboard data pattern.
- 2. Under worst case conditions of 90°C; Worst case V_{CC}, 100,000 cycles.
- 3. Effective programming time (typ) is $15 \ \mu s$ (per word), $7.5 \ \mu s$ (per byte).
- 4. Effective accelerated programming time (typ) is 12.5 μs (per word), 6.3 μs (per byte).
- 5. Effective write buffer specification is calculated on a per-word/per-byte basis for a 16-word/32-byte write buffer operation.
- 6. In the pre-programming step of the Embedded Erase algorithm, all bits are programmed to 00h before erasure.
- 7. System-level overhead is the time required to execute the command sequence(s) for the program command. See Tables 25 and 26 for further information on command definitions.



TSOP Pin and BGA Package Capacitance

Parameter Symbol	Parameter Description	Test S	Тур	Max	Unit	
C			TSOP	6	7.5	pF
C _{IN}	Input Capacitance	$V_{IN} = 0$	BGA	4.2	5.0	pF
C C			TSOP	8.5	12	pF
COUT	C _{OUT} Output Capacitance	$V_{OUT} = 0$	BGA	5.4	6.5	pF
G	Control Din Consultance		TSOP	7.5	9	pF
C _{IN2}	Control Pin Capacitance	$V_{IN} = 0$	BGA	3.9	4.7	pF

Notes:

1. Sampled, not 100% tested.

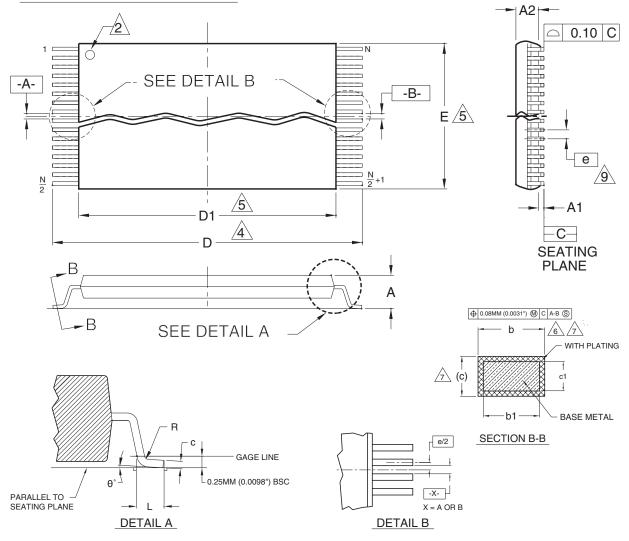
2. Test conditions $T_A = 25 \,^{\circ}C$, $f = 1.0 \,$ MHz.



Physical Dimensions

TS048—48-Pin Standard Thin Small Outline Package (TSOP)

STANDARD PIN OUT (TOP VIEW)



Package		TS 048	;	
Jedec	MO)-142 (B)	EC	
Symbol	MIN	NOM	MAX	
A	-	_	1.20	
A1	0.05	-	0.15	
A2	0.95	1.00	1.05	
b1	0.17	0.20	0.23	
b	0.17	0.22	0.27	
c1	0.10	_	0.16	
С	0.10	-	0.21	
D	19.80	20.00	20.20	
D1	18.30	18.40	18.50	
E	11.90	12.00	12.10	
е	0.5	50 BASI	Ċ	
L	0.50	0.60	0.70	
0	0°	3°	5°	
R	0.08	-	0.20	
N	48			

NOTES

CONTROLLING DIMENSIONS ARE IN MILLIMETERS (MM).

- A (DIMENSIONING AND TOLERANCING CONFORMS TO ANSI Y14.5M-1982)
- PIN 1 IDENTIFIER FOR STANDARD PIN OUT (DIE UP).
- NOT APPLICABLE.
- TO BE DETERMINED AT THE SEATING PLANE C-. THE SEATING PLANE IS DEFINED AS THE PLANE OF 4CONTACT THAT IS MADE WHEN THE PACKAGE LEADS ARE ALLOWED TO REST FREELY ON A FLAT HORIZONTAL SURFACE.
- DIMENSIONS D1 AND E DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE MOLD PROTUSION IS 0.15MM (.0059") PER SIDE.
- 6 DIMENSION b DOES NOT INCLUDE DAMBAR PROTUSION. ALLOWABLE DAMBAR PROTUSION SHALL BE 0.08 (0.0031") TOTAL IN EXCESS OF b DIMENSION AT MAX. MATERIAL CONDITION. MINIMUM SPACE BETWEEN PROTRUSION AND AN ADJACENT LEAD TO BE 0.07 (0.0028").

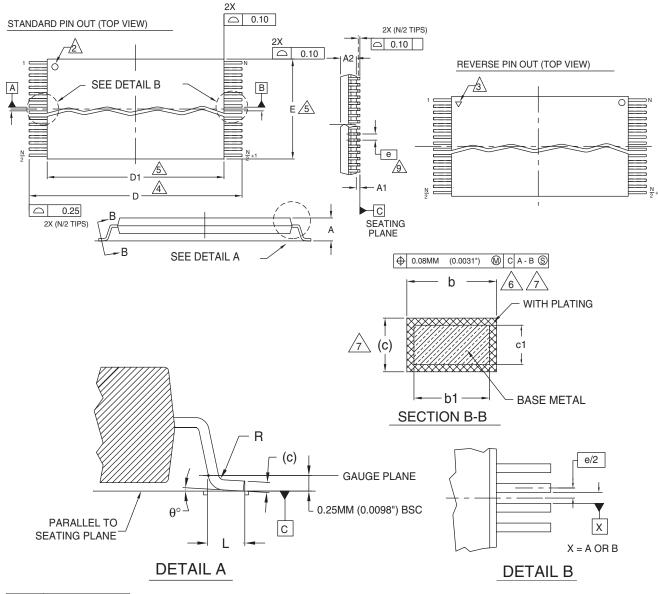
 \triangle THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.10MM (.0039") AND 0.25MM (0.0098") FROM THE LEAD TIP.

LEAD COPLANARITY SHALL BE WITHIN 0.10MM (0.004") AS MEASURED FROM THE SEATING PLANE. DIMENSION "e" IS MEASURED AT THE CENTERLINE OF THE LEADS

3325 \ 16-038 10a



TS056—56-Pin Standard Thin Small Outline Package (TSOP)



Package		TS 056		
Jedec	MO	-142 (D)	EC	
Symbol	MIN	NOM	MAX	
A	-	-	1.20	
A1	0.05	-	0.15	
A2	0.95	1.00	1.05	
b1	0.17	0.20	0.23	
b	0.17	0.22	0.27	
c1	0.10	-	0.16	
С	0.10	-	0.21	
D	19.80	20.00	20.20	
D1	18.30	18.40	18.50	
E	13.90	14.00	14.10	
е	0.50 BASIC			
L	0.50	0.60	0.70	
θ	0°	_	8°	
R	0.08	_	0.20	
Ν	56			

NOTES:

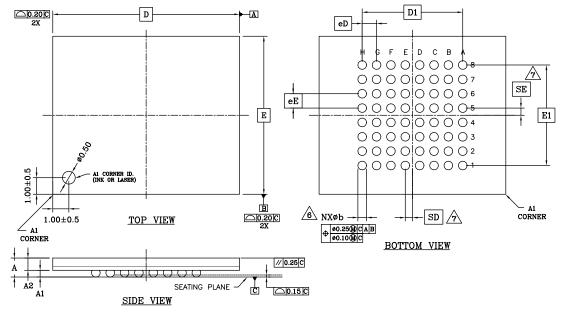
- CONTROLLING DIMENSIONS ARE IN MILLIMETERS (mm).
 - (DIMENSIONING AND TOLERANCING CONFORMS TO ANSI Y14.5M-1982)
- PIN 1 IDENTIFIER FOR REVERSE PIN OUT (DIE UP).
- A PIN 1 IDENTIFIER FOR REVERSE PIN OUT (DIE DOWN), INK OR LASER MARK.
- TO BE DETERMINED AT THE SEATING PLANE C. THE SEATING PLANE IS DEFINED AS THE PLANE OF CONTACT THAT IS MADE WHEN THE PACKAGE LEADS ARE ALLOWED TO REST FREELY ON A FLAT HORIZONTAL SURFACE.
- DIMENSIONS D1 AND E DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE MOLD PROTUSION IS 0.15mm (.0059") PER SIDE.
- DIMENSION b DOES NOT INCLUDE DAMBAR PROTUSION. ALLOWABLE DAMBAR PROTUSION SHALL BE 0.08 (0.0031") TOTAL IN EXCESS OF b DIMENSION AT MAX. MATERIAL CONDITION. MINIMUM SPACE BETWEEN PROTRUSION AND AN ADJACENT LEAD TO BE 0.07 (0.0028").
- THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.10MM (.0039") AND 0.25MM (0.0098") FROM THE LEAD TIP.
- LEAD COPLANARITY SHALL BE WITHIN 0.10mm (0.004") AS MEASURED FROM THE SEATING PLANE.
- DIMENSION "e" IS MEASURED AT THE CENTERLINE OF THE LEADS.

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LAA064—64-Ball Fortified Ball Grid Array (BGA)



PACKAGE	LAA 064			
JEDEC		N/A		
	13.00x11.00 mm PACKAGE			
SYMBOL	MIN.	NOM. MAX.		NOTE
A	-	-	1.40	PROFILE HEIGHT
A1	0.40	-	-	STANDOFF
A2	0.60	_	-	BODY THICKNESS
D	13	5.00 BS	с.	BODY SIZE
E	11	.00 BS	с.	BODY SIZE
D1	7	.00 BS(c.	MATRIX FOOTPRINT
E1	7	.00 BS	с.	MATRIX FOOTPRINT
MD		8		MATRIX SIZE D DIRECTION
ME		8		MATRIX SIZE E DIRECTION
N		64		BALL COUNT
øb	0.50	0.60	0.70	BALL DIAMETER
eD	1.00 BSC.			BALL PITCH - D DIRECTION
eΕ	1.00 BSC.			BALL PITCH - E DIRECTION
SD/SE	0.50 BSC.			SOLDER BALL PLACEMENT
	A1-	A8, K1	-к8	DEPOPULATED SOLDER BALLS

NOTES:

1. DIMENSIONING AND TOLERANCING METHODS PER ASME Y14.5M-1994 .

2. ALL DIMENSIONS ARE IN MILLIMETERS

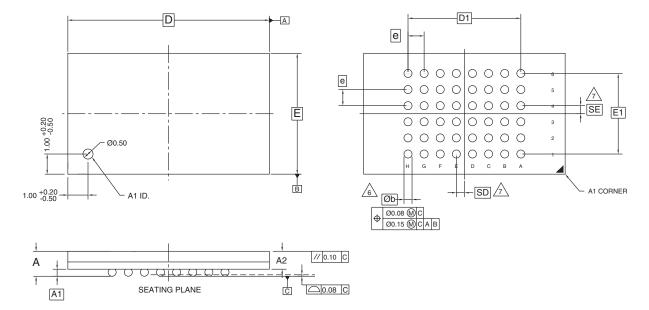
3. BALL POSITION DESIGNATION PER JESD 95-1, SPP-010 (EXCEPT AS NOTED).

4. e REPRESENTS THE SOLDER BALL GRID PITCH .

- 5. SYMBOL "MD" IS THE BALL MATRIX SIZE IN THE "D" DIRECTION.
- SYMBOL "ME" IS THE BALL COLUMN MATRIX SIZE IN THE "E" DIRECTION. N IS THE NUMBER OF POPULATED SOLDER BALL POSITIONS FOR MATRIX SIZE MD X ME.
- dimension "b" is measured at the maximum ball diameter in a plane parallel to datum "C".
- \bigwedge SD AND SE ARE MEASURED WITH RESPECT TO DATUMS A AND B AND DEFINE THE POSITION OF THE CENTER SOLDER BALL IN THE OUTER ROW. WHEN THERE IS AN ODD NUMBER OF SOLDER BALLS IN THE OUTER ROW, SD OR SE = 0.000. WHEN THERE IS AN EVEN NUMBER OF SOLDER BALLS IN THE OUTER ROW, SD OR SE = e/2
- 8. "X" IN THE PACKAGE VARIATIONS DENOTES PART IS UNDER QUALIFICATION.
- 9. "+" INDICATES THE THEORETICAL CENTER OF DEPOPULATED BALLS.



VBN048-48-Ball Fine-pitch Ball Grid Array (BGA) 10x 6 mm Package



PACKAGE	VBN 048			
JEDEC		N/A		
	10.00 mm x 6.00 mm NOM PACKAGE			
SYMBOL	MIN	NOM	MAX	NOTE
A			1.00	OVERALL THICKNESS
A1	0.17			BALL HEIGHT
A2	0.62		0.73	BODY THICKNESS
D		10.00 BSC.		BODY SIZE
E		6.00 BSC.		BODY SIZE
D1		5.60 BSC.		BALL FOOTPRINT
E1		4.00 BSC.		BALL FOOTPRINT
MD		8		ROW MATRIX SIZE D DIRECTION
ME		6		ROW MATRIX SIZE E DIRECTION
N		48		TOTAL BALL COUNT
φb	0.35 0.45		0.45	BALL DIAMETER
е	0.80 BSC.			BALL PITCH
SD / SE	0.40 BSC.			SOLDER BALL PLACEMENT
	NONE			DEPOPULATED SOLDER BALLS

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
- 2. ALL DIMENSIONS ARE IN MILLIMETERS.
- 3. BALL POSITION DESIGNATION PER JESD 95-1, SPP-010 (EXCEPT AS NOTED).
- 4. e REPRESENTS THE SOLDER BALL GRID PITCH.
- 5. SYMBOL "MD" IS THE BALL ROW MATRIX SIZE IN THE "D" DIRECTION.

SYMBOL "ME" IS THE BALL COLUMN MATRIX SIZE IN THE "E" DIRECTION.

N IS THE TOTAL NUMBER OF SOLDER BALLS.

- DIMENSION "b" IS MEASURED AT THE MAXIMUM BALL DIAMETER IN A PLANE PARALLEL TO DATUM C.
- A AND SE ARE MEASURED WITH RESPECT TO DATUMS A AND B AND DEFINE THE POSITION OF THE CENTER SOLDER BALL IN THE OUTER ROW.

WHEN THERE IS AN ODD NUMBER OF SOLDER BALLS IN THE OUTER ROW PARALLEL TO THE D OR E DIMENSION, RESPECTIVELY, SD OR SE = 0.000.

WHEN THERE IS AN EVEN NUMBER OF SOLDER BALLS IN THE OUTER ROW, SD OR SE = $\boxed{e/2}$

- 9. "+" INDICATES THE THEORETICAL CENTER OF DEPOPULATED BALLS.
- A1 CORNER TO BE IDENTIFIED BY CHAMFER, LASER OR INK MARK, METALLIZED MARK INDENTATION OR OTHER MEANS.

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^{8.} NOT USED.



Revision Summary

Revision A (October 13, 2004)

Initial Release.

Revision AI (December 17, 2004)

Secured Silicon Sector Flash Memory Region

Updated Secured Silicon Sector address table with addresses in x8-mode.

DC Characteristics (CMOS Compatible)

ILIT re-specified over temperature.

Corrected WP#/ACC input load current footnote.

Revision A2 (January 28, 2005)

Global

Added S29GL032A information.

Colophon

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